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Attorney Docket No. 125.003USR1

#### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

**James Leroy Snell** 

Serial No.: 10/005,483

Filed: November 9, 2001

For: HIGH DATA RATE SPREAD

SPECTRUM TRANSCEIVER AND

**ASSOCIATED METHODS** 

Group Art Unit: 2631

Examiner: Not Assigned

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BOX DAC Commissioner for Patents Washington, D.C. 20231

OFFICE OF PETITIONS

## RENEWED PETITION UNDER 37 C.F.R. § 1.47(b) TO FILE APPLICATION WITHOUT INVENTOR'S SIGNATURE

Pursuant to 37 C.F.R. § 1.47(b), petitioner Intersil Americas Inc. ("Intersil"), respectfully seeks permission to file the above-identified reissue application without the signature of one of the inventors, James Leroy Snell. James Leroy Snell has refused to execute the reissue application. The last known address for James Leroy Snell is as follows:

**James Leroy Snell** 

Residence/Post Office Address: 2695 Lemon Street NE

Palm Bay, FL 32905

Citizenship: US

Snell is the inventor named on U.S. Patent No. 5,982,807, issued November 9, 1999 for "High Data Rate Spread Spectrum Transceiver and Associated Methods" (the "'807 patent").

As set forth in the Declaration of Elizabeth A. Bauer, submitted herewith, *bona fide* attempts and diligent efforts have been made to present the reissue application and corresponding inventor's declaration to James Leroy Snell for signature in accordance with MPEP 409.03(b) and 37 C.F.R. §1.47(b). As indicated in paragraphs 2 and 3 of the Declaration of David N. Fogg,

#### RENEWED PETITION 1.47(a) TO FILE REISSUE APPLICATION WITHOUT INVENTOR'S SIGNATURE

Serial No. 10/005,483 Filed: November 9, 2002

Title: HIGH DATA RATE SPREAD SPECTRUM TRANSCEIVER AND ASSOCIATED METHODS

Attorney Docket No. 125.003USR1 PAGE 2 OF 2

James Leroy Snell has refused to execute the reissue application and corresponding inventor's declaration.

The declaration of Paul A. Bernkopf, submitted with the prior Petition on June 28, 2002 (copy enclosed), shows that the petitioner Intersil, is the assignee of the '807 patent. Intersil filed a reissue application on the '807 patent without the inventor's signature on November 9, 2001, serial number 10/005,483, to broaden the scope of the claims of the '807 patent. Respectfully, Intersil has sufficient proprietary right to act as agent for the inventor in this application.

Filing of this reissue application is necessary to preserve the rights of the parties hereto. Irreparable harm will result to Intersil if the petition is not granted as shown by the Declaration of Paul A. Bernkopf.

Applicant previously submitted a Reissue Application: Consent of Assignee: Statement of Non-Assignment and Statement under 37 C.F.R. 3.73(b) (copies enclosed) on June 28, 2002.

It is Applicant's understanding that there are no additional fees for this RENEWED Petition. However, if any additional fees or credits are deemed necessary, please charge or credit Deposit Account No. 502432

Based on the foregoing, it is respectfully submitted that the petitioner has demonstrated sufficient proprietary interest to make the reissue application on behalf of and as agent for the inventor James Leroy Snell who has refused to sign the inventor declaration. Petitioner respectfully requests that the petition Under 37 CER §1.47(b) be granted.

Respectfully submitted,

Date:

David N. Fogg

Reg. No. 35,138

Attorneys for Applicant Fogg & Associates, LLC P.O. Box 581339

Minneapolis, MN 55458-1339 Telephone: 612-332-4720

Facsimile: 612-677-3553

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#### Declaration Of Paul A. Bernkopf

#### I, Paul A. Bernkopf, hereby declare:

- I am Chief Intellectual Property Counsel and Corporate Vice President of Intersil Americas Inc., formerly known as Intersil Corporation and Intersil Communications Inc. ("Intersil"). Intersil is a successor in interest to Harris Corporation and assignee of Harris Corporation's interest in certain intellectual property, including U.S. Patent No. 5,982,807, issued to James Leroy Snell, inventor, on November 9, 1999 for "High Data Rate Spread Spectrum Transceiver And Associated Methods" (the "807 patent"), as shown by assignment dated August 11, 1997, and recorded on September 19, 1997, at Reel: 8728, Frame: 0769, in the United States Patent and Trademark Office.
- 2. James Leroy Snell is a former employee of Harris Corporation and Intersil. He was involved in research and development of Harris Corporation and Intersil products. Snell is sole inventor of the "807 patent." On information and belief, he is retired.
- 3. James Leroy Snell agreed in writing to assign all of his right, title and interest in and to the invention of the '807 patent to Harris Corporation, Intersil's predecessor in interest, as shown by assignment dated August 11, 1997, and recorded on September 19, 1997, at Reel: 8728, Frame: 0769, in the United States Patent and Trademark Office.
- 4. Intersil filed a reissue application on the '807 patent without the inventor's signature on November 9, 2001, RE 10/005,483, to broaden the scope of the claims of the '807 patent.
- 5. The invention of the '807 patent represents valueable intellectual property of Intersil. Intersil will be irreparably harmed if it is not able to exploit this intellectual property by filing and prosecuting the subject reissue application since the scope of the invention was not fully realized by the claims of of the '807 patent.

I further declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Paul A. Bernkopf

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PTO/S8/53 (10-00)

Under the Pacerwork Reduction Act of 1995, no persons are re-	Patent and	Approved for use through 12/30/2000. OMB 0651-003 at Trademark Office; U.S. DEPARTMENT OF COMMERCITION of information unless it displays a valid OMB
REISSUE APPLICATION: CONSENT O	F ASSIGNEE:	Docket Number (Optional)
STATEMENT OF NON-ASSIGN	MENT	125.003USR1
:		
This is part of the application for a reissue patent based Name of Patentee(s) James I erroy Snell	d on the original pate	ant identified below.
Name of Patentee(s) James Leroy Snell		
Patent Number 5,982,807	Date Patent Issued	d
5,982,807 Title of Invention	November 9, 199	99
HIGH DATA RATE SPREAD SPECTRUM TRANSCEIV	/ER AND ASSOCIAT	FED METHODS
1. X Filed herein is a certificate under 37 CFR 3.73	(b). (Form PTO/SB/	/96)
2. Ownership of the patent is in the inventor(s), a	and no assignment of	f the patent is in effect.
One of boxes 1 or 2 above must be checked. If multiple box 2 is checked, skip the next entry and go directly to	"Name of Assignee".	•
The written consent of all assignees and inventors ownithis application for reissue.	ing an undivided inte	erest in the original patent is included in
The assignee(s) owning an undivided interest in said on	riginal natent is/are	Intersil Americas, Inc. 7585 Irvine Center Drive Suite 100 Irvine, California 92618
and the assignee(s) consents to the accompanying app	lication for reissue.	Trune, Gamorina 52515
Name of assignee/inventor (if not assigned)		
Signature W Charles	Date 6/7/	602
Typed or printed name and the title of person signing for assignee (if assigned)		400
Paul A. Bernkopf Chief Intellectual Property Counsel & Corporate Vio	ce President	
·		
·		

PTO/SB/96 (6-98)

Approved for use through 09/30/2000. OMB 0651-0031

Patent and Trademark Office, U.S. DEPARTMENT OF COMMERCE

Under the Paperwork/Reduction Act of 1995, no persons are required to respond to a collection of information unless it displays a valid OMB control number.

Under the Paperwork/Reduction Act of 1995, no persons are required to respond to a collection of information unless it displays a valid OMB control number
STATEMENT UNDER 37 CFR 3.73(b)
Applicant/PatentOwner_Intersil Americas, Inc.
Application No./Patent No.: 08/819,846 - 5,982,807 Filed/Issue Date: 03/17/97 - 11/09/99
Entitled: HIGH DATA RATE SPREAD SPECTRUM TRANSCRIVER AND ASSOCIATED METHODS
Intersil Americas Inc. ,a corporation ,
(Name of Assignee) (Type of Assignee, e.g., corporation, partnership, university, government agency, etc.)
states that it is:
1. Let the assignee of the entire right, title, and interest; or
2. an assignee of an undivided part interest
in the patent application/patent identified above by virtue of either:
A. [ ] An assignment from the inventor(s) of the patent application/patent identified above. The assignment was recorded in the Patent and Trademark Office at Reel, Frame, or for which a copy thereof is attached.
OR
B. [V] A chain of title from the inventor(s), of the patent application/patent identified above, to the current assignee as shown below:
1. From: James Leroy Snell To: Harris Corporation
The document was recorded in the Patent and Trademark Office at Reel 8728 , Frame 0769 , or for which a copy thereof is attached.
2. From: Harris Corporation To: Intersil Corporation
The document was recorded in the Patent and Trademark Office at Reel 10884 , Frame 0394 , or for which a copy thereof is attached.
3. From: Intersil Corporation To: Intersil Communication Inc.
The document was recorded in the Patent and Trademark Office at Reel, Frame, or for which a copy thereof is attached.
[V] Additional documents in the chain of title are listed on a supplemental sheet.
Copies of assignments or other documents in the chain of title are attached.  [NOTE: A separate copy (i.e., the original assignment document or a true copy of the original document) must be submitted to Assignment Division in accordance with 37 CFR Part 3, if the assignment is to be recorded in the records of the PTO. See MPEP 302-302.8]
The undersigned (whose title is supplied below) is empowered to sign this statement of belialf of the assignee.
0/26/02 Pull Signature
Paul A. Bernkopf Typed or printed name
Chief IP Counsel & Corporate VP
Title

Burden Hour Statement: This form is estimated to take 0.2 hours to complete. Time will vary depending upon the needs of the individual case. Any comments on the amount of time you are required to complete this form should be sent to the Chief Information Officer, Patent and Trademark Office, Washington, DC 20231. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Assistant Commissioner for Patents, Washington, DC 20231.

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4. Intersil Communication Inc.
Intersil Americas Inc. From:

To:

This document is attached, but has not been recorded in the U.S. Patent and Trademark Office.

## Office of the Secretary of State

I, HARRIET SMITH WINDSOR, SECRETARY OF STATE OF THE STATE OF DELAWARE, DO HEREBY CERTIFY THE ATTACHED IS A TRUE AND CORRECT COPY OF THE RESTATED CERTIFICATE OF "INTERSIL CORPORATION", CHANGING ITS NAME FROM "INTERSIL CORPORATION" TO "INTERSIL COMMUNICATIONS, INC.", FILED IN THIS OFFICE ON THE TWENTY-FIFTH DAY OF MAY, A.D. 2081, AT 4:15 O'CLOCK P.M.

A FILED COPY OF THIS CERTIFICATE HAS BEEN FORWARDED TO THE NEW CASTLE COUNTY RECORDER OF DEEDS.

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OFFICE OF PETITIONS



Darriet Smith Windson, Secretary of State

AUTHENTICATION: 1155634

DATE: 05-25-01

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#### AMENDED AND RESTATED CERTIFICATE OF INCORPORATION

OF

#### INTERSIL CORPORATION

INTERSIL CORPORATION, a corporation organized and existing under the laws of the State of Delaware, hereby certifies as follows:

FIRST: The present name of the corporation is INTERSIL

CORPORATION and the name under which the corporation was originally incorporated is HSS

Operating Corporation. The date of filing of its original Certificate of Incorporation with the

Secretary of State of the State of Delaware was June 2, 1999.

SECOND: This Amended and Restated Certificate of Incorporation (the "Certificate") restates and integrates and further amends in its entirety the Certificate of Incorporation of this corporation. This Certificate was duly adopted by a majority vote of the stockholders of the corporation in accordance with Sections 228, 242 and 245 of the General Corporation Law of the State of Delaware.

THIRD: This Certificate shall become effective immediately upon its filing with the Secretary of State of the State of Delaware.

FOURTH: Upon the filing of the Certificate with the Secretary of State of the State of Delaware, the Certificate of Incorporation of the corporation shall be amended and restated in its entirety to read as set forth on Exhibit A attached hereto.

IN WITNESS WHEREOF, said corporation has caused this Certificate to be executed by a duly authorized officer this 23rd day of May, 2001.

By:

inegary Williams
Life Executive Officer

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OFFICE OF PETITIONS

STATE OF DELAWARE SECRETARY OF STATE DIVISION OF COMPORATIONS FILED 04:15 PM 05/25/2001 010253080 - 3050122

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EXHIBIT A

#### AMENDED AND RESTATED CERTIFICATE OF INCORPORATION

OF

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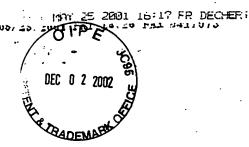
#### INTERSIL COMMUNICATIONS, INC.

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**OFFICE OF PETITIONS** 

- 1. Name. The name of the Corporation is Intersil Communications, Inc.
- 2. Registered Office and Agent. The address of the Corporation's registered office in the State of Delaware is 1209 Orange Street, in the City of Wilmington. County of New Castle. The name of the Corporation's registered agent at such address is The Corporation Trust Company.
- 3. Purpose. The purposes for which the Corporation is formed are to engage in any lawful act or activity, including, without limitation, forming and/or acquiring foreign subsidiaries, for which corporations may be organized under the General Corporation Law of the State of Delaware ("DGCL") and to possess and exercise all of the powers and privileges granted by such law and any other law of Delaware.
- 4. Authorized Capital. The aggregate number of shares of stock which the Corporation shall have authority to issue is One Thousand (1,000) shares, all of which are of one class and are designated as Common Stock, par value \$.01 per share.
- 5. Incorporator. The name and mailing address of the incorporator are Marian T. Ryan, 4000 Bell Atlantic Tower, 1717 Arch Street, Philadelphia, Pennsylvania 19103-2793.
- 6. Bylaws. In furtherance and not in limitation of the powers conferred by law, the board of directors of the Corporation is authorized to adopt, amend or repeal the bylaws of the Corporation, except as otherwise specifically provided therein, subject to the powers of the stockholders of the Corporation to amend or repeal any bylaws adopted by the board of directors.
- 7. Elections of Directors. Elections of directors need not be by written ballot unless and except to the extent the bylaws of the Corporation shall so provide.
- 8. Right to Amend: The corporation reserves the right to amend or repeal any provision contained in this Certificate as the same may from time to time be in effect in the manner now or hereafter prescribed by law, and all rights, preferences and privileges conferred on stockholders, director or others hereunder are subject to such reservation.
- 9. Unanimous Written Consent Required. If any action is to be taken by stockholders without a meeting, such action must be authorized by unanimous written consent signed by all of the holders of outstanding voting stock.

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10. Limitation on Liability. The directors of the Corporation shall be entitled to the benefits of ... limitations on the liability of directors generally that are now or hereafter become available under the DGCL. Without limiting the generality of the foregoing to the fullest extent permitted by the DGCL, as it exists on the date hereof or as it may hereafter be amended, no director of the Corporation shall be personally liable to the Corporation or its stockholders for monetary damages for heach of fiduciary duty as a director, except for liability (i) for any breach of the director's duty of loyalty to the Corporation or its stockholders, (ii) for acts or omissions not in good faith or which involve intentional misconduct or a knowing violation of law, (iii) under Section 174 of the DGCL, or (iv) for any transaction from which the director derived an improper personal benefit. Any repeal or modification of this Section 10 hall be prospective only, and hall not affect, to use detriment of any director, any limitation on the personal liability of a director of the Corporation existing at the time of such repeal, modification or adoption.

Dated: May 23, 2001

By

Gregory I. Williams Chief Executive Office

DEC 0-3 2002

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#### **CONTRIBUTION AGREEMENT**

DEC 0 2 2002

This Contribution Agreement (the "Agreement") is effective as of December 31, 2001 (the "Effective Date") at 11:59 PM United States of America EST (the "Effective Time") by and between Intersil Communications, Inc., a Delaware corporation ("Intersil"), and Intersil Americas Inc., a Delaware corporation ("Intersil Americas").

#### Background

To promote greater efficiency and economy in the management of the businesses carried on by the parties to this Agreement, Intersil desires to make a capital contribution to Intersil Americas of certain intellectual property and other assets used in the business of Intersil and its affiliates.

#### Terms

Intending to be legally bound, the parties to this Agreement agree as follows:

- 1. Effective as of the date first written above, Intersil shall contribute the following to Intersil Americas, in deemed exchange for stock of Intersil Americas in a non-recognition transaction as described in Section 351 of the Internal Revenue Code of 1986, as amended:
- (i) all right, title and interest in and to the trademarks shown in <u>Schedule A</u> and all slogans, logotypes, designs, and trade dress associated therewith (the "Trademarks"), together with the U.S. federal registrations and applications for registration of the Trademarks, in and to all income, royalties, damages and payments now or hereafter due or payable with respect thereto and in and to all rights of action arising from the Trademarks, to be held and enjoyed by Intersil Americas for its own use and benefit and for its successors and assigns as the same would have been held by Intersil had this contribution not been made, and the goodwill of the business symbolized by the Trademarks;
- (ii) all right, title and interest in and to the U.S. patents and patent applications shown in Schedule A (the "Patents"), including all reissues, divisions, continuations, continuations-in-part, and extensions thereof, to be held and enjoyed by Intersil Americas as fully and entirely as they would have been held and enjoyed by Intersil if this contribution had not been made, including all licenses of and proceeds from the Patents, all claims, demands and rights to recovery that Intersil has or may have in profits and damages for past and future infringements, if any, and all rights to compromise, sue for, and collect such profits and damages;
- (iii) all right, title, and interest in and to all inventions shown in <u>Schedule A</u> (the "Inventions"), and all intellectual property rights relating thereto, including, without limitation, trade secret rights in the Inventions, and all rights of action arising from the Inventions, to be held and enjoyed by Intersil Americas for its own use and benefit and for its successors and assigns as the same would have been held by Intersil had this contribution not been made; and
- (iv) all right, title, and interest in and to all copyrights owned by Intersil as of the date first written above that are not otherwise excluded from contribution under the terms of this Agreement, whether or not such copyrights have been registered (collectively, the "Copyrights"),

including, without limitation, all U.S. registrations and applications for registration of the Copyrights, all licenses of and proceeds from the Copyrights, all publishing, electronic publishing, and other proprietary rights arising from or related to the Copyrights, all causes of action relating to the Copyrights that may have arisen prior to this contribution, and any recovery resulting from such causes of action.

Notwithstanding the foregoing or any specific item listed on <u>Schedule A</u>, the intellectual property used in connection with providing products or services that are regulated by the United States Department of State shall not be contributed to Intersil Americas.

2. Intersil and Intersil Americas shall each take any and all additional actions as may be necessary or appropriate to effect the transactions contemplated by this Agreement. Such actions may include, without limitation, the execution of additional documents to record the contribution made in this Agreement and the filing of such documents with the appropriate governmental authorities.

[Signatures commence on the following page]

IN WITNESS WHEREOF, the parties have caused this Agreement to be executed as of the date below to be effective as of the Effective Date and Effective Time.

INTERSIL COMMUNICATIONS, INC. a Delaware corporation

By: Date: 12/2/01
Name: AUL A. BORNOPF

Title: ASSP SECRETARY

INTERSIL AMERICAS INC. a Delaware Corporation

0110/1

Date: 12/21/01

Name: PAU A BERNYOPE Title: ASST- SECRETARY

### SCHEDULE A TRADEMARKS

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T458	Pending	PRISM	76/049825	
T457	Pending	UNLEASHING THE POWER OF CONNECTIVITY	7 76/020163	
T470	Pending	ENDURA (AND DESIGN)	76/131333	
T473	Pending	DOES YOUR HOME NETWORK DO THIS	76/168307	
T476	Pending	COMMLINK (And Design)	76/177125	·
T477	Pending	AIRLOCK	75/813888	
T452	Pending	STAR*POWER AND DESIGN	75/886802	
<sup>,</sup> T440	Pending	WHEN FAILURE IS NOT AN OPTION	75/792441	
T441-2	Pending	INTERSIL	75/721773	
T441-3	Pending	INTERSIL	75/721751	
T442	Pending	INTERSIL (AND DESIGN)	75/746727	
T442-2	Pending	INTERSIL (AND DESIGN)	75/746761	
T442-3	Pending	INTERSIL (AND DESIGN)	75/746792	
T445	Pending	I (AND DESIGN)	75/773846	
T445-2	Pending	I (AND DESIGN)	75/773844	
T445-3	Pending	I (AND DESIGN)	75/773843	
T446	Pending	STAR*POWER	75/851663	
T447	Pending	WIRELESS AT THE SPEED OF LIFE	75/873518	
T448	Pending	DENSETRENCH	75/853697	
T459	Pending	INTERBOND	76/068207	
T451	Pending	STAR*LITE AND DESIGN	75/900860	
T472	Pending	INTELLITRIP	76/132081	
T475	Pending	PRISMWORK	76/160295	
T450	Pending	STAR*LITE	75/900859	
T474	Pending	PRISM/HOME	76/160296	
T441-2 US	Pending	INTERSIL	75/746761	
T471	Pending	THE POWER TO PROTECT	76/132080	
T483	Pending	PRISM AND DESIGN	76/180032	
T469	Pending	ENDURA 7	76/122189	
T468	Pending	COMMLINK 7	76/135647	
T465	Pending	INTERFACE AND DESIGN 7	76/099311	
T464	Pending	INTERFACE 7	76/099352	



#### SCHEDULE A TRADEMARKS

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T441-3 US	Pending	INTERSIL	75/746792	
T248	REGISTERED	INTERSIL	16741	1014040
T387	Registered	PRISM	75/230863	2197112
T359	Registered	PRISM (AND DESIGN)	75/088186	2108394
T325	Registered	SYNCHROFET	74/612382	2011392.
T441	Registered	INTERSIL	75/722352	2488585

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XRCA77096		Granted	545048	24-Oct-198	3 4472459	18-Sep-198	LOCAL OXIDATION OF SILICON SUBSTRATE USING LPCVD S
VD0474047	<u>.</u>	Garated	224050	22 Nov. 409	14420204	24 lon 100	4 OPERATIONAL AMPLIFIER
XRCA74917		Granted	324059	23-Nov-198	14429284	31-Jan-190	4OPERATIONAL AMPLIPIER
SE-102	A	Granted	973822	27-Dec-1978	34881111	14-Nov-198	9 RADIATION HARD, HIGH EMITTER-BASE BREAKDOWN BIOPOLAR TRANSISTOR
SE145	A	Granted	200386	24-Oct-1980	4670769	02-Jun-198	FABRICATION OF ISOLATED REGIONS FOR USE II SELF-ALIGNING DEVICE PROCESS UTILIZING SELECTIVE OXIDATION
SE-198		Granted	382603	27-May-1982	4528504	09-Jul-198	PULSED LINEAR INTEGRATED CIRCUIT TESTER
SE-198	A	Granted	744336	13-Jun-1985	4616178	07-Oct-1986	PULSED LINEAR INTEGRATED CIRCUIT TESTER
SE200		Granted	353604	01-Mar-1982	4461000	17-Jul-1984	ROM/PLA STRUCTURE AND METHOD OF TESTING
SE-201	·	Granted	363815	31-Mar-1982	4514802	30-Apr-1985	INTEGRATED PROGRAM COUNTER MEMORY MGMT REGISTER AND INCREMENTER
SE202		Granted	416034	08-Sep-1982	4567578	28-Jan-1986	CACHE MEMORY FLUSH SCHEME
SE-208		Granted	296192	25-Aug-1981	4472648	18-Sep-1984	TRANSISTOR CIRCUIT FOR REDUCING GATE LEAKAGE CURRENT IN A JFET
SE212		Granted	326345	01-Dec-1981	4464631		CIRCUIT FOR TRIMMING JFET DIFFERENTIAL PAIR OFFSET VOLTAGE WITHOUT INCREASING THE OFFSET VOLTAGE TEMPERATURE COEFFICIENT
SE213		Granted	301761	14-Sep-1981	4682057		CIR DESIGN TECH TO PREVENT CURRENT HOGGING WHEN MINIMIZE INTERCON STRIPES BY PARALL STL OR ISL GATE INPUTS
SE215		Granted .	396072	07-Jul-1982	4524246	1	SLIC II - COMMON MODE CURRENT REJECTION DURING RINGING

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SE216		Granted	309194	06-Oct-19	81 4456918	26-Jun-198	34 ISOLATED GATE JFET STRUCTURE
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SE216	Α	Granted	599817	13-Apr-198	34 4495694	29-Jan-198	S ISOLATED GATE JEET STRUCTURE
1		}			<b>]</b> .	1 .	
SE-219		Granted	406333	09-Aug-198	2 4532003	30-Jul-198	5 METHOD OF FAB BIPOLAR TRANSISTOR
					.		WIMPROVED BASE COLLECTOR BRKDN VOLTAGE AND COLLECTOR SERIES RESISTANCE
25.00					·		
SE-221	A	Granted	782192	30-Sep-198	5 4652895	24-Mar-198	DEEP N+ BURIED ZENER STRUCTURE
					1	1	
SE-222	В	0	007005	07.5 1.400	1,000001		
SE-222	ľ	Granted	827285	07-Feb-198	14862231	29-Aug-1989	METHOD OF FAB AN IC INCL ELEC-OPTIC TRANSMITTERS AND RECEIVERS
				[	İ	•	
SE-222	C	Granted	07/143328	13-Jan-1988	3 4845052	04 Jul 1090	METHOD OF FAB AN IC INCL ELEC-OPTIC
OL-222		Cranted	077143320	13-3411-1300	14043032	04-301-1968	TRANSMITTERS AND RECEIVERS
	137					ļ	
SE-224		Granted	414862	03-Sep-1982	4528461	09-Jul-1985	INTEGRATED CIRCUIT SWITCH USING STACKED
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SE-224	A	Granted	460020	21-Jan-1983	4528462	09-Jul-1985	INTEGRATED CIRCUIT SWITCH USING STACKED
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SE225		Granted	500910	03-Jun-1983	4580131		A BINARILY-WEIGHTED D TO A CONVERTER
							LADDER WITH INHERENTLY REDUCED SWITCHING NOISE
		ļ	. 1				OTHER MAINE NOISE
SE229	Α	Granted	883279	07-Jul-1986	4729008		HIGH VOLTAGE INTEGRATED CIRCUIT JEET
							STRUCTURES AND A CIRCUIT USING HIGH VOLTAGE JEETS TO ACHIEVE TRANSISTOR
				· .			OPERATION T
SE229	В	Granted	130521	09-Dec-1987	4808547		HIGH VOLTAGE INTEGRATED CIRCUIT JFET STRUCTURES AND A CIRCUIT USING HIGH
						1	VOLTAGE JFETS TO ACHIEVE TRANSISTOR
SE231		Contod	254442	00.5-1-4000	1474000	1	OPERATION T
3E231		Granted	351442	23-Feb-1982	44/1236		HIGH TEMPERATURE BIAS LINE STABILIZED CURRENT SOURCES
SE232	<del> </del>	Granted	351443	23-Feb-1982	4450414	22 May 1084	HIGH TEMPERATI IDE CHIRDENT MIDROR
		Siunteu		20-1 60-1302	7730414	1	HIGH TEMPERATURE CURRENT MIRROR  AMPLIFIER
			] [		İ		
SE227	-	Granted	447947	08-Dec-1982	4586193	29-Apr-1986	FORMANT-BASED SPEECH SYNTHESIZER
						25 7.47 7000	S. S. S. S. S. S. S. S. S. S. S. S. S. S
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SE228		Granted	526065	24-Aug-19	83 4703505	27-Oct-198	37 SPEECH DATA ENCODING SCHEME
SE233	-	Granted	460061	21-Jan-19	83 4559608	17-Dec-198	25 ARITHMETIC LOGIC UNIT
SE234	<u> </u>	Granted	475618	15-Mar-198	83 4581548	08-Apr-198	6 ADDRESS DECODER
						00,15,100	, 155, 1 <u>2</u> 55 5 <u>2</u> 5552.
SE236		Granted	506794	22-Jun-198	33 4567385	28-Jan-198	6 POWER SWITCHED LOGIC GATES
SE-237	·	Granted	566400	28-Dec-198	3 4596068	24-Jun-198	PROCESS FOR MINIMI BORON DEPLETION IN N- CHANNEL FET AT SILICON OXIDE INTERFACE
SE-241		Granted	435221	19-Oct-198	2 4466179	21-Aug-1984	METHOD FOR PROVID POLYSILICON THIN FILMS OF IMPROVED UNIFORMITY VE UNIFORMITY OF LASER-ANNEALED POLYSILICON THIN FILM
SE-241	A	Granted	612877	22-May-198	4 4536231	20-Aug-1985	METHOD FOR PROVID POLYSILICON THIN FILMS OF IMPROVED UNIFORMITY VE UNIFORMITY OF LASER-ANNEALED POLYSILICON THIN FILM
SE-243		Granted	447946	08-Dec-1982	2 4546539	15-Oct-1985	12L STRUCTURE AND FABRICATION PROC COMPAT W/HI VOLT BIPOLAR TRANS
SE-245		Granted	467295	17-Feb-1983	3 4464825	_	PROCESS FOR FAB OF HI-SPEED RADIATION HARD BIPOLAR SEMI DEVICES
SE-249	Α	Granted	771160	30-Aug-1985	4620179	28-Oct-1986	METHOD FOR ANALOG TO DIGITAL CONVERSION
SE254/256		Granted	518598	29-Jul-1983	4590664		METHOD OF FAB LOW NOISE REFERENCE DIODES AND TRANSISTORS
SE-251	·	Granted	493234	10-May-1983	4495537	22-Jan-1985	CONTROLLED CURRENT LIMITER IPATION
SE-247	·	Granted	454533	30-Dec-1982	4503387	05-Mar-1985	AC TESTING OF LOGIC ARRAYS
SE258		Granted	518725	29-Jul-1983	4468414		DIELECTRIC ISOLATION FAB FOR LASER TRIMMING Y
					<u></u>		

E Cligatear	Subces		Au	File		isspac	The state of the s
SE257		Granted	506793	22-Jun-198	33 4584660	22-Apr-198	6 REDUCTION OF SERIES PROPAGATION DELAY AND IMPEDANCE
SE-252		Granted	504312	02-Aug-198	3 4532481	30-Jul-198	5 HIGH VOLTAGE CURRENT MIRROR
SE-253		Granted	526066	24-Aug-198	3 4566796	28-Jan-1986	METHOD OF DETERMINING POSITION OF A WAFER BY INTERROGATING A TARGET
SE264/265	A	Granted	678075	04-Dec-198	4 4554059	19-Nov-1985	ELECTROCHEM DI SINGLE TYPE ISOLATED ISLANDS
SE269		Granted	728271	29-Apr-198	5 4717847	05-Jan-1988	TTL COMPATIBLE CMOS INPUT BUFFER
SE271		Granted	610583	15-May-1984	4594265	10-Jun-1986	LASER TRIMMING RESISTORS OVER DIELECTRICALLY ISOLATED ISLAND S
SE273		Granted	668864	06-Nov-1984	4639684	1	AN IMPROVED DIFFERENTIAL INPUT STAGE FOR THE REALIZATION OF LOW NOISE AND HIGH PRECISION BIPOLAR TRANSISTOR AMPLIFIERS
SE275		Granted	593516	26-Mar-1984	4631636		HIGH DENSITY PACKAGING TECHNIQUE FOR ELECTRONICS SYSTEM
SE-277	,	Granted	694096	23-Jan-1985	4632557	1 1	ALIGNMENT TARGET IMAGE ENHANCEMENT FOR MICROLITHOGROPHY PROCESS
SE278		Granted	676846	01-Feb-1985	4639896	1	REDUND ROW DECODING FOR PROGRAMMABLE DEVICES
SE280		Granted	788585	17-Oct-1985	4734885		PROGRAMMING ARRANGEMENT FOR PROGRAMMABLE DEVICES
SE281	A	Granted	914524	03-Oct-1986	4757363	<b> </b>	DIFFUSED RESISTOR AND NPN TRANSISTOR ESD PROTECTION NETWORK FOR MOS CIRCUITS WITH SCR PREVENTION GUARD RINGS
SE282		Granted	598985	11-Apr-1984	4613772	23-Sep-1986	CURRENT COMPENSATION FOR LOGIC GATES
SE286		Granted	620728	14-Jun-1984	4591826	27-May-1986	GRAY CODE DAC LADDER
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¿ ClientRet	SubCa	de la status	A Anna	FIDAC	<b>对</b> 区内的	- lesigne-	
SE289	A	Granted	. 07/302386	27-Feb-198	39 4941027	10-Jul-199	HIGH VOLTAGE MOS STRUCTURE
SE288	ļ	Granted	675222	27-Nov-198	4 4618743	21-Oct-198	6 MONOLITHIC TRANSIENT PROTECTOR
SE-298		Granted	625222	27-Jun-198	4 4665327	12-May-198	7 CURRENT TO VOLTAGE INTERFACE
SE299 _		Granted	903785	05-Sep-198	6 4757528	12-Jul-198	8 THERMALLY COUPLED INFORMATION TRANSMISSION ACROSS ELECTRICAL ISOLATION BOUNDARIES
SE292		Granted	720679	08-Apr-198	5 4644383	17-Feb-198	SUBCOLLECTOR FOR OXIDE AND JUNCTION ISOLATED IC'S
SE-291		Granted	620835	15-Jun-1984	4599789	15-Jul-1986	PROCESS OF MAKING TWIN WELL VLSI CMOS
SE300		Granted	630280	12-Jun-1984	4560948	24-Dec-1985	CIRCUIT FOR INCREASING VOLTAGE GAIN
SE-301/302 ,		Granted	669787	09-Nov-1984	4595608	17-Jun-1986	METHOD FOR SEL DEPOS OF TUNGSTEN ON SILICON DEVICES
SE210B	<del></del> .	Granted	431229	30-Sep-1982	4401940	30-Aug-1983	VOLTAGE EQUALIZER BRIDGE
SE308		Granted	673386	20-Nov-1984	4633107		A CMOS POWER-UP RESET CIRCUIT FOR GATE ARRAYS AND STANDARD CELLS
SE310		Granted	777685	19-Sep-1985	4644191		PROGRAM ARRAY LOGIC W/SHARED PRODUCT TERMS
SE311		Granted	777686	19-Sep-1985	4644192		PROGRAMMABLE ARRAY LOGIC WISHARED PROD TERMS J-K REG OUTPUTS
SE314/315		Granted	771846	09-Sep-1985	4684055		METHOD OF A SEL SOLDER UNDERSIDE OF SUBSTRATE HAVING LEADS
SE-317		Granted	828186	11-Feb-1986	4666737	19-May-1987	VIA METALIZATION USING METAL FILLETS

CONTRACT CONTRACTOR	SibG	se siaus				als Dale	
SE307		Granted	739843	31-May-19	85 4719598	12- Jan-198	88 BIT ADDRESSABLE PROGRAMMING
JCE307		Clantos	700040	3 1-may-13	1 13330	ار بو	ARRANGEMENT
SE-320		Granted	669788	09-Nov-198	34 4608530	26-Aug-198	6 PROGRAMMABLE CURRENT MIRROR
SE-321		Granted.	824870	31-Jan-198	6 4760433	26-Jul-198	8 ESD PROTECTION TRANSISTORS
SE-323 .	C	Granted	07/919001	23-Jul-199	2 5448100	05-Sep-199	5 BREAKDOWN DIODE STRUCTURE
SE324		Granted	787927	16-Oct-198	5 4665425	12-May-1987	FAB VERTICAL NPN/PNP BIPOLAR TRANS IN MONOLITHIC SUBSTRATE TH FT IN THE 1-GHZ RANGE
SE324	A	Granted	000377	05-Jan-198	7 4717680	05-Jan-1988	FAB VERTICAL NPN/PNP BIPOLAR TRANS IN MONOLITHIC SUBSTRATE TH FT IN THE 1-GHZ RANGE
SE-329		Granted	702601	19-Feb-1985	4694313	15-Sep-1987	CONDUCTIVITY MODULATED SEMICONDUCTOR STRUCTURE
SE-330	A	Granted	048482	05-May-1987	4713681	15-Dec-1987	STRUCTURE FOR HIGH BREAKDOWN PN DIODE WITH RELATIVELY HIGH SURFACE DOPING
SE332	A	Granted	944399	19-Dec-1986	4754388	1 1	REG CIRCUIT FOR CONVERT ALTERNATE INPUT TO A CONSTANT DIRECT OUTPUT
SE-336		Granted	798668	15-Nov-1985	4703566		COVEYOR FOR VAPOR PHASE REFLOW SYSTEM OR NON-METALLIC LEAD COATINGS ON SEMICONDUCTOR PACKAG
SE-344		Granted	643362	22-Aug-1984	4578859	01-Apr-1986	IMPLANT MASK REVERSAL
SE341		Granted	723581	12-Apr-1985	4606936		STRESS FREE DIELECTRIC ISOLATION TECHNOLOGY
SE346		Granted	777269	18-Sep-1985	4807012		IC WHICH ELIMINATES SUPPORT BIAS INFLUENCE ON DIELECTRICALLY ISOLATED COMPONENTS
SE346	A	Granted	07/311812	17-Feb-1989	4923820	08-May-1990 I	C WHICH ELIMINATES SUPPORT BIAS INFLUENCE ON DIELECTRICALLY ISOLATED COMPONENTS

SE-705  Granted 768326 22-Aug-1985 4716071 29-Dec-1987 METHOD FOR ENSURING ADHESION OF CHEMICALLY VAPOR DEPOSITED OXIDE TO GOLD INTEGRATED CIRCUIT INTERCONNECT LINES  SE-705  A Granted 045526 04-May-1987 4713260 15-Dec-1987 METHOD FOR ENSURING ADHESION OF CHEMICALLY VAPOR DEPOSITED OXIDE TO GOLD INTEGRATED CIRCUIT INTERCONNECT LINES  SE-385  Granted 896097 13-Aug-1986 4755770 05-Jul-1988 LOW NOISE CURRENT SPECTRAL DENSITY INPUT BIAS CURRENT CANCEL SCHEME  SE-394  Granted 723239 15-Apr-1985 4705597 10-Nov-1987 PHOTORESIST TAPERING PROCESS	- Gliegika	8 1.G	se / Shie	y. And the	STATE OF THE STATE	N. Palify	/ Isobate	
SE-352   Granted   793316   31-Oct-1985 4682059   21-Jul-1987 A COMPARATOR INPUT STAGEFOR INTERFACE WITH SIGNAL CURRENT	SE-358		Granted	774474	10-Sep-198	35 4677321	30-Jun-198	7 A TTL COMPATIBLE INPUT BUFFER
SE-359   Granted   782691   01-Oct-1986 4650696   17-Mar-1987 PROCESS USING TUNGSTEN FOR MULTILEVEL METALIZATION							ų	. ·
SE-359   Granted   782691   01-Oct-1986 4650696   17-Mar-1987 PROCESS USING TUNGSTEN FOR MULTILEVEL METALIZATION	SE352	·	Granted	793316	31-Oct-198	5 4682059	21-Jul-198	7 A COMPARATOR INPUT STAGEFOR INTERFACE
SE-363   Granted   936609   D1-Dec-1986 4761853   D1-Nov-1988 METHOD OF ETCH & ENHANC SILICON ETCHING CAP OF ALKALI HYDROXIDE THROUGH ADD OF POSITIVE VALENCE IMPURITY IONS								
SE-363   Granted   936609   D1-Dec-1986 4761853   D1-Nov-1988 METHOD OF ETCH & ENHANC SILICON ETCHING CAP OF ALKALI HYDROXIDE THROUGH ADD OF POSITIVE VALENCE IMPURITY IONS								
SE-363   A   Granted   187268   28-Apr-1988   4859280   22-Aug-1989   METHOD OF ETCH & ENHANC SILLOON ETCHING CAP OF ALKALI HYDROXIDE THROUGH ADD OF POSITIVE VALENCE IMPURITY IONS	SE-359	ŀ	Granted	782691	01-Oct-198	5 4650696	17-Mar-1987	
SE-363   A   Granted   187268   28-Apr-1988   4859280   22-Aug-1989   METHOD OF ETCH & ENHANC SILLOON ETCHING CAP OF ALKALI HYDROXIDE THROUGH ADD OF POSITIVE VALENCE IMPURITY IONS						-		
POSITIVE VALENCE IMPURITY IONS	SE-363		Granted	936609	01-Dec-198	6 4781853	01-Nov-1988	· ·
CAP OF ALKALI HYDROXIDE THROUGH ADD OF POSITIVE VALENCE IMPURITY IONS						i.		)
POSITIVE VALENCE IMPURITY IONS	SE-363	Α	Granted	187268	28-Apr-1988	4859280	22-Aug-1989	
DUAL TAPERED VIA ETCH								· ·
DUAL TAPERED VIA ETCH	SE-370	-	Granted	723238	15-Apr-1985	4705596	10-Nov-1987	SIMULTANEOUS PLASMA SCULPTURING AND
SE704   Granted   771712   03-Sep-1985 4624749   25-Nov-1986   ELECTRODEPOSITION OF SUBMICROMETER METALLIC INTERCONNECT FOR INTEGRATED CIRCUITS								
SE704   Granted   771712   03-Sep-1985 4624749   25-Nov-1986   ELECTRODEPOSITION OF SUBMICROMETER METALLIC INTERCONNECT FOR INTEGRATED CIRCUITS								
METALLIC INTERCONNECT FOR INTEGRATED CIRCUITS	SE377		Granted	782689	01-Oct-1985	4636744	13-Jan-1987	FRONT END OF AN OPERATIONAL AMPLIFIER
METALLIC INTERCONNECT FOR INTEGRATED CIRCUITS						į		
SE-705   Granted   768326   22-Aug-1985 4716071   29-Dec-1987   METHOD FOR ENSURING ADHESION OF CHEMICALLY VAPOR DEPOSITED OXIDE TO GOLD INTEGRATED CIRCUIT INTERCONNECT LINES	SE704		Granted	771712	03-Sep-1985	4624749	1 1	
CHEMICALLY VAPOR DEPOSITED OXIDE TO GOLD INTEGRATED CIRCUIT INTERCONNECT LINES							i i	
SE-705	SE-705	<del> </del>	Granted	768326	22-Aug-1985	4716071		·
CHEMICALLY VAPOR DEPOSITED OXIDE TO GOLD INTEGRATED CIRCUIT INTERCONNECT LINES			1					
CHEMICALLY VAPOR DEPOSITED OXIDE TO GOLD INTEGRATED CIRCUIT INTERCONNECT LINES	SF-705	A	Granted	045526	04-May-1987	4713260	15-Dec-1987	METHOD FOR ENSURING ADHESION OF
SE-385   Granted   896097   13-Aug-1986 4755770   05-Jul-1988   LOW NOISE CURRENT SPECTRAL DENSITY INPUT BIAS CURRENT CANCEL SCHEME								CHEMICALLY VAPOR DEPOSITED OXIDE TO GOLD
BIAS CURRENT CANCEL SCHEME  SE-394 Granted 723239 15-Apr-1985 4705597 10-Nov-1987 PHOTORESIST TAPERING PROCESS  Granted 831384 07-Jan-1986 4823173 18-Apr-1989 HIGH VOLTAGE LATERAL MOS STRUCTURE WITH DEPLETED TOP GATE REGION  SE-395 B Granted 07/705509 24-May-1991 5264719 23-Nov-1993 HIGH VOLTAGE LATERAL MOS STRUCTURE WITH								
Granted 831384 07-Jan-1986 4823173 18-Apr-1989 HIGH VOLTAGE LATERAL MOS STRUCTURE WITH DEPLETED TOP GATE REGION  SE-395 B Granted 07/705509 24-May-1991 5264719 23-Nov-1993 HIGH VOLTAGE LATERAL MOS STRUCTURE WITH	SE-385		Granted	896097		4755770		1
Granted 831384 07-Jan-1986 4823173 18-Apr-1989 HIGH VOLTAGE LATERAL MOS STRUCTURE WITH DEPLETED TOP GATE REGION  SE-395 B Granted 07/705509 24-May-1991 5264719 23-Nov-1993 HIGH VOLTAGE LATERAL MOS STRUCTURE WITH							·	
DEPLETED TOP GATE REGION  SE-395 B Granted 07/705509 24-May-1991 5264719 23-Nov-1993 HIGH VOLTAGE LATERAL MOS STRUCTURE WITH	SE-394		Granted	723239	15-Apr-1985	4705597	10-Nov-1987	PHOTORESIST TAPERING PROCESS
DEPLETED TOP GATE REGION  SE-395 B Granted 07/705509 24-May-1991 5264719 23-Nov-1993 HIGH VOLTAGE LATERAL MOS STRUCTURE WITH				1.		-		·
SE-395 B Granted 07/705509 24-May-1991 5264719 23-Nov-1993 HIGH VOLTAGE LATERAL MOS STRUCTURE WITH	SE-395		Granted	831384	07-Jan-1986	4823173	18-Apr-1989 F	HIGH VOLTAGE LATERAL MOS STRUCTURE WITH
							Į.	DEPLETED TOP GATE REGION
	SF_305	В	Granted	07/706500	24 May 1001	264710	22 Nov. 40021	HIGH VOI TAGE LATERAL MOS STRUCTURE MUTH
	JJ3J	٥	Granieu	011103509	24-way-1991)	204/19	ľ	•

DEVICES   DEVI	- Clintrei	StileGar	e Sinius	T APP	(Filtrain)	A Partie	F Jaseria	A THE STATE OF THE
PROGRAM MEMORY DEVICES	SE396		Granted	842272	21-Mar-198	6 4733168		OVERHEAD TEST CIRCUITRY IN PROGRAMMABLE
SE-383         Granted         798242         08-Nov-1985 4720739         19-Jan-1988 DENSE REDUCED LEAKAGE CMOS STRUC           SE-384         A         Granted         110775         21-Oct-1987 4873564         10-Oct-1989 CONDUCTIVITY-MODULATED FET WITH IMPROVED PINCH OFF-ON PERFORMANCE           SE405         Granted         763861         09-Aug-1985 4686384         11-Aug-1987 FUSE PROGRAMMABLE DC LEVEL GENERAL DEVELOPMENT OF PROGRAM FUSE LINKS           SE406         Granted         790115         22-Oct-1985 4734886         29-Mar-1988 AUX WORDLINE DRIVER FOR EFFECTIVE CONTROL PROGRAM FUSE LINKS           SE407         Granted         754711         15-Jul-1985 4675798         23-Jun-1987 DRECT COUPLED SWITCH PWR SUPPLY WITCH	SE397		Granted	842267	21-Mar-198	6 4698589	06-Oct-1987	
SE-384         A         Granted         110775         21-Oct-1987 4873564         10-Oct-1988 CONDUCTIVITY-MODULATED FET WITH IMPROVED PINCH OFF-ON PERFORMANCE           SE-405         Granted         763861         09-Aug-1985 4686384         11-Aug-1987 FUSE PROGRAMMABLE DC LEVEL GENERA           SE-406         Granted         790115         22-Oct-1985 4734886         29-Mar-1988 AUX WORDLINE DRIVER FOR EFFECTIVE CONTROL PROGRAM FUSE LINKS           SE-407         Granted         754711         15-Jul-1985 4675798         23-Jun-1987 DIRECT COUPLED SWITCH PWR SUPPLY W SCR SWITCH ELEMENT           SE412         Granted         782690         01-Oct-1985 4636743         13-Jan-1987 FRONT END STAGE OF AN OPERATIONAL AMPLIFIER           SE412         A         Granted         917441         07-Oct-1986 4783637         08-Nov-1988 FRONT END STAGE OF AN OPERATIONAL AMPLIFIER           SE-413         Granted         813718         27-Dec-1985 4683485         28-Jul-1987 TECH FOR INCREASING GATE-DRAIN BKDN VOLTAGE OF ION-IMPLANT JFET           SE-709         A         Granted         019697         27-Feb-1987 4814285         21-Mar-1989 METHOD FOR FORMING PLANARIZED INTERCONNECT LEVEL USING SELECTIVE DEPOSITION AND ION IMPLANTATION           SE-710         C         Granted         07/928992         12-Aug-1992 5247199         21-Sep-1993 PROCESS FOR FORMING TWIN WELL CMOS INTEGRATED CIRCUITS	SE399		Granted	07/347574	05-May-198	9 5028824	02-Jul-1991	PROGRAMMABLE DELAY CIRCUIT
MPROVED PINCH OFF-ON PERFORMANCE	SE-383		Granted	798242	08-Nov-198	4720739	19-Jan-1988	DENSE REDUCED LEAKAGE CMOS STRUCTURE
SE406   Granted   790115   22-Oct-1985 4734886   29-Mar-1988   AUX WORDLINE DRIVER FOR EFFECTIVE CONTROL PROGRAM FUSE LINKS	SE-384	A	Granted	110775	21-Oct-1987	4873564		CONDUCTIVITY-MODULATED FET WITH IMPROVED PINCH OFF-ON PERFORMANCE
CONTROL PROGRAM FUSE LINKS	SE405		Granted	763861	09-Aug-1985	4686384	11-Aug-1987	FUSE PROGRAMMABLE DC LEVEL GENERATOR
SE412   Granted   782690   01-Oct-1985 4636743   13-Jan-1987 FRONT END STAGE OF AN OPERATIONAL AMPLIFIER	SE406		Granted	790115	22-Oct-1985	4734886		
AMPLIFIER  A Granted 917441 07-Oct-1986 4783637 08-Nov-1988 FRONT END STAGE OF AN OPERATIONAL AMPLIFIER  SE-413 Granted 813718 27-Dec-1985 4683485 28-Jul-1987 TECH FOR INCREASING GATE-DRAIN BKDN VOLTAGE OF ION-IMPLANT JFET  SE-709 A Granted 019697 27-Feb-1987 4814285 21-Mar-1989 METHOD FOR FORMING PLANARIZED INTERCONNECT LEVEL USING SELECTIVE DEPOSITION AND ION IMPLANTATION  SE-710 C Granted 07/928992 12-Aug-1992 5247199 21-Sep-1993 PROCESS FOR FORMING TWIN WELL CMOS INTEGRATED CIRCUITS	SE407		Granted	754711	15-Jul-1985	4675798		
AMPLIFIER  AMPLIFIER	SE412		Granted	782690	01-Oct-1985	4636743		
VOLTAGE OF ION-IMPLANT JFET  VOLTAGE OF ION-IMPLANT JFET  VOLTAGE OF ION-IMPLANT JFET  VOLTAGE OF ION-IMPLANT JFET  VOLTAGE OF ION-IMPLANT JFET  VOLTAGE OF ION-IMPLANT JFET  VOLTAGE OF ION-IMPLANT JFET  VOLTAGE OF ION-IMPLANT JFET  VOLTAGE OF ION-IMPLANT JFET  VOLTAGE OF ION-IMPLANT JFET  VOLTAGE OF ION-IMPLANT JFET  VOLTAGE OF ION-IMPLANT JFET  INTERCONNECT LEVEL USING SELECTIVE DEPOSITION AND ION IMPLANTATION  SE-710  C  Granted  07/928992  12-Aug-1992 5247199  21-Sep-1993 PROCESS FOR FORMING TWIN WELL CMOS INTEGRATED CIRCUITS	SE412	A	Granted	917441	07-Oct-1986	4783637		
INTERCONNECT LEVEL USING SELECTIVE DEPOSITION AND ION IMPLANTATION  SE-710 C Granted 07/928992 12-Aug-1992 5247199 21-Sep-1993 PROCESS FOR FORMING TWIN WELL CMOS INTEGRATED CIRCUITS	SE-413			1 1	27-Dec-1985	4683485		
INTEGRATED CIRCUITS	6E-709	<b>A</b>	Granted		27-Feb-1987	4814285	1	NTERCONNECT LEVEL USING SELECTIVE
E-710 D Granted 08/080744 22-Jun-1993 5429958 04-Jul-1995 PROCESS FOR FORMING TWIN WELL CMOS	6E-710 (	C	Granted	07/928992	12-Aug-1992	5247199		
INTEGRATED CIRCUITS	E-710 [	D	Granted	08/080744	22-Jun-1993	5429958	1	

o Cligata	of y Subc	:SE - SAU	AT AT E	. PariDale s		A STESOFICE	
SE415		Granted	013851	12-Feb-198	37 4761570	02-Aug-198	88 PROGRAM LOGIC DEVICE WITH PROG SIGNAL
						,	INHIB AND INVERSION MEANS
			ŀ				
SE416		Granted	051386	19-May-198	7 4823300	18-Apr-198	9 PERFORMING BINARY MULTI-PLICATION USING
							MINIMAL PATH ALGORITHM
05740							
SE713		Granted	792988	30-Oct-198	5 4669884	02-Jun-198	7 VARIABLE WAVELENGTH OPTICAL ALIGN SYSTEM
SE418		Granted	901841	28-Aug-198	6 4728820	01-Mar-198	8 LOGIC STATE TRANS DETECTION CIRCUIT FOR
						]	CMOS DEVICES
							}
SE421		Granted	046691	07-May-1987	4780688	25-Oct-1988	BLARGE SIGNAL OUTPUT CURRENT
							ENHANCEMENT FOR A DIFFERENTIAL PAIR
SE425		Granted	786701	09-Oct-1985	4050050	44.4 - 400	ANTERNAL OVER LANGUE ANTERNAL OF THE PARTY O
JGE423		Gianteu	780701	09-001-1965	4030233	14-Apr-1987	INTERNAL SYNCH MATRIX STRUCT USED IN EXTER ASYNC PROG DEVICES
ļ					<u> </u>		
SE714		Granted	874393	16-Jun-1986	4702967	27-Oct-1987	MULTILAYER MULTIPHASE TITANIUM/NITROGEN
				ŀ			ADHESION/DIFFUSIONS TRUCTUN A GOLD-BASED MICROCIRCUIT INTERCONNECT METALLIZATION
SE-716	A	Granted	181718	14-Apr-1988	4970573	13-Nov-1990	SELF-PLANARIZED ELECTROPLATED GOLD INTERCONNECT LAYER
	1 .						INTERCORNECT BATER
SE-717	A	Granted	224320	26-Jul-1988	4818725	04-Apr-1989	A PLANAR GATE STRUCTURE
		Jordan, G	12.020	20-041-1000	4010723	04-Api-1303	AT DANAK GATE STRUCTURE
		-	ŀ				·
SE718		Granted	841297	19-Mar-1986	4702000	1 1	TECHNIQUE FOR ELIMINATION OF POLYSILICON
· · · · · · · · · · · · · · · · · · ·							STRINGERS IN DIRECT MOAT FIELD OXIDE STRUCTURE
SE718	A	Granted	084556	11-Aug-1987	4908683	1	TECHNIQUE FOR ELIMINATION OF POLYSILICON STRINGERS IN DIRECT MOAT FIELD OXIDE
				. ]			STRUCTURE
SE441		Granted	896103	13-Aug-1986	4701644	20-Oct-1987	LOW POWER SENSE AMPLIFIER
				15 / 125 / 1000		25 050 1007	ESTATE OF THE CONTRACT OF THE
SE451		Granted	027940	19-Mar-1987	1804865		FAST VOLTAGE REFERENCE STABILIZATION
							rechnique
		<u> </u>					
SE455		Granted	07/437472	15-Nov-1989 5	5051949	24-Sep-1991	CONTENT ADDRESSABLE MEMORY DEVICE
		<u> </u>	il		1		

2 Cleare	f 8.60	ලේ වීම නික්ෂ	April 1	(FIIDbir)		a la la Dale d	
SE-456		Granted	118251	09-Nov-198	7 4855625	08-Aug-198	9 OPERATIONAL AMPLIFIER HAVING LOW DC
						در ا	CURRENT INPUT CIRCUIT
SE-438		Granted	000778	06-Jan-198	7 4789426	06-Dec-198	8 PROCESS FOR PERFORM VARIABLE SELEC
					11.00.20	1 00 200 100	POLYSILICON ETCH
	. ]				, ·		
SE-457	A	Granted	07/819748	13-Jan-199	2 5214329	25-May-199	3 BIAS CURRENT MODULATION FOR
				1		20	DIFFERENTIALLY COUPLED TRANSISTOR CIRCUIT
						:	
SE-466		Granted	919465	16-Oct-198	4708747	24-Nov-198	7 DIELECTRIC FOR LASER TRIMMING
	- [				],		
	}						1.
SE-466	В	Granted	07/296855	13-Jan-1989	4839711	13-Jun-1989	DIELECTRIC FOR LASER TRIMMING
				1 .		1	
				·			
SE-472		Granted	042135	24-Apr-1987	4771016	13-Sep-1988	USING A RAPID THERMAL PROCESS FOR MFG
							WAFER BONDED SOL SEMIC ONDUCT
1	-						
SE723		Granted	947749	30-Dec-1986	4786608	22-Nov-1988	TECH FOR FORMING ELEC FIELD SHIELD LAYER
						1	IN OXY-IMPLANT SILICON SUR IN OXYGEN-
						ĺ	IMPLANTED SILICON SUBSTRATES
SE-477		Granted	523427	15-May-1990	5014108	07-May-1991	METHOD OF MAKING SILICON MESFET FOR
	1	-		:		]	DIELECTRICALLY ISOLATED INTEGRATED
						]	CIRCUITS
SE-477	A	Granted	07/606193	31-Oct-1990	5306650	26-Apr-1994	METHOD OF MAKING SILICON MESFET FOR
		<i>'</i>		•		i i	DIELECTRICALLY ISOLATED INTEGRATED CIRCUITS
						]	CIRCUITS
SE-480		Granted	151184	01-Feb-1988	4912053		ION IMPLANTED JEET WITH SELF-ALIGNED
	•				12 1		SOURCE AND DRAIN
SE-481		Granted	07/387534	31-Jul-1989	4968900		PROGRAMMABLE SPEED/POWER ARRANGEMENT
					. •	i I	FOR INTEGRATED DEVICES HAVING LOGIC MATRICES
					, .	l	WATNICES
SE487	<u> </u>	Granted	07/301835	26-Jan-1989	4876579		LOW TOP GATE RESISTANCE GATE JFET
	1	· ·				[	STRUCTURE
SE489/491		Granted	057398	12-May-1987	4795718	03-Jan-1989	SELF-ALIGNED CONTACT FOR MOS PROCESSING
						ĺ	
SE-490	1	Granted	062309	15-Jun-1987	1752591		SELF-ALIGNED CONTACTS FOR BIPOLAR
	1					ļf	PROCESS
							j
		1	l if	1	j	. 1	

s ClientRe	s Sub	Case Prisialis		Tillede iv	Pai	/ IssDare.	
SE-725	Carl Maria	Granted	055356	29-May-198	7 4753851	28-Jun-198	8 MULTI LAYER TUNGSTEN/TITANIUM
	1	1.	Ī			, i	TITANIUM/NITRIDE ADHESION/DIFFUSION BARRI
•							LAYER STRUCT FOR GOLD-BASE MICROCIRCUIT
SE-500		Granted	O7/403865	07-Sep-198	9 5051619	24-Sep-199	1 PREDRIVE CIRCUIT HAVING LEVEL SENSING
		1 .		1		ļ	CONTROL
				''		}	
SE-500	Α	Granted	90/002598	10-Feb-199	B1 5051619	02-Mar-199	3 PREDRIVE CIRCUIT HAVING LEVEL SENSING
	1		[			İ	CONTROL
					İ	İ	
SE-505	Α	Granted	07/334148	06-Apr-1989	4914501	03-Apr-199	VERTICAL CONTACT STRUCTURE
· [							
SE-508		Granted	025539	13-Mar-1987	4851257	25-Jul-1989	PROCESS FOR THE FABRICATION OF A VERTICAL
							CONTACT
SE-511		Granted	025435	13-Mar-1987	5066995	19-Nov-1991	DOUBLE LEVEL CONDUCTOR STRUCTURE
-		1					
	4			-			
SE-516		Granted	075641	20-Jul-1987	4818901	04-Арг-1989	CONTROLLED SWITCHING CMOS OUTPUT BUFFER
							BOTTER
	<u>.</u>			20.4. 1007			
SE-727	1	Granted	036508	09-Apr-1987	4812962	14-Mar-1989	AREA FEATURE SORTING MECHANISM FOR NEIGHBORHOOD-BASED PROXIMITY
	1	ļ					CORRECTION IN LITHOGRAPHY PROCESING OF
	4		1057045	40.0 4.4000	1007507		INTEGRATED CIRCUIT PATTERNS
SE-525	1	Granted	257015	13-Oct-1988	489/56/	30-Jan-1990	FAST LEVEL TRANSLATOR CIRCUIT
		İ					
SE-526	<u> </u>	Granted	049637	13-May-1987	482408C	09 Aug 1090	BONDING TECHNIQUE TO JOIN TWO OR MORE
32-320		Giarned	049037	13-May-1307	4034900		SILICON WAFERS
	-				··		
SE-529	1.	Granted	067838	29-Jun-1987	4851078	25. Jul-1989	DIELECTRIC ISOLATION PROCESS USING DOUBLE
OL 323		.:	001000	25-5011-1501			WAFER BONDING
SE-533	<del>                                     </del>	Granted	213823	03-Jun-1988	4857764	15-Aug-1989	CURRENT COMPENSATED PRECHARGED BUS
				02 03 1000		.sag 1000	
		1.		ļ			
SE-541	-	Granted	092975	03-Sep-1987	4897362	30-Jan-1990	DOUBLE EPITAXIAL METHOD OF FAB
·							SEMICONDUCTOR DEVICES ON BONDED WAFERS
			]		.		Ì
SE-543	<del>                                     </del>	Granted	106071	07-Oct-1987	1882698	21-Nov-1989	CELL BASED ALU WITH TREE STRUCTURED
•							CARRY, INVERT LOGIC AND BALANCED LOADING
				}			
			<u>_</u>		<u>_</u>	<u>_</u>	

S Cliente	Selic	ese y Sielus	STATE OF THE	S Por all Dales		istae:	
SE-544		Granted	124807	24-Nov 10	37 5047974	10 Sop 100	OLICELL BASED ADDED WEBER CADUCATIONS
3L-344		Granted	124607	24-1100-196	57 5047974	10-Sep-198	21 CELL BASED ADDER WITREE STRUCTURED CARRY INVERTING LOGIC AND BALANCED LOADING
SE-547		Granted	164342	04-Mar-198	8 4948746	14-Aug-199	ISOLATED GATE MESFET AND METHOD OF MAKING AND TRIMMING
SE-547	A	Granted	07/537936	14-Jun-199	0.5040277	22.4400	AUGOLATED CATE MEDEET AND METHOD OF
) 			07/337936	14-3011-199	0 3010377	23-Apr-199	1 ISOLATED GATE MESFET AND METHOD OF MAKING AND TRIMMING
SE-553		Granted	132186	14-Dec-198	7 4868778	19-Sep-198	SPEED ENHANCEMENT FOR MULTIPLIERS USING MINIMAL PATH ALGORITHM
SE-555	1:	Granted	07/382388	20-Jul-1989	5081063	14-Jan-1992	METHOD OF MAKING EDGE-CONNECTED
·							INTEGRATED CIRCUIT STRUCTURE
SE-555	В	Granted	07/802882	06-Dec-1991	5185292	09-Feb-1993	METHOD OF MAKING EDGE-CONNECTED INTEGRATED CIRCUIT STRUCTURE
SE-557	В	Granted	07/834439	12-Feb-1992	5266135	30-Nov-1993	WAFER BONDING USING TRAPPED OXIDIZING VAPOR
SE-557	С	Granted	08/137293	14-Oct-1993	5334273	02-Aug-1994	WAFER BONDING USING TRAPPED OXIDIZING VAPOR
SE-560		Granted	07/376019	06-Jul-1989	4929566		METHOD OF MAKING DIELECTRICALLY ISOLATED INTEGRAT CIRCUITS USING OXYGEN IMPLAN AND EXPITAXIAL GROWTH
SE-562		Granted	103620	30-Sep-1987	4801065		CHIP CARRIER SOLDERING PALLET SOLDER LEVELING PIN
SE-565		Granted	195265	18-May-1988	4949296		METHOD AND APPARTUS FOR COMPUTING SQUARE ROOTS OF BINARY NUMBERS
SE-567		Granted	07/467590	19-Jan-1990	5070388	03-Dec-1991	TRENCH-RESIDENT INTERCONNECT STRUCTURE
SE-568		Granted	263189	27-Oct-1988	1879520		HIGH ACCURACY CURRENT SOURCE AND HIGH ACCURACY TRANSCONDUCTANCE STAGE
SE-572		Granted	289747	27-Dec-1988 4	1891604		HIGH SPEED LOW INPUT CURRENT VOLTAGE FOLLOWER STAGE

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SE-573		Granted	07/281546	.08-Dec-198	8 4900689	13-Feb-199	METHOD OF FABRICATION OF DIELECTRICALLY ISOLATED COMPLEMENTARY BIPOLAR DEVICES
SE-574		Granted	07/235543	24-Aug-198	8 4951102	21-Aug-199	0 TRENCH GATE VCMOS METHOD OF MANUFACTURE
SE-574	A	Granted	07/533435	05-Jun-1990	5032529	16-Jul-199	1 TRENCH GATE VCMOS METHOD OF MANUFACTURE
SE-580	A	Granted	07/651460	06-Feb-1991	5120669	09-Jun-1992	2 METHOD OF FORMING SELF-ALIGNED TOP GATE CHANNEL BARRIER REGION IN ION-IMPLANTED JFET
SE-582		Granted	07/370280	23-Jun-1989	4980651	25-Dec-1990	HIGH SPEED, HIGH PRECISION OPERATIONAL AMPLIFIER
SE-583		Granted	07/505899	06-Apr-1990	5148475	15-Sep-1992	REDUCED CONTACT RESISTANCE ON A SLIC
SE-586		Granted	07/340705	20-Apr-1989	4982194	01-Jan-1991	BACK-SAMPLING CHARGE REDISTRIBUTION ANALOG TO DIGITAL CONVERTER
SE-586	* A	Granted	07/587089	24-Sep-1990	5059982		BACK-SAMPLING CHARGE REDISTRIBUTION ANALOG TO DIGITAL CONVERTER
SE-587	A	Granted	07/416419	03-Oct-1989	5021359		RADIATION HARDENED COMPLEMENTARY TRANSISTOR INTEGRATED CIRCUITS
SE-594/600		Granted	07/289748	27-Dec-1988	4888741	1	MEMORY WITH CACHE REGISTER INTERFACE STRUCTURE
SE-603		Granted	195273	18-May-1988	1916497		INTEGRATED CIRCUITS INCL PHOTO-OPTICAL DEVICES AND PRESSURE TRANSDUCERS AND METHOD OF FABRICATION
SE-603	A	Granted	07/465314	12-Jan-1990 5	037765	<u> </u>	INTEGRATED CIRCUITS INCL PHOTO-OPTICAL DEVICES AND PRESSURE TRANSDUCERS AND METHOD OF FABRICATION
SE-603	С	Granted	07/606155	31-Oct-1990 5	070596	ļ	NTEGRATED CIRCUITS INCL PHOTO-OPTICAL DEVICES AND PRESSURE TRANSDUCERS AND METHOD OF FABRICATION
SE-608		Granted	282064	09-Dec-1988 4	968628		METHOD OF FABRICATING BACK DIFFUSED BONDED OXIDE SUBSTRATE

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SE-617		Granted	271656	16-Nov-198	8 4893088	09-Jan-199	0 TRANSIMPEDANCE FOCAL PLANE PROCESSOR
SE-600		Granted	266812	03-Nov-198	8 4937774	26-Jun-199	DEAST IMAGE PROCESSING ACCELERATOR FOR REAL TIME IMAGE PROCESSING APPLICATIONS
SE563		Granted	07/307944	09-Feb-198	9 4891606	02-Jan-1990	PHOTOCURRENT COMPENSATION USING ACTIVE DEVICES
SE-570		Granted	07/272908	18-Nov-1988	3 4879523	07-Nov-1989	HIGH ACCURACY, HIGH IMPEDANCE DIFFERENTIAL TO SINGLE-ENDED CURRENT CONVERTER
SE-626		Granted	07/313435	22-Feb-1989	4908566	13-Mar-1990	VOLTAGE REGULATOR HAVING STAGGERED POLE-ZERO COMPENSATION NETWORK
SE-619		Granted	07/357898	26-May-1989	4929923	29-May-1990	THIN FILM RESISTORS AND METHOD OF TRIMMING
SE-620		Granted	07/336787	13-Apr-1989	4933648	12-Jun-1990	CURRENT MIRROR EMPLOYING CONTROLLED BYPASS CIRCUIT
SE-631	8	Granted	07/361439	05-Jun-1989	4970677		FULL ADDER CIRCUIT WITH IMPROVED CARRY AND SUM LOGIC GATES
SE-637	A	Granted	07/973932	24-Nov-1992	5262976	16-Nov-1993	PLURAL BIT RECORDING MULTIPLIER
SE-639	A	Granted	07/972510	06-Nov-1992	5469556		RESOURCE ACCESS SECURITY SYSTEM FOR CONTROLLING ACCESS TO RESOURCES OF A DATA PROCESSING SYSTEM
SE-642		Granted	07/436247	14-Nov-1989	5039888	. 1	METHOD AND CIRCUIT ARRANGEMENT FOR PROVIDING PROGRAMMABLE HYSTERESIS TO A DIFFERENTIAL COMPARATOR
SE-638		Granted	07/367788	19-Jun-1989	5028973		BIPOLAR TRANSISTOR WITH HIGH EFFICIENT EMITTER
SE-651		Granted	07/405282	11-Sep-1989	1929568		METHOD OF ISOLATING A TOP GATE OF A MESFET AND THE RESULTING DEVICE
SE-651	В	Granted	07/668984	12-Mar-1991	5107312		METHOD OF ISOLATING A TOP GATE OF A MESFET AND THE RESULTING DEVICE

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SE-641		Granted	07/475007	05-Feb-199	5084839	28-Jan-199	VARIABLE LENGTH SHIFT REGISTER
SE-656		Granted	07/447618	08-Dec-198	9 5038248	06-Aug-199	AUTOMATIC ESD PROTECTION DEVICE FOR SEMICONDUCTORS PACKAGES
SE-659		Granted	07/451249	15-Dec-198	9 4979011	18-Dec-199	0 SCR STRUCTURE FOR FAST TURNON SWITCHING
SE-660		Granted	07/457504	27-Dec-1989	9 5060192	22-Oct-199	1 CROSS-POINT SWITCH
SE-661		Granted	07/482803	21-Feb-1990	5265225	23-Nov-1993	3 DSP ADDRESS SEQUENCER
SE-654	A	Granted	07/679182	02-Apr-1991	5248894	28-Sep-1993	SELF-ALIGNED CHANNEL STOP FOR TRENCH- ISOLATED ISLAND
SE-654	₹ B	Granted	08/106160	13-Aug-1993	5436189	25-Jul-1995	SELF-ALIGNED CHANNEL STOP FOR TRENCH- ISOLATED ISLAND
SE-657	*	Granted	07/424917	20-Oct-1989	5008719	16-Apr-1991	DUAL LAYER SURFACE GATE JFET HAVING ENHANCED GATE-CHANNEL BREAKDOWN VOLTAGE
SE-657	A	Granted	07/609801	05-Nov-1990	5118632		DUAL LAYER SURFACE GATE JFET HAVING ENHANCED GATE-CHANNEL BREAKDOWN VOLTAGE
SE-688	A	Granted	07/336632	10-Apr-1989	5070451	03-Dec-1991	FORTH SPECIFIC LANGUAGE MICROPROCESSOR
SE-688	В	Granted	07/745764.	16-Aug-1991	5319757	07-Jun-1994	FORTH SPECIFIC LANGUAGE MICROPROCESSOR
SE-625		Granted	07/431517	03-Nov-1989	5015887		A-B BUFFER CIRCUIT WITH TTL COMPATIBLE OUTPUT DRIVE
SE-675/471	A	Granted	07/651327	05-Feb-1991 5	5306944	<b> </b>	SEMICONDUCTOR STRUCTURE WITHIN DI SLANDS HAVING BOTTOM PROJECTION FOR CONTROLLING DEVICE CHARACTERISTICS
E-663-TD	A	Granted	07/755314	05-Sep-1991 5	327006	F	THIN, DIELECTRICALLY ISOLATED ISLAND RESIDENT TRANSISTOR STRUCTURE HAVING LOW COLLECTOR RESISTANCE

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SE-670	A	Granted	07/717347	18-Jun-199	1 5218321	08-Jun-199	3 LOW OFFSET UNITY GAIN BUFFER AMPLIFIER
						-	
SE-682	A	Granted	07/640041	11 lon 100	1 5100205	20 14 400	2 PUOTOLITUO PARUIO FORMATION OF DIE TO
SE-002		Granted		11-Jan-199	115198385	30-Mar-199	3 PHOTOLITHOGRAPHIC FORMATION OF DIE-TO- PACKAGE AIRBRIDGE
					1		
SE-664		Granted	07/561821	02-Aug-1990	51.13361	12-May-199	SIN/COS GENERATOR IMPLEMENTATION
							•
SE-665	<del> </del>	Granted	07/490316	08-Mar-1990	5034343	23-Jul-199	MANUFACTURING ULTRA-THIN WAFE USING A
						20 0011100	HANDLE WAFER
	<u> </u>						·
SE-655		Granted	07/563276	06-Aug-1990	5057895	15-Oct-1991	TRENCH CONDUCTOR AND CROSSUNDER ARCHITECTURE
				<u> </u>			, morning rocks
SE-655	А	Granted	07/738532	31-Jul-1991	5196373	23-Mar-1993	TRENCH CONDUCTOR AND CROSSUNDER
							ARCHITECTURE
35.055			1				
SE-655	В	Granted	07/916198	17-Jul-1992	5283461	01-Feb-1994	TRENCH CONDUCTOR AND CROSSUNDER ARCHITECTURE
SE-695	<b></b>	Granted	07/498642	26-Mar-1990	5079176	07-Jan-1992	METHOD OF FORMING A HIGH VOLTAGE
							JUNCTION IN A DIELECTRICALLY ISOLATED ISLAND
SE-693		Granted	07/509405	16-Apr-1990	5001331	25 Eab 1002	ULTRA THIN CIRCUIT FABRICATION BY
02 000		Granicu	07/303403	. 10-Api-1990	3091331		CONTROLLED WAFER DEBONDING
							·
SE-692		Granted	07/508568	13-Apr-1990	5015877	14-May-1991	LOW DISTORTION SAMPLE AND HOLD CIRCUIT
					***************************************	· · · · · · · · · · · · · · · · · · ·	
SE-669		Granted	07/529548	29-May-1990	5081410	14-Jan-1992	BAND-GAP REFERENCE
	-						
SE-697		Granted	07/516310	30-Apr-1990	5079734	07-Jan-1992	DIGITAL DECIMATION FILTER
SE-698		Granted	07/624964	10-Dec-1990 5	5151953	29-Sep-1992	SINGLE CHIP 2-D CONVOLVER
SE-699		Granted	07/474172	31-Jan-1990 5	248932		CURRENT MIRROR CIRCUIT WITH CASCODED BIPOLAR TRANSISTORS.
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		<del></del>	<u></u>	<u>L</u>			

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SE-700		Granted	07/474417	31-Jan-199	0 5030862	09-Jul-199	TURNOFF CIRCUIT FOR GATE TURN OFF SCR
SE-666	A	Granted	07/668694	07-Mar-199	1 5081061	14-Jan-199	2 MANUFACTURING ULTRA-THIN DIELECTRICALLY ISOLATED WAFERS
RD 14147		Granted	362682	29-Mar-1982	4429011	31-Jan-198	4 COMPOSITE CONDUCTIVE STRUCTURES AND METHOD OF MAKING SAME
RD 14174		Granted	374586	03-May-1982	4468574	28-Aug-198-	DUAL GATE CMOS TRANSISTOR CIRCUITS HAVING REDUCED ELECTRODE CAPACITANCE
RD 14366		Granted	489613	28-Apr-1983	4471004	11-Sep-1984	METHOD OF FORMING REFRACTORY METAL CONDUCTORS OF LOW RESISTIVITY
RD 14176		Granted	374587	03-May-1982	4472821	18-Sep-1984	DYNAMIC SHIFT REGISTER UTILIZING CMOS DUAL GATE TRANSISTORS
RD 15243		Granted	653274	24-Sep-1984	4584207	22-Apr-1986	METHOD FOR NUCLEATING AND GROWING TUNGSTEN FILMS
RD 15709 ·		Granted	615403	26-Jun-1984	4585493	29-Apr-1986	GRAIN DRIVEN ZONE MELTING OF SILICON FILMS ON INSULATING SUBSTRATES
28-ME-2005	<u> </u>	Granted	687357	28-Dec-1984	4602210	22-Jul-1986	MULTIPLEXED ACCESS SCAN TESTABLE INTEGRATED CIRCUIT
RD 16243		Granted	790911	24-Oct-1985	4638400	·	REFRACTORY METAL CAPACITOR STRUCTURES PARTICULARLY FOR ANALOG INTEGRATED CIRCUIT DEVICES
XRCA83013		Granted	830760	19-Feb-1986 4	1704186		RECESSED OXIDE METHOD FOR MAKING A SILICON ON INSULATOR SUBSTRATE
28-ME-2016		Granted	935372	26-Nov-1986 4	1707455	1 . 1	METHOD OF FABRICATING A TWIN TUB CMOS DEVICE
XRCA82113		Granted	782581	01-Oct-1985 4	725875		MEMORY CELL WITH DIODES PROVIDING RADIATION HARDNESS
RD 17522		Granted	891058	31-Jul-1986 4	729005		METHOD AND APPARATUS FOR IMPROVED METAL INSULATOR SEMICONDUCTOR DEVICE OPERATION

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XRCA82873		Granted	856280	28-Apr-19	36 4735917	05-Apr-198	88 SIICON ON SAPPHIRE INTEGRATED CIRCUITS
						, p	
		j					·
28-ME-2014		Granted	060490	11-Jun-198	4745089	17-May-198	88 SELF ALIGNED BARRIER METAL AND OXIDATION
					.		MASK METHOD
V	ļ						
XRCA82373		Granted	780897	27-Sep-198	15 4751554	14-Jun-198	8 SILICON ON SAPPHIRE INTEGRATED CIRCUIT AND METHOD OF MAKING THE SAME
	<b>-</b>  -						
RD 17954P		Granted	033378	02-Apr-198	7 4751561	14-Jun-198	8 DIELECTRICALLY ISOLATED PMOS, NMOS, PNP
		1.					AND NPN TRANSISTORS ON A SILICON WAFER
	}						·
XRCA82384		Granted	863432	15-May-198	6 4755481	05-Jul-198	METHOD OF MAKING A SILICON ON INSULATOR
	1.						TRANSISTOR
VD0400400	<u> </u>	<u> </u>	1001150	05.0 100	1-00		
XRCA83489		Granted	904156	05-Sep-1986	4/6055/	26-Jul-1988	RADIATION HARD MEMORY CELL CIRCUIT WITH HIGH INVERTER IMPEDANCE RATIO
XRCA83030	<del> </del>	Granted	911423	25-Sep-1986	4775641	04-Oct-1988	METHOD OF MAKING SILICON ON SAPPHIRE
	ļ						SEMICONDUCTOR DEVICES
			1	ļ ·			
RD 17689 🕏		Granted	081076	03-Aug-1987	4782249	01-Nov-1988	STATIC CMOS PROGRAMMABLE LOGIC ARRAY
VDCA02050:	ļ	0		45.0.44007	14005407	44.51.4000	
XRCA83959		Granted	108656	15-Oct-1987	4805187	14-reb-1989	DETERMINATION OF SUBSTRATE TEMPERATURE USED DURING OXYGEN IMPLANTATION OF SIMOX
		}					WAFER
RD 18187P		Granted	137314	23-Dec-1987	4824698	25-Apr-1989	HIGH TEMPERATURE ANNEALING TO IMPROVE
			1.				SIMOX CHARACTERISTICS
35ME02029		Granted	274176	21-Nov-1988	5034789		DIELECTRIC ISOLATION FOR SOI ISLAND SIDE
							WALL FOR REDUCING LEAKAGE CURRENT
2514502020		0	07/044400	45 1 4004	5050050	04 0 4 4004	DIELECTRIC IONI ATION FOR COLUMN AND CIDE
35ME02029	Α	Granted	07/641486	15-Jan-1991	5053353		DIELECTRIC ISOLATION FOR SOI ISLAND SIDE WALL FOR REDUCING LEAKAGE CURRENT
35ME02040		Granted	266756	03-Nov-1988	4956306		METHOD FOR FORMING COMPLEMENTARY
							PATTERNS IN A SEMICONDUCTOR MATERIAL WHILE USING A SINGLE MASKING STEP
				:			WHILE GOING A SHAGLE MASKING STEF
28-IS-003B		Granted	443600	09-Dec-1982	4568913	04-Feb-1986	HIGH SPEED ANALOG TO DIGITAL CONVERTER
		<u> </u>					

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28-IS-005B	25 05227 8.20	Granted	381386	24-May-198	2 4465996	14-Aug-198	HIGH ACCURACY DIGITAL-TO-ANALOG CONVERTER
28-IS-0011		Granted	328518	08-Dec-198	1 4473757	25-Sep-198	ACTIVE CURRENT STEERING NETWORK
28-IS-0013		Granted	328519	08-Dec-198	4433282	21-Feb-1984	MONOLITHIC VOLTAGE DIVIDER
28-IS-0016		Granted	407332	12-Aug-1982	4595906	17-Jun-1986	SCALED ANALOG TO DIGITAL CONVERTER
28-IS-0017		Granted	434893	18-Oct-1982	4547683	15-Oct-1985	HIGH SPEED CHARGE BALANCING COMPARATOR
28-IS-0018		Granted	395670	06-Jul-1982	4535410	13-Aug-1985	POWER SUPPLY FAILURE EARLY WARNING DETECTOR
28-IS-0019	· · ·	Granted	453237	27-Dec-1982	4546324	08-Oct-1985	DIGITALLY SWITCHED ANALOG SIGNAL CONDITIONER
28-IS-0023 .		Granted	340765	19-Jan-1982	4486670		A MONOLITHIC CMOS LOW POWER DIGITAL LEVEL SHIFTER
28-IS-0027		Granted	578535	09-Feb-1984	4641129		HIGH SPEED AND HIGH ACCURACY ANALOG TO DIGITAL CONVERTER
28-IS-0029		Granted	567577	03-Jan-1984	4617473	14-Oct-1986	CMOS BACKUP POWER SWITCHING CIRCUIT
28-IS-0033		Granted	615353	30-May-1984	4652808		IMPROVED EFFICIENCY SWITCHING VOLTAGE CONVERTER
28-IS-0035		Granted	579276	13-Feb-1984	4639715		IMPROVED FLASH ANALOG TO DIGITAL CONVERTER
28-IS-0036		Granted ·	669119	07-Nov-1984	4667164	19-May-1987	MPROVED FREQUENCY RESPONSE AMPLIFIER
28-IS-0039		Granted	714866	22-Mar-1985 4	1787047		ELECTRICALLY ERASABLE FUSED PROGRAMMABLE LOGIC ARRAY

. Clentic	SIL	Gase 3 Status		SVEIDAR.	a Par	( sedere	
28-IS-0040	Augh Promoved	Granted	745580	17-Jun-198	35 4644353	17-Feb-198	7 PROGRAMMABLE INTERFACE
						<b>.</b>	
28-IS-0041	-	Granted	719478	03-Apr-198	5 4702400	: 27 Oct 109	7 NON-RESTRICTED LEVEL SHIFTER
20-13-0041		Granteu	1/194/0	03-Apt-190	15/4/03/199	27-001-198	/INON-RESTRICTED LEVEL SHIFTER
28-IS-0044		Granted	718171	01-Apr-198	5 4646331	24-Feb-198	7 ELECTRONIC STATIC SWITCHED-LATCH FREQUENCY DIVIDER CIRCUIT WITH ODD
							NUMBER COUNTING CAPABILITY
28-IS-0047		Granted	785381	07-Oct-198	5 4656459	07-Apr-1987	7 DUAL SLOPE CONVERTER WITH LARGE
							APPARENT INTEGRATOR SWING
28-IS-0050		Granted	786175	09-Oct-1985	4633221	30-Dec-1986	DUAL SLOPE ANALOG TO DIGITAL CONVERTER WITH AUTOMATIC SHORT CYCLE RANGE
							DETERMINATION
28-IS-0054		Granted	892702	01-Aug-1986	4855722	08-Aug-1989	ALTERNATING CURRENT POWER LOSS
							DETECTOR
20 10 2055	ļ		1000100	15.0			
28-IS-0055		Granted	908489	17-Sep-1986	4831577	16-May-1989	DIGITAL MULTIPLIER ARCHITECTURE WITH TRIPLE ARRAY SUMMATION
28-IS-0060 *	1	Granted	123056	18-Nov-1987	5159204	•	STRUCTURE AND METHOD FOR PREVENTING
		~					LATCH-UP IN INTEGRATED CIRCUITS
RD 15746	-	Granted	668454	05-Nov-1984	<b>4552783</b>	12 Nov 1085	ENHANCING THE SELECTIVITY OF TUNGSTEN
10740	į	Siuncu		05-1407-1304	4332703		DEPOSITION ON CONDUCT OR AND
		·					SEMICONDUCTOR SURFACES
SE-701		Granted	07/615358	19-Nov-1990	5085084	•	METHOD AND APPARATUS FOR TESTING LEAD BONDS AND DETECTING FAILURE
						· · · · · · · · · · · · · · · · · · ·	BONDS AND DETECTING LAILONE
SE-703	A	Granted	07/750752	20-Aug-1991	5138319	11-Aug-1992	TWO STAGE A/D CONVERTER UTILIZING DUAL
		14		_			MULTIPLEXED CONVERTERS WITH A COMMON CONVERTER
	·						
SE-735		Granted	07/891910	01-Jun-1992	5240876	31-Aug-1993	SOI WAFER WITH SIGE
			·		-		
SE-735	A	Granted	07/891052	01-Jun-1992	5218213	08-Jun-1993	SOI WAFER WITH SIGE
SE-742	·	Grantad	07/509165	16 0~ 1000	006242	04 Eab 4000	EACT TUDN OF THYPICTOR CTRUCTURE
SE-142		Granted	07/598165	16-Oct-1990	0080242	U4-reb-1992	FAST TURN-OFF THYRISTOR STRUCTURE
-							·
			<del></del>			<del></del>	

O.	Sobo	se Shir	AD S	FIDERS .	F Pall	e destate	
46		Granted	07/523020	14-May-19	90 5119321	02-Jun-19	P92 ADAPTIVE THRESHOLD SUPPRESSION OF IMPULSE NOISE
		Granted	07/739133	30-Jul-199	91 5241213	31-Aug-19	93 BURIED ZENER DIODE HAVING AUXILIARY ZENE JUNCTION ACCESS PATH
		Granted	07/769209	01-Oct-199	91 5200733	06-Apr-19	93 RESISTOR STRUCTURE AND METHOD OF FABRICATION
- <u>-</u>	A	Granted	08/131369	04-Oct-199	3 5668397	16-Sep-199	7 HIGH FREQUENCY ANALOG TRANSISTORS,
				·			METHOD OF FABRICATION AND CIRCUIT IMPLEMENTATION
	В	Granted	08/462851	05-Jun-199	5 5807780	15-Sep-199	BHIGH FREQUENCY ANALOG TRANSISTORS, METHOD OF FABRICATION AND CIRCUIT IMPLEMENTATION
		Granted	07/674147	25-Mar-199	15311054	10-May-199	IMPROVED GRADED COLLECTOR FOR INDUCTIVE LOADS
tak Gr	A	Granted	08/191963	03-Feb-1994	5397714	14-Mar-199	5 IMPROVED GRADED COLLECTOR FOR INDUCTIVE LOADS
ţ		Granted	07/647346	29-Jan-1991	5140326	18-Aug-1992	CONVERTER COMPARATOR CELL WITH IMPROVED RESOLUTION
		Granted	07/774620	10-Oct-1991	5450339	12-Sep-1995	NONCANONIC FULLY SYSTOLIC LMS ADAPTIVE ARCHITECTURE
.		Granted	07/774628	01-Jul-1991	5258939	02-Nov-1993	FOLD AND DECIMATE FILTER ARCHITECTURE
		Granted	07/604883	29-Oct-1990	5117282	26-May-1992	STACKED CONFIGURATION FOR INTEGRATED CIRCUITS DEVICES
A	•	Granted	07/825133	24-Jan-1992	5228192		STACKED CONFIGURATION FOR INTEGRATED CIRCUITS DEVICES
A		Granted	07/816321	30-Dec-1991	5194867	ĺ	FLASH ANALOG-TO-DIGITAL CONVERTER EMPLOY LEAST SIGNIFICANT BIT REPRESENTATIVE COMPARATIVE REFERENCE VOLTAGE
+		Granted	07/689645	23-Apr-1991	5233289		VOLTAGE DIVIDER AND USE AS BIAS NETWORK FOR STACKED TRANSISTORS
	\$ A		A Granted  Granted  A Granted  Granted  Granted  Granted  Granted  Granted  Granted  Granted  Granted  Granted  A Granted  Granted  A Granted  A Granted	Granted 07/739133  Granted 07/769209  A Granted 08/131369  B Granted 08/462851  Granted 07/674147  A Granted 07/647346  Granted 07/774620  Granted 07/774620  Granted 07/774628  A Granted 07/825133  A Granted 07/816321	Granted 07/739133 30-Jul-199  Granted 07/769209 01-Oct-199  A Granted 08/131369 04-Oct-199  Granted 07/674147 25-Mar-199  Granted 07/674147 25-Mar-199  A Granted 07/674147 25-Mar-199  Granted 07/774620 10-Oct-1991  Granted 07/774628 01-Jul-1991  Granted 07/774628 01-Jul-1991  Granted 07/604883 29-Oct-1990  A Granted 07/825133 24-Jan-1992  A Granted 07/816321 30-Dec-1991	Granted 07/739133 30-Jul-1991 5241213  Granted 07/739133 30-Jul-1991 5241213  Granted 07/769209 01-Oct-1991 5200733  A Granted 08/131369 04-Oct-1993 5668397  B Granted 08/462851 05-Jun-1995 5807780  Granted 07/674147 25-Mar-1991 5311054  A Granted 08/191963 03-Feb-1994 5397714  C Granted 07/647346 29-Jan-1991 5140326  Granted 07/774620 10-Oct-1991 5450339  Granted 07/774628 01-Jul-1991 5258939  Granted 07/604883 29-Oct-1990 5117282  A Granted 07/825133 24-Jan-1992 5228192	Granted 07/523020 14-May-1990 5119321 02-Jun-15 Granted 07/739133 30-Jul-1991 5241213 31-Aug-19 Granted 07/769209 01-Oct-1991 5200733 06-Apr-19 A Granted 08/131369 04-Oct-1993 5668397 16-Sep-199 Granted 07/674147 25-Mar-1991 5311054 10-May-199 Granted 07/674147 25-Mar-1991 5311054 10-May-199  A Granted 08/191963 03-Feb-1994 5397714 14-Mar-199  Granted 07/647346 29-Jan-1991 5140326 18-Aug-1992 Granted 07/774620 10-Oct-1991 5450339 12-Sep-1995 Granted 07/774628 01-Jul-1991 5258939 02-Nov-1993 Granted 07/604883 29-Oct-1990 5117282 26-May-1992 A Granted 07/804883 29-Oct-1990 5117282 26-May-1992 A Granted 07/804883 29-Oct-1990 5117282 20-Jul-1993 A Granted 07/816321 30-Dec-1991 5194867 16-Mar-1993 A Granted 07/816321 30-Dec-1991 5194867 16-Mar-1993

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SE-696	Ā	Granted	08/071795	04-Jun-19	93 5493207	20-Feb-199	FOR STACKED TRANSISTORS
RD 18146		Granted	173918	28-Mar-198	38 4942449	17-Jul-199	0 FAB METHOD AND STRUCTURE FOR FIELD ISOLATION IN FIELD EFFECT TRANSISTORS ON IC CHIPS
SE-778		Granted	07/724206	01-Jul-199	5206821	27-Apr-199	3 DECIMATING FILTER
SE-778	A	Granted .	07/945674	15-Sep-199	2 5341335	23-Aug-1994	4 DECIMATING FILTER
SE-776		Granted	07/689624	23-Apr-199	15096850	17-Mar-1992	METHOD OF LASER TRIMMING
SE-776	A	Granted	07/852541	17-Mar-199	2 5235205	10-Aug-1993	METHOD OF LASER TRIMMING
SE-653	<u> </u>	Granted	07/732475	18-Jul-199	5359211	25-Oct-1994	HIGH VOLTAGE PROTECTION USING SCRS
SE-653	A	Granted	08/253287	26-Aug-1994	5670799	23-Sep-1997	HIGH VOLTAGE PROTECTION USING SCRS
SE-784	A	Granted	08/216217	21-Mar-1994	5429993		SEMICONDUCTOR ACCELEROMETER AND METHOD OF ITS MANUFACTURE
SE-784	B	Granted	08/457643	31-May-1995	5656512		SEMICONDUCTOR ACCELEROMETER AND METHOD OF ITS MANUFACTURE
SE-787		Granted	07/930072	14-Aug-1992	5515402	07-May-1996	QUADRATURE FILTER WITH REAL CONVERSION
28-SV-0070		Granted	07/601974	22-Oct-1990	5138413		PISO ELECTROSTATIC DISCHARGE PROTECTION DEVICE
RD 15522		Granted	593064	26-Mar-1984	4590130		SOLID STATE ZONE RECRYSTALLIZATION OF SEMICONDUCTOR MATERIA
RD 16311		Granted	890050	28-Jul-1986	4695489		ELECTROLESS NICKEL PLATING COMPOSITION AND METHOD
	L	<u> </u>	LL	l			

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RD ·16392		Granted	805651	06-Dec-19	85 4685040	04-Aug-198	7 UNIVERSAL INTEGRATED CIRCUIT POWER SUPPLY CHIP
RD 16484		Granted	853108	17-Apr-198	36 4677736	07-Jul-198	7 SELF-ALIGNED INLAY TRANSISTOR WITH OR WITHOUT SOURCE AND DR
			·				
RD 16518		Granted	790716	24-Oct-198	35 4661838	28-Apr-198	7 HIGH VOLTAGE SEMICONDUCTOR DEVICES ELECTRICALLY ISOLATED FR
RD 16587		Granted	047739	08-May-198	7 4746375	24-May-198	ACTIVATION OF REFRACTORY METAL SURFACES FOR ELECTROLESS PLA
RD 16999		Granted	085922	17-Aug-198	7 4768016	30-Aug-1988	TIMING AND CONTROL CIRCUITRY FOR FLASH ANALOG TO DIGITAL CO
RD 17119		Granted	935470	26-Nov-1986	6 4717679	05-Jan-1988	MINIMAL MASK PROCESS FOR FABRICATING A LATERAL INSULATED GATE SEMI DEVICE
RD 18011		Granted	045494	04-May-1987	74733104	22-Mar-1988	UNIVERSAL INTEGRATED CIRCUIT POWER SUPPLY CHIP
RD 18025P	,	Granted .:	048857	12-May-1987	4810617		TREATMENT OF PLANARIZING LAYER IN MULTILAYER ELECTRON BEAM
RD 18163P		Granted	073897	13-Jul-1987	4872039		BURIED LATERAL DIODE AND METHOD FOR MAKING SAME
RD 18171		Granted	178045	05-Apr-1988	4897650		SELF-CHARACTERIZING ANALOG-TO-DIGITAL CONVERTER
RD 18387		Granted	182602	18-Apr-1988	4951221	, ,	A CELL STACK FOR VARIABLE DIGIT WIDTH SERIAL ARCHITECTURE
RD 19125		Granted	265285	25-Oct-1988	4895780		ADJUSTABLE WINDAGE METHOD AND MASK FOR CORRECTION OF PROXIM
XRCA71930		Granted	948103	03-Oct-1978	4724530		FIVE TRANSISTOR CMOS MEMORY CELL INCLUDING DIODES
XRCA74253A		Granted	328435	07-Dec-1981	4393438		METHOD FOR THE MANUFACTURE OF PORCELAIN COATED METAL BOARDS
						<u> </u>	

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XRCA75085	/	Granted	374967	05-May-198	2 4369220	18-Jan-198	3 CROSSOVER DIELECTRIC INKS
	1		1.			14	÷
XRCA75431A		Granted	396662	: 	2 4200220	16 Aug 100	3 CONDUCTOR INKS
ARCA754317	`	Granted	. 390002	09-30-190	2 4399320	10-Aug-196	SCUNDUCTOR HARS
	1						
XRCA75653B		Granted	780898	27-Sep-198	5 4638498	20-Jan-198	DIGITAL TIMING SYSTEM
XRCA75805A	ļ	Granted	396661	09-Jul-1982	2 4401700	30 Aug 1003	OVERGLAZE INKS
JANCA / 3003A		Granted	330001	09-301-1902	14401709	30-Aug-190.	OVERGLAZE IIVKS
		1.				ŀ	
XRCA76785A		Granted	455310	03-Jan-1983	4415624	15-Nov-1983	AIR-FIREABLE THICK FILM INKS
ļ					ł		
XRCA77188	<u> </u>	Commission	1202004	24 14 - 4000	4070004	00.14 . 4000	APPARATUS FOR ELECTROPIJORETIO
XRCA77168		Granted	363801	31-Mar-1982	43/6031	U8-Mar-1983	APPARATUS FOR ELECTROPHORETIC DEPOSITION
ļ		1		:		ļ.	
XRCA77250		Granted	739911	31-May-1985	4651178	17-Mar-1987	DUAL INVERSE ZENER DIODE WITH BURIED
							JUNCTIONS ·
XRCA78911		Granted	889209	25-Jul-1986	4724500	45 M 4000	CONSTANT CURRENT LOAD AND LEVEL SHIFTER
ARCA76911		Granteu	009209	· 25-Jul-1900	4731369		CIRCUITRY
XRCA78956B		Granted	858024	01-May-1986	4652773		INTEGRATED CIRCUITS WITH ELECTRICALLY
						<u> </u> -	ERASABLE ELE
XRCA79084		Granted	459754	21-Jan-1983	4467000	21 Aug 1004	INDIUM OXIDE RESISTOR INKS
7(10) (1 3004		Clanted	1400704	21-Jan-1905	4407003	21-Aug-1304	INDIGIN CARDE REGISTOR INVO
XRCA79100		Granted	460008	21-Јап-1983	4452844	05-Jun-1984	LOW VALUE RESISTOR INKS
XRCA79245		Granted	685251	21-Dec-1984	4639898	27- Jan-1987	BIT-LINE PULL-UP CIRCUIT
XI (O/ II 0240			000251	21-000-100-1	4003030	27-3411-1307	BIT-LINE I GEL-OF GINGOIT
		ļ					·
XRCA79643A		Granted	755828	17-Jul-1985	4639752	27-Jan-1987	FAST TERNARY (GAINAS) LOGIC GATE DEVICE
XRCA79815		Granted	612427	21-May-1984	4641261	03-Feb-10971	UNIVERSAL INTERFACE CIRCUIT FOR
VI 70-VI 30-13		Jianteu	312421	21-Way-1904			MICROPROCESSOR PER
		L				<del> </del>	

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XRCA80702	Granted	674845	26-Nov-198	4 4656373	07-Apr-198	7 HIGH-SPEED VOLTAGE LEVEL SHIFT CIRCUIT
XITOAGGIGZ	Granica	074040	207101-150	7-1-030373	υν-τφι-130	THE THE LED VOLTAGE ELVEL STILL TOROGET
XRCA81192	Granted	176323	31-Mar-198	8 5023613	11-Jun-199	1 DECODER ERROR PREVENTION APPARATUS FOR
			ļ			USE IN FLASH ANALOG TO DIGITAL CONVERTERS
XRCA81448	Granted	839917	17-Mar-198	6 4682055	21-Jul-198	7 A CIRCUIT HAVING ABOUT EQUAL CURRENTS IN
	}				·	COMPLEMEN
		<u> </u>				
XRCA81630	Granted	055220	29-May-198	7 4772568	20-Sep-198	METHOD OF MAKING INTEGRATED CIRCUIT WITH PAIR OF MOS FIELD EFFECT TRANSISTORS
, i	1		· .	ľ		SHARE A COMMON SOURCE DRAIN REGION
<u> </u>						
XRCA81642	Granted	803006	29-Nov-198	5 4668080	26-May-1987	METHOD AND APPARATUS FOR FORMING LARGE AREA HIGH R
			,	ł	1.	
XRCA81833	Granted	890275	29-Jul-1986	4707623	17 Nov 1987	CMOS INPUT BUFFER CIRCUIT
ANCA01033	Granted	090275	29-301-1980	4707023	17-1100-1907	CIVIOS INFOT BOFFER CIRCUIT
XRCA81900	Granted	722371	12-Apr-1985	4672314	09-Jun-1987	COMPREHENSIVE SEMICONDUCTOR TEST
					1	STRUCTURE
XRCA81971 _;	Granted	777584	19-Sep-1985	4662059	05-May-1987	METHOD OF MAKING STABILIZED SILICON-ON-
			1 .	}		INSULATOR F
,		j	1			
XRCA82183 **	Granted	055545	29-May-1987	4774452	27-Sep-1988	ZENER REFERENCED VOLTAGE CIRCUIT
		.			,	·
			ļ			
XRCA82579	Granted	802020	25-Nov-1985	4702993	27-Oct-1987	MULTILAYER ELECTRON BEAM RESIST
XRCA82756	Grantad	166483	10 Mar 1000	49076EE	20: lan 1000	HIGH CREED APPARATUS FOR A SINGLE LATCH
ARCA02750	Granted	100403	10-Mar-1988	4697000		HIGH SPEED APPARATUS FOR A SINGLE LATCH FLASH ANALOG-TO-DIG ITAL CONVERTER
			[ . ]			
XRCA82787	Granted	823257	28-Jan-1986	4697085	29-Sep-1987	APPARATUS AND METHOD FOR PRODUCING IONS
1						1
XRCA82788	Granted	823258	28-Jan-1986	4691109	01-Sep-1987	APPARATUS AND METHOD FOR PRODUCING IONS
			·			
XRCA82851	Granted	388416	02-Aug-1989	4923826		METHOD FOR FORMING DIELECTRICALLY
	1					ISOLATED TRANSISTOR

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XRCA82865		Granted	359176	· 31-May-198	39 5036219	30-Jul-199	PRECISE, HIGH SPEED CMOS TRACK (SAMPLE)/HOLD CIRCUITS
XRCA83137		Granted	895365	11-Aug-198	36 4794437	27-Dec-198	8 ARC GAP FOR INTEGRATED CIRCUITS
XRCA 83180		Granted	173498	25-Mar-198	8 4998156	05-Mar-199	1 STRUCTURE FOR A COMPLEMENTARY- SYMMETRY COMFET PAIR
XRCA83194		Granted :	301073	24-Jan-198	9 4945070	31-Jul-199	METHOD OF MAKING CMOS WITH SHALLOW SOURCE AND DRAIN JUNCTIO NS
XRCA83222		Granted	356086	24-May-198	9 4988902	29-Jan-199	SEMICONDUCTOR TRANSMISSION GATE WITH CAPACITANCE COMPENSATION
XRCA83223		Granted	040168	20-Apr-198	7 4968989	06-Nov-1990	SWITCHED CAPACITOR FILTER FOR USE WITH A DIGITAL-TO-ANALOG D/A CONVERTER
XRCA83248		Granted	104405	05-Oct-1987	74783643	08-Nov-1988	IMPEDANCE TRANSFORMING CIRCUIT FOR MULTIBIT PARALLEL DIGITA
XRCA83254÷		Granted	916846	07-Oct-1986	4737033	12-Apr-1988	ALIGNMENT KEY AND METHOD OF MAKING THE SAME
XRCA83261		Granted	356311	24-May-1989	4978925	18-Dec-1990	UNITY-GAIN CMOS/SOS ZERO-OFFSET BUFFER
XRCA83310	·	Granted	860814	08-May-1986	4684878	04-Aug-1987	TRANSISTOR BASE CURRENT REGULATOR
XRCA83493		Granted	048704	12-May-1987	4791464		SEMICONDUCTOR DEVICE THAT MINIMIZED THE LEAKAGE CURRENT ASSOCIATED WITH THE PARASITIC EDGE TRANSIS AND A METHOD
XRCA83529		Granted	301926	26-Jan-1989	4945262	1 2	VOLTAGE LIMITER APPARATUS WITH INHERENT LEVEL SHIFTING EMPLOYING MOSFETS
XRCA83554	<del></del>	Granted	356084	24-May-1989	5014055		ANALOG-TO-DIGITAL CONVERTER AND METHOD OF USE UTILIZING CHARGE REDISTRIBUTION
XRCA83563		Granted	120422	13-Nov-1987	4847518	11-Jul-1989	CMOS VOLTAGE DIVIDER CIRCUITS
					·		

Clicate	Silicas	Seine		/ Jalipate		Fisibele.	And the second second
XRCA83629		Granted	104406	05-Oct-198	37 4833473	23-May-198	9 DIGITAL TO ANALOG CONVERTER WITH SWITCH FUNCTION COMPENSATION
XRCA83680		Granted	149514	28-Jan-198	8 4924225	08-May-199	0 ANALOG TO DIGITAL CONVERTER WITH INTEGRAL LINEARITY ERROR COMPENSATION AND METHOD OF OPERATION
XRCA83871	<del></del>	Granted	084464	12-Aug-198	7 4810619	07-Mar-1989	IMPROVED PHOTOLITHOGRAPHY OVER REFLECTIVE SUBSTRATES
XRCA84091		Granted	178982	21-Apr-1988	3 4967388	30-Oct-1990	TRUNCATED PRODUCT PARTIAL CANONICAL SIGNED DIGIT MULTIPLIER
28-SP-1387	· .	Granted	163534	17-Mar-1988	5015921	14-May-1991	SOFT START SOLID STATE SWITCH
28-SP-1394		Granted	243200	08-Sep-1988	4933994	<b>j</b> '	METHOD FOR FABRICATING A SELF-ALIGNED LIGHTLY DOPED DRAIN SEMICONDUCTOR DEVICE WITH SILICIDE
28-SV-0009	• .	Granted	187869	29-Apr-1988	4947362		DIGITAL FILTER EMPLOYING PARALLEL PROCESSING
28-SV-0018 🔅		Granted	440187	22-Nov-1989	5021747		SYMMETRICAL VARIABLE IMPEDANCE APPARATUS EMPLOYING MOS TRANSISTORS
28-SV-0028		Granted	279885	05-Dec-1988	4853610		PRECISION TEMPERATURE-STABLE CURRENT SOURCES/SINKS
28-SV-0035		Granted	390147	07-Aug-1989	4978868		SIMPLIFIED TRANSISTOR BASE CURRENT COMPENSATION CIRCUITRY
28-IS-0063	·	Granted	07/637047	03-Jan-1991	5150120	22-Sep-1992	MULTIPLEXED SIGMA-DELTA A/D CONVERTER
RD 14706		Granted	534898	22-Sep-1983	4536782		FIELD EFFECT SEMICONDUCTOR DEVICES AND METHOD OF MAKING SAM
RD 12241		Granted	320379	12-Nov-1981 4	1390393	28-Jun-1983 N	METHOD OF MAKING INTEGRATED CIRCUITS
RD 13620		Granted	712940	18-Mar-1985	609932		METHOD FOR FABRICATING NONPLANAR ION- SENSITIVE FIELD-EFFEC

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RD 13655		Granted	364294	01-Apr-198	5014102	07-May-199	MOSFET GATED BIPOLAR TRANSISTORS AND THYRISTORS WITH BOTH TURN ON AND TURN OFF
RD 13683		Granted	387717	11-Jun-198	2 4500029	19-Feb-198	5 ELECTRICAL ASSEMBLY INCLUDING A CONDUCTOR PATTERN BONDED TO
RD:13870		Granted	395778	06-Jul-198	2 4414243	08-Nov-198	METHOD FOR MAKING SURFACE ACOUSTIC WAVE DEVICE
RD 14037		Granted	333596	23-Dec-198	14412868	01-Nov-1983	METHOD OF MAKING INTEGRATED CIRCUITS
RD 14111		Granted	394346	01-Jul-1982	2 4494134	15-Jan-1985	HIGH VOLTAGE SEMICONDUCTOR DEVICES .
RD 14133		Granted	616756	04-Jun-1984	4635092	06-Jan-1987	TAPE AUTOMATED MANUFACTURE OF POWER SEMICONDUCTOR DEVICES
RD 14141	·	Granted	534520	21-Sep-1983	4528582	09-Jul-1985	INTERCONNECTION STRUCTURE FOR POLYCRYSTALLINE SILICON RESIS
RD 14226		Granted	464099	04-Feb-1983	4499558		FIVE TRANSISTOR STATIC MEMORY CELL IMPLEMENTAL IN CMOS/BULK
RD 14227		Granted	478014	23-Mar-1983	4521695	1	CMOS-D TYPE LARCH EMPLOYING SIX TRANSISTORS AND FOUR DIODES
RD 14230		Granted	478015	23-Mar-1983	4484087		CMOS LATCH CELL INCLUDING FIVE TRANSISTORS AND STATIC FLIP
RD 14504		Granted	471617	03-Mar-1983	4444618		IMPROVED PROCESSES AND GAS MIXTURES FOR THE REACTIVE ION ET
RD 14955		Granted	651014	17-Sep-1984	4628174		FORMING ELECTRICAL CONDUCTORS IN LONG MICRODIAMETER HOLES
RD 15477	<u> </u>	Granted	557997	05-Dec-1983	4498924		METHOD FOR PRODUCING EUTECTICS AS THIN FILMS
RD 15478		Granted	557996	05-Dec-1983	1498923	1	METHOD FOR PRODUCING EUTECTIC AS THIN FILMS

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RD 15479	1	Granted	557998	05-Dec-198	3 4498925	12-Feb-198	5 METHOD FOR PRODUCING EUTECTICS AS THIN FILMS
					[	p.	
RD 15480	<b></b> -	Crantad	557999	05 No. 409	2 4400000	40.5-1-400	CASTUOD FOR PROPURING SUFFERING AS THE
15460	ľ	Granted	1557999	05-Nov-198	3 4498926	12-Feb-198	METHOD FOR PRODUCING EUTECTICS AS THIN
	1		_			·	<u> </u>
RD 15488	<del> </del>	Granted	558123	05-Dec-198	2 4406624	20 Jan 109	ELITECTIC FINE MIDE ADDAYS
RD 13400		Granieu	556125	05-Dec-196	314490034	29-Jan-198	EUTECTIC FINE WIRE ARRAYS
1				1	1		
RD 15489	<u> </u>	Granted	558125	05-Dec-198	2 4402720	09 lan 109	ELITECTIC FINE WIDE ADDAVE
15469	]	Granteu	336123	05-Dec-196.	4492739	1 00-Jan-198:	EUTECTIC FINE WIRE ARRAYS
				1			
RD 15490		Granted	558124	05-Dec-1983	4402729	09 lon 1095	EUTECTIC FINE WIRE ARRAYS
15490		Granteu	336124	05-Dec-1963	4492736	06-Jan-1965	EUTECTIC FINE WIRE ARRAYS
1			· ·	1			
RD 15501		Granted	711333	13-Mar-1985	4502204	22 Apr 1096	METHOD OF MAKING AN INTEGRATED CIRCUIT
15501		Granted	7 1 1333	13-Wai-1983	4303201	22-Api-1960	METHOD OF MAKING AN INTEGRATED CIRCUIT
RD 15596		Granted	595179	30-Mar-1984	4620258	28 Oct 1986	CIRCUIT FOR SELF COMMUTATED TURN OFF OF
10000		Ciamed	1000110	30-11141-1304	4020230		LATCHED DEVICES, SU
	-						
RD 15805		Granted	667933	02-Nov-1984	4593458	10- lun-1986	FABRICATION OF INTEGRATED CIRCUIT WITH
		Johanne		02 1101 1004	1000100	10-0411-1500	COMPLEMENTARY DIELEC
					٠	]	
RD 16199		Granted	722640	12-Apr-1985	4680603	14-Jul-1987	GRADED EXTENDED DRAIN CONCEPT FOR
		Jordinos	1220.0	127101000	4000000	1 1	REDUCED HOT ELECTRON EFFECT
			1				
RD 16214	<del></del>	Granted	722642	12-Apr-1985	4613882	23-Sep-1986	HYBRID EXTENDED DRAIN CONCEPT FOR
1							REDUCED HOT ELECTRON EFFE
			-				
RD 16232		Granted	803049	29-Nov-1985	4963951	16-Oct-1990	LATERAL INSULATED GATE BIPOLAR
		1				l l	TRANSISTORS WITH IMPROVED LATCH UP
							IMMUNITY
RD 16407	<del></del>	Granted	713215	18-Mar-1985	4597002	24-Jun-1986	FLOW THROUGH ISFET AND METHOD OF
		1 .					FORMING
		1	].				
RD 16483		Granted	840635	17-Mar-1986	1737828	12-Apr-1988	METHOD FOR GATE ELECTRODE FABRICATION
			]				AND SYMMETRICAL SELF-
RD 16670		Granted	845110	27-Mar-1986	1767724	30-Aug-1988 L	JNFRAMED VIA INTERCONNECTION WITH
							DIELECTRIC ETCH STOP
							·
		L		<del></del>			

: Gienke	SubCas	e - Aleus	AD P	: EIDAG	A POLICE	/ Installer	
RD 16745		Granted	003678	15-Jan-198	7 4796070	03-Jan-198	LATERAL CHARGE CONTROL SEMICONDUCTOR DEVICE AND METHOD OF FABRICATING
RD. 16991		Granted	807612	11-Dec-198	5 4862242	29-Aug-1989	SEMICONDUCTOR WAFER WITH AN ELECTRICALLY ISOLATED SEMICONDU
RD 17177		Granted	892652	04-Aug-1986	6 4729079	01-Mar-1988	BILLUMINATOR FOR VISUAL INSPECTION OF CURVED SPECULAR SURFAC
RD 17190		Granted	868923	29-May-1986	4775952	04-Oct-1988	PROCESS ACCELERATOR
RD 17249		Granted	051427	19-May-1987	4888627	19-Dec-1989	MONOLITHICALLY INTEGRATED LATERAL INSULATED GATE SEMICONDUCTOR DEVICE
RD 17317	-	Granted	857283	30-Apr-1986	4691433	08-Sep-1987	HYBRID EXTENDED DRAIN CONCEPT FOR REDUCED HOT ELECTRON EFFE
RD 17462		Granted	882857	07-Jul-1986	4778776	18-Oct-1988	PASSIVATION WITH A LOW OXYGEN INTERFACE
RD 17541		Granted	898082	20-Aug-1986	4716124		TAPE AUTOMATED MANUFACTURE OF POWER SEMICONDUCTOR DEVICES
RD 17903P		Granted	041565	23-Apr-1987	4766317		OPTICAL REFLECTANCE METHOD OF EXAMINING A SIMOX ARTICLE
RD 18061P		Granted	093655	08-Sep-1987	4990995		LOW RELFECTANCE CONDUCTOR IN AN INTEGRATED CIRCUIT
RD 18166P	<u>-</u>	Granted	073371	10-Jul-1987	4733039	22-Mar-1988	METHOD OF LASER SOLDERING
RD 18373P		Granted	124129	23-Nov-1987	4764482		METHOD OF FABRICATING AN INTEGRATED CIRCUIT CONTAINING BIPO
RD 18564		Granted	152703	05-Feb-1988	4868921		HIGH VOLTAGE INTEGRATED CIRCUIT DEVICES ELECTRICALLY INSOLA
RD 18808	`	Granted	196416	20-May-1988	4859620		GRADED EXTENDED DRAIN CONCEPT FOR REDUCED HOT ELECTRON EFFE

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RD 18946	Granted	235087	23-Aug-198	THE PERSON NAMED IN	J	SELF PACKAGING CHIP MOUNT
				.	, , , , , , , , , , , , , , , , , , ,	
RD 19031	Granted	243210	09-Sep-198	8 4942440	17-Jul-1990	HIGH VOLTAGE SEMICONDUCTOR DEVICES WITH REDUCED ON-RESISTAN
RD 19878	Granted	454547	21-Dec-198	9 4996116	26-Feb-1991	ENHANCED DIRECT BOND COPPER PROCESS AND STRUCTURE
XRCA78891	Granted	532898	16-Sep-198	3 4786814	22-Nov-1988	METHOD OF REDUCING ELECTROSTATIC CHARGE ON ION-IMP
XRCA81354	Granted	935389	26-Nov-1980	6 4758744	19-Jul-1988	IMPROVED DECODER CIRCUITRY
XRCA83421	Granted	250249	27-Sep-1988	4964726		APPARATUS AND METHOD FOR OPTICAL DIMENSION MEASUREMENT USING INTERFERENCE OF SCATTERED ELECTROMAG ENERGY
28-IS-0043	Granted	757808	22-Jul-1985	4683528		PULSE POSITION MODULATED REGULATION FOR POWER SUPPLIES
28IS00045 ·	Granted	708351	05-Mar-1985	4789959	06-Dec-1988	DELAY CIRCUIT FOR A REAL TIME CLOCK
28-IS-0051	Granted	725216	19-Apr-1985	4754160	28-Jun-1988	POWER SUPPLY SWITCHING CIRCUIT
			·			
28-SP-1348	Granted	793426	31-Oct-1985	4750216	07-Jun-1988	VIDEO COUPLER DEVICE
28-SP-1375	Granted	064133	19-Jun-1987	4795716		METHOD OF FABRICATING A POWER IC STRUCTURE
28-SP-1391	Granted	224636	27-Jul-1988	4820968	11-Apr-1989	COMPENSATED CURRENT SENSING CIRCUIT
28-SV-0015	Granted	197098	20-May-1988	4864379	05-Sep-1989 I	BIPOLAR TRANSISTOR WITH FIELD SHIELDS
35EL01572	Granted	402161	26-Jul-1982	4498172		A SYSTEM FOR POLYDIV SELF TESTING OF DIGITAL NETWORKS

09-Oct-1984 METHOD OF MAKING AN INTEGRATED CIRCUIT INCORPORATING LOW VO
18-Jul-1989 ACTIVE AREA PLANARIZATION WITH SELF ALIGNED CONTACTS
25-Apr-1989 METHOD OF FILLING INTERLEVEL DIELECTRIC V OR CONTACT HOLES IN MULTILEVEL VLSI METALLIZATION STRUCTURE
01-Jan-1991 MO/TI CONTACT TO SILICON
05-Mar-1991 TWO DIMENSIONAL HYBRID DIGITAL CONVOLVER
28-Feb-1989 IMPROVED CHIP CARRIER AND METHOD OF FABRICATION
8-Sep-1990 HIGH VOLTAGE INTEGRATED CIRCUITS
02-Apr-1996 POWER DRIVER CIRCUIT
28-Apr-1998 BIASING OF ISLAND-SURROUNDING MATERIAL TO SUPPRESS REDUCTION OF BREAKDOWN VOLTAGE DUE TO FIELD PLATE ACTING ON BURIED LAYER/ISLAND JUNCTION BETWEEN HIGH
4-Dec-1993 METHOD AND DEVICE IN WHICH BOTTOMING A WELL IN A DIELECTRICALLY ISOLATED ISLAND IS ASSURED
1-Aug-1995 METHOD AND DEVICE IN WHICH BOTTOMING A WELL IN A DIELECTRICALLY ISOLATED ISLAND IS ASSURED
1-Feb-1997 METHOD AND DEVICE IN WHICH BOTTOMING A WELL IN A DIELECTRICALLY ISOLATED ISLAND IS ASSURED
2-Feb-1994 STATIC ELECTRICITY DISPERSANT
8-Apr-1998 TELEPHONE SUBSCRIBER LINE CIRCUIT, COMPONENTS AND METHODS

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RD 17837P		Granted	013529	11-Feb-198	4732838	22-Mar-198	88 METHOD OF FORMING A PATTERNED GLASS LAYER OVER THE SURFACE OF A SUBSTRATE
RD 18445P		Granted	134585	14-Dec-198	7 4933904	12-Jun-199	DENSE EPROM AND OPERATING METHODS THEREFOR
RD 19923		Granted	440962	24-Nov-198	9 4983537	08-Jan-199	1 METHOD OF MAKING A BURRIED OXIDE FIELD ISOLATION STRUCTURE
XRCA80272		Granted	724245	17-Apr-198	5 4594560	10-Jun-198	PRECISION SETTING OF THE BIAS POINT OF AN AMPLIFYI
XRCA80326		Granted	613410	24-May-1984	4639859	27-Jan-198	PRIORITY ARBITRATION LOGIC FOR A MULT- MASTER BUS S
XRCA80447		Granted	645217	29-Aug-1984	4586375	06-May-1986	REUSABLE CENTRIFUGE FIXTURE AND METHODS OF MAKING
XRCA80515		Granted	631869	18-Jul-1984	4589002	13-May-1986	DIODE STRUCTURE
XRCA80629		Granted	671917	15-Nov-1984	4643385	17-Feb-1987	ANTI-VIBRATION SYSTEM
SE-964		Granted	08/268417	30-Jun-1994 :	5570407	29-Oct-1996	DISTORTIONLESS X-RAY INSPECTION
SE-967		Granted	08/195667	03-Feb-1994	5451263		PLASMA CLEANING METHOD FOR IMPROVED INK BRAND PERMANENCY ON IC PACKAGES WITH METALLIC PARTS
SE-958		Granted	08/180737	13-Jan-1994	5466963	14-Nov-1995	TRENCH RESISTOR ARCHITECTURE
SE-968		Granted	08/310280	21-Sep-1994	5648678		PROGRAMMABLE ELEMENT IN BARRIER METAL DEVICE AND METHOD
28-SV-0084		Granted	08/180267	12-Jan-1994	5574609	12-Nov-1996	FAIL-SAFE MOS SHUTDOWN CIRCUITRY
SE-1025-TD	A	Granted	08/884032	27-Jun-1997	5808348		NON-UNIFORMLY NITRIDED GATE OXIDE AND METHOD
		]	<u> </u>				

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SE-1363-TD		Granted	08/929734	15-Sep-19	97 6040707	21-Mar-200	00 CONSTANT SLEW-RATE AMPLIFIER
SE-1258-AP		Granted	08/931340	16-Sep-199	5942677	24-Aug-199	RESPONDING TO A DISCONNECT CONDITION (AS AMENDED)
SE-1486-IP		Pending	09/552117	19-Apr-200	00		ACCESSING MAIN ATX OUTPUTS WITHOUT MONITORING ALL OUTPUTS
SE-906	D	Pending	09/316580	21-May-199	9		BONDED WAFER PROCESSING WITH METAL SILICIDATION
SE-1463-TD		Pending	09/307896	10-May-199	9		LASER DECAPSULATION APPARATUS AND METHOD
XRCA72592A		Granted	466593	15-Feb-1983	3 4433469	28-Feb-1984	METHOD OF FORMING A SELF ALIGNED ALUMINUM POLYCRYS
XRCA72827A		Granted	221367	30-Dec-1980	4668973	26-May-1987	PASSIVATING COMPOSITE FOR A SEMICONDUCTOR DEVICE C
XRCA72827B		Granted	304347	22-Sep-1981	0032351	17-Feb-1987	METHOD OF MANUFACTURING A PASSIVATING COMPOSITE CO
XRCA73341		Granted	335707	30-Dec-1981	4395467	26-Jul-1983	TRANSPARENT CONDUCTIVE FILM HAVING AREAS OF HIGH A
XRCA73678		Granted	320015	10-Nov-1981	4396702	02-Aug-1983	METHOD OF FORMING PATTERN IN POSITIVE RESIST MEDIA
XRCA73760D		Granted	712479	18-Mar-1985	4575746	1	CROSSUNDERS FOR HIGH DENSITY SOS INTEGRATED CIRCUI
SE-880		Granted	07/947177	18-Sep-1992	5315144	·	REDUCTION OF BIPOLAR GAIN AND IMPROVEMENT IN SNAP BACK SUSTAINING VOLTAGE IN SOI FIELD EFFECT TRANSISTOR
SE-883		Granted	07/939115	01-Sep-1992	5270265		STRESS RELIEF TECHNIQUE OF REMOVING OXIDE FROM SURFACE OF TRENCH-PATTERNED SEMICONDUCTOR-ON-INSULATOR STRUCTURE
SE-884/864	Α	Granted	08/304433	12-Sep-1994	5548542	20-Aug-1996	HALF BAND FILTER AND METHOD

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SE-884/864	В	Granted	08/462684	05-Jun-199	5 5574671	i	6 HALF BAND FILTER AND METHOD
						با	
SE-891	<b>†</b>	Granted	07/905015	26-Jun-199	2 5311070	10-May-199	4 SEU-IMMUNE LATCH FOR GATE ARRAY
							STANDARD CELL AND OTHER ASIC APPLICATIONS
SE-873	ļ	Created	07/882070	12-May-199	2522204	24 10- 400	INTEGRATION OF HIGH VOLTAGE LATERAL CMOS
SE-0/3		Granted	077882070	12-Way-199.	25322604	21-3011-1994	DEVICES IN LOW VOLTAGE MOS ARCHITECTURE
			·				USING CMOS COMPATIBLE PROCESS STEPS
SE-873	Α	Granted	08/227157	13-Apr-1994	5541435	30-Jul-1996	INTEGRATION OF HIGH VOLTAGE LATERAL CMOS DEVICES IN LOW VOLTAGE MOS ARCHITECTURE
							USING CMOS COMPATIBLE PROCESS STEPS
SE-966		Granted	08/462171	05-Jun-1995	5618752	08-Apr-1997	METHOD OF FABRICATION OF SURFACE
	ļ				-		MOUNTABLE INTEGRATED CIRCUITS
SE-990		Granted	08/456727	01-Jun-1995	5633180	27-May-1997	METHOD OF FORMING P-TYPE ISLANDS OVER P-
	<b>.</b>	Crantes	00/400/2/	01-0411-1000	3000 100	27-May-1007	TYPE BURIED LAYER
SE-996		Granted	08/402381	13-Mar-1995	5659269		ZERO PHASE ERROR SWITCHED-CAPACITOR PHASE LOCKED LOOP FILTER
SE-1002-TL		Granted	08/380409	30-Jan-1995	5671272	23-Sep-1997	CURRENT MODE RING TRIP DETECTOR
					-		
SE-1003-TL		Granted	08/380412	30-Jan-1995	5572162	05-Nov-1996	A FILTER WITH REDUCED ELEMENT RATINGS AND
				·			METHOD
SE-1004-TD			00/020700	00 No. 4004	FC4004	04 1-14007	METHOD FOR MAKING OLUMO CONTACT TO
SE-1004-1D		Granted	08/336768	09-Nov-1994	5643821		METHOD FOR MAKING OHMIC CONTACT TO LIGHTLY DOPED ISLAND FROM A SILICIDE BURIED
	· · · · · · · · · · · ·						LAYER AND APPLICATION
XRCA73949		Granted	561220	14-Dec-1983	4727515	23-Feb-1988	HIGH DENSITY PROGRAMMABLE MEMORY ARRAY
							·
XRCA73966		Granted	559720	09-Dec-1983	4499853	19-Feb-1985	DISTRIBUTOR TUBE FOR CVD REACTOR
·						l . I	
XRCA74378		Granted	379103	17-May-1982	4420503		LOW TEMPERATURE ELEVATED PRESSURE
				·	2000		GLASS FLOW/RE-FL
	<u> </u>						·
XRCA74465		Granted	330492	14-Dec-1981	1397938		METHOD OF FORMING RESIST PATTERNS USING. K-RAYS OR
		<u> </u>	<del></del>	i		L	

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XRCA74518E	Granted	299344	04-Sep-198	1 4589008	13-May-198	GAPPARATUS FOR ELECTRICALLY JOINING THE ENDS OF SUB
XRCA74727	Granted	412807	30-Aug-1982	24521703	04-Jun-198	5 HIGH SPEED SENSE AMPLIFIER
XRCA74823	Granted 	304785	23-Sep-1981	4450524	22-May-198	4 SINGLE CHIP MICROCOMPUTER WITH EXTERNAL DECODER AN
XRCA74996	Granted	666721	31-Oct-1984	4618849	21-Oct-1986	GRAY CODE COUNTER
XRCA75007	Granted	613415	24-May-1984	4617550	14-Oct-1986	ANALOG-TO-DIGITAL CONVERTERS WITH VIRTUAL INTEGRAT
XRCA75166B	Granted -	741703	07-Jun-1985	4595941	17-Jun-1986	PROTECTION CIRCUIT FOR INTEGRATED CIRCUIT DEVICES
XRCA75350	Granted	332831	21-Dec-1981	4489422	18-Dec-1984	FREEZE CLOCK CIRCUIT
XRCA75357A	Granted	380284	20-May-1982	4803528	07-Feb-1989	METHOD FOR FABRICATING ADJACENT CONDUCTING AND INS
XRCA75485	Granted	377001	11-May-1982	4395304		SELECTIVE ETCHING OF PHOSPHOSILICATE GLASS
(RCA75561	Granted	311512	15-Oct-1981	4456837		CIRCUITRY FOR GENERATING NON- OVERLAPPING PULSE TRA
(RCA75596	Granted	510174	01-Jul-1983	4472453	•	PROCESS FOR RADIATION FREE ELECTRON BEAM DEPOSITIO
(RCA75648A	Granted	561272	14-Dec-1983	4478472	23-Oct-1984	ELECTRICAL CONNECTOR
(RCA75660	Granted	547012	31-Oct-1983	1507334		SURFACE PREPARATION FOR DETERMINING DIFFUSION LENG
RCA75849	Granted	326162	30-Nov-1981	1449185	7 1	IMPLEMENTATION OF INSTRUCTION FOR A BRANCH WHICH C

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XRCA75868A		Granted	572955	23-Jan-198	4 4484331	20-Nov-198	4 REGULATOR FOR BIAS CURRENT OF SEMICONDUCTOR LASER
XRCA75902		Granted	646102	31-Aug-1984	4612466	16-Sep-198	6 HIGH-SPEED OUTPUT DRIVER
XRCA75915A		Granted	347107	09-Feb-1982	4393160	12-Jul-198	3 AQUEOUS DEVELOPABLE POLY(OLEFIN SULFONE) TERPOLYME
VD0475002			202046	20 lun 1000	1400449	20 Jan 1001	PROCESS FOR FORMING AN IMPROVED SILICON-
XRCA75983		Granted	393616	30-Jun-1982	4496418	29-Jan-1983	ON-SAPPHIR
XRCA75992		Granted	328437	07-Dec-1981	4434381	28-Feb-1984	SENSE AMPLIFIERS
XRCA76011		Granted	390782	21-Jun-1982	4445270	01-May-1984	LOW RESISTANCE CONTACT FOR HIGH DENSITY INTEGRATED
XRCA76041	·	Granted	362465	26-Mar-1982	4450562	22-May-1984	TWO LEVEL PARITY ERROR CORRECTION SYSTEM
KRCA76166		Granted	448724	10-Dec-1982	4716451		SEMICONDUCTOR DEVICE WITH INTERNAL GETTERING REGION
(RCA76204		Granted	349515	17-Feb-1982	4498775		METHOD FOR DETECTING DISTANCE DEVIATIONS TO A PHOT
(RCA76218A		Granted	480596	30-Mar-1983	4495427	22-Jan-1985	PROGRAMMABLE LOGIC GATES AND NETWORKS
(RCA76543		Granted	359434	18-Mar-1982	4450371	22-May-1984	SPEED UP CIRCUIT
RCA76692		Granted	560459	12-Dec-1983	4519126		METHOD OF FABRICATING HIGH SPEED CMOS DEVICES
RCA76700A		Granted	396663	09-Jul-1982	1405776		POSITIVE RADIATION SENSITIVE RESIST TERPOLYMER FRO
RCA76859		Granted	334818	28-Dec-1981	1441069	03-Apr-1984	SELF-EXTINGUISHING LOAD DRIVING SYSTEM
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XRCA76972	Granted	313660	22-Oct-198	1 4437024	13-Mar-198	ACTIVELY CONTROLLED INPUT BUFFER
XRCA76998	Granted	326153	30-Nov-198	1 4449118	15-May-198	SWITCHING CIRCUITRY AS FOR A FLASH A/D CONVERTER
XRCA77148	Granted	322002	16-Nov-198	4460868	17-Jul-1984	FIXTURE FOR TESTING SEMICONDUCTOR DEVICES
XRCA77193	Granted	444164	24-Nov-1982	4502014	26-Feb-1985	COINCIDENT PULSE CANCELLING CIRCUIT
XRCA77199	Granted	362464	26-Mar-1982	4472805	18-Sep-1984	MEMORY SYSTEM WITH ERROR STORAGE
XRCA77238	Granted	582752	23-Feb-1984	4512073	23-Apr-1985	METHOD OF FORMING SELF-ALIGNED CONTACT OPENINGS
XRCA77251	Granted	421517	22-Sep-1982	4484244		PROTECTION CIRCUIT FOR INTEGRATED CIRCUIT DEVICES
XRCA77256	Granted	376572	10-May-1982	4436509		CONTROLLED ENVIRONMENT FOR DIFFUSION FURNACE
XRCA77321	Granted	335852	30-Dec-1981	4357203	02-Nov-1982	PLASMA ETCHING OF POLYIMIDE
XRCA77339	Granted	479518	28-Mar-1983	4457976	I I	METHOD FOR MOUNTING A SAPPHIRE CHIP ON A METAL BAS
XRCA77403	Granted	342473	25-Jan-1982	4439245		ELECTROMAGNETIC RADIATION ANNEALING OF SEMICONDUCT
XRCA77450	Granted	547326	31-Oct-1983	1567431		METHOD FOR REVEALING SEMICONDUCTOR SURFACE DAMAGE
KRCA77461	Granted	330579	14-Dec-1981	1397939		METHOD OF USING A POSITIVE ELECTRON BEAM RESIST ME
KRCA77474	Granted	352179	25-Feb-1982 4	1442409	•	PUSH-PULL NON-COMPLEMENTARY TRANSISTOR AMPLIFIER

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XRCA77496	Granted	352883	26-Feb-198	2 4482422	13-Nov-198	4 METHOD FOR GROWING A LOW DEFECT MONOCRYSTALLINE LA
XRCA77524	Granted	362041	25-Mar-198	2 4372807	08-Feb-198	3 PLASMA ETCHING OF ALUMINUM
XRCA77525	Granted	362044	25-Mar-1982	4375385	01-Mar-1983	PLASMA ETCHING OF ALUMINUM
XRCA77557	Granted	320434	12-Nov-1981	4429283	31-Jan-1984	DIFFERENTIAL CURRENT AMPLIFIER
XRCA77561	Granted	362043	25-Mar-1982	4370196	25-Jan-1983	ANISOTROPIC ETCHING OF ALUMINUM
XRCA77565	Granted	448690	10-Dec-1982	4513397	23-Apr-1985	ELECTRICALLY ALTERABLE, NONVOLATILE FLOATING GATE
XRCA77663	Granted	571423	17-Jan-1984	4582745		DIELECTRIC LAYERS IN MULTILAYER REFRACTORY METALLI
XRCA77676	Granted	565338	27-Dec-1983	4470871		PREPARATION OF ORGANIC LAYERS FOR OXYGEN ETCHING
XRCA77679	Granted	320016	10-Nov-1981	4357369	02-Nov-1982	METHOD OF PLASMA ETCHING A SUBSTRATE
XRCA77895	Granted	401625	26-Jul-1982	4471243	11-Sep-1984	BIDIRECTIONAL INTERFACE
XRCA77920	Granted	391923	24-Jun-1982	1401775	30-Aug-1983	EPOXY ENCAPSULATING FORMULATION
XRCA77961	Granted	476781	18-Mar-1983	1442134	10-Apr-1984 (	CHEMICAL DEPOSITION TERMINATION
XRCA77965A	Granted	793311	31-Oct-1985	1642772		SYSTEM FOR DETERMINING TIME DURATION OF ANGULAR RO
KRCA78024	Granted	435971	22-Oct-1982 4	440799		MONITOR FOR IMPURITY LEVELS IN ALUMINUM DEPOSITION

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XRCA78078	Granted	605245	30-Apr-198	4 4625120		DEEP ULTRAVIOLET (DUV) FLOOD EXPOSURE SYSTEM
XRCA78128	Granted	362463	.26-Mar-198	2 4464755	07-Aug-1984	MEMORY SYSTEM WITH ERROR DETECTION AND CORRECTION
XRCA78129	Granted	362462	26-Mar-1982	4464754	07-Aug-1984	MEMORY SYSTEM WITH REDUNDANCY FOR ERROR AVOIDANCE
XRCA78160	Granted :	567336	30-Dec-1983	4546487	08-Oct-1985	AUTO RANGING COUNTER
XRCA78254	Granted	405451	05-Aug-1982	4487125	11-Dec-1984	TIMING CIRCUIT
XRCA78299	Granted	437835	29-Oct-1982	4451507		AUTOMATIC LIQUID DISPENSING APPARATUS FOR SPINNING
XRCA78324	Granted	439562	05-Nov-1982	4498772		METHOD TO DETERMINE THE CRYSTALLINE PROPERTIES OF
XRCA78341	Granted	537817	30-Sep-1983	4532436	30-Jul-1985	FAST SWITCHING CIRCUIT
XRCA78360	Granted	386240	08-Jun-1982	4436999	13-Mar-1984	STRUCTURAL DEFECT DETECTION
XRCA78366	Granted	563627	20-Dec-1983	4612211		SELECTIVE SEMICONDUCTOR COATING AND PROTECTIVE MAS
		-				
XRCA78374	Granted	381733	24-May-1982	1462002 ·	24-Jul-1984 T	FRIMMING CIRCUITS FOR PRECISION AMPLIFIER
XRCA78386	Granted	380289	20-May-1982	1491807	01-Jan-1985 F	ET NEGATIVE RESISTANCE CIRCUITS
XRCA78463	Granted	484525	13-Apr-1983 4	476994	16-Oct-1984 L	ID LATCHING APPARATUS
KRCA78468	Granted	483876	11-Apr-1983 4	421502	20 Doc 1092 D	REVERSE ETCHING OF CHROMIUM

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XRCA78469	Granted	441682	· 15-Nov-198	2 4433044	21-Feb-198	4 DRY DEVELOPABLE POSITIVE PHOTORESISTS
XRCA78554	Granted	456493	07-Jan-1983	4472210	18-Sep-1984	4 METHOD OF MAKING A SEMICONDUCTOR DEVICE TO IMPROVE
XRCA78607	Granted	450062	15-Dec-1982	4525635	25-Jun-1985	TRANSIENT SIGNAL SUPPRESSION CIRCUIT
XRCA78660	Granted	407897	13-Aug-1982	4471237	11-Sep-1984	OUTPUT PROTECTION CIRCUIT FOR PREVENTING A REVERSE
XRCA78665	Granted	448279	09-Dec-1982	4411734		ETCHING OF TANTALUM SILICIDE/DOPED POLYSILICON STR
XRCA78705	Granted	532973	16-Sep-1983	4489103	18-Dec-1984	SIPOS DEPOSITION METHOD
XRCA78707	Granted	451818	21-Dec-1982	4400257	23-Aug-1983	METHOD OF FORMING METAL LINES
XRCA78784A	Granted	783268	04-Oct-1985	4579454		OPTICAL PROFILOMETER FOR STEEP SURFACE CONTOURS WI
XRCA78807	Granted	509787	30-Jun-1983	4567387	28-Jan-1986	LINEAR SENSE AMPLIFIER
XRCA78808	Granted	528035	31-Aug-1983	4639897	27-Jan-1987 I	PRIORITY ENCODED SPARE ELEMENT DECODER
XRCA78837	Granted	457578	13-Jan-1983	1686112	11-Aug-1987 [	DEPOSITION OF SILICON DIOXIDE
XRCA78840	Granted	444459	24-Nov-1982 4	501978	26-Feb-1985 L	LEVEL SHIFT INTERFACE CIRCUIT
XRCA78877	Granted	499397	31-May-1983 4	558435	10-Dec-1985 N	MEMORY SYSTEM
XRCA78890	Granted	532899	16-Sep-1983 4	560879	· •	METHOD AND APPARATUS FOR IMPLANTATION OF DOUBLY-CH

- Cliented / St	Cree Sale	Apl.	Vallede"		i∤rciks©ale:	
XRCA78892A	Granted	775942	12-Sep-198	5 4595837	17-Jun-198	6 METHOD FOR PREVENTING ARCING IN A DEVICE
					بو	DURING IO
XRCA78902	Granted	764551	12-Aug-198	5 4660276	28-Apr-198	METHOD OF MAKING AN MOS FIELD EFFECT
						TRANSISTOR IN
			,			
XRCA78945A	Granted	715039	22-Mar-198	5 4598462	08-Jul-198	METHOD FOR MAKING SEMICONDUCTOR DEVICE WITH INTEGR
	ļ					WITH INTEGR
XRCA78956Z	Granted	627920	05-Jul-1984	4 4596938	24-Jun-1986	ELECTRICALLY ERASABLE PROGRAMMABLE ELECTRONIC CIRC
			j		·	
XRCA79011	Granted	523921	17-Aug-1983	1609501	26 Aug 1006	ELECTRICALLY ALTERABLE PROGRAMMABLE
ARCA79011	Granteu	523521	17-Aug-1983	4000591	20-Aug-1900	NONVOLATILE FL
XRCA79016	Granted	633188	23-Jul-1984	4618876	21-Oct-1986	ELECTRICALLY ALTERABLE, NONVOLATILE
	ł	·		ľ		FLOATING GATE
XRCA79086	Granted	443925	23-Nov-1982	4529892	16-Jul-1985	DETECTION CIRCUITRY WITH MULTIPLE
						OVERLAPPING THRE
]						·
XRCA79112	Granted	828687	12-Feb-1986	4926236		MULTILAYER INTERCONNECT AND METHOD OF FORMING SAME
						FORMING SAME
						<u> </u>
XRCA79157	Granted	475035	14-Mar-1983	4457259		APPARATUS FOR SPRAYING A LIQUID ON A SPINNING SURF
XRCA79196	Granted	546181	27-Oct-1983	AEE 02AE	10 Dog 1095	MULTIPLE CONNECTION BOND PAD FOR AN
ARGATSTSO	Granted	1340101	27-001-1983	4000040	1	INTEGRATED CIR
XRCA79221	Granted	728588	29-Apr-1985	4603082	29-Jul-1986	DIAMOND-LIKE FILM
				. •		
			}	•	·	
XRCA79518	Granted	556931	01-Dec-1983	4567381		BIAS NETWORK HAVING ONE MODE FOR
						PRODUCING A REGUL
XRCA79556	Granted	584814	29-Feb-1984	4598249		METHOD USING SURFACE PHOTOVOLTAGE (SPV) MEASUREMEN
					]. · ]	MITVOOVEINITIA
		1	70 11 101	150005		
XRCA79558	Granted	553255	18-Nov-1983	4502206		METHOD OF FORMING SEMICONDUCTOR CONTACTS BY IMPLAN
İ				•		· -

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XRCA79563	Granted	605244	30-Apr-198	34 4575636	11-Mar-198	6 DEEP ULTRAVIOLET (DUV) FLOOD EXPOSURE
·		;		}		SYSTEM
				·		
XRCA79679	Granted	592397	22-Mar-198	34 4504521	12-Mar-198	5 LPCVD DEPOSITION OF TANTALUM SILICIDE
XRCA79754	Granted	562529	19-Dec-198	3 4631422	23-Dec-198	6 TTL CIRCUIT WITH A CLAMPING TRANSISTOR FOR
						SPEEDY
XRCA79829	Granted	503044	10-Jun-198	3 4555025	21 Jan 1096	CMOS STRUCTURE INCORPORATING VERTICAL
ARCA79029	Granted	503044	10-3011-190	3 4500025	21-Jan-1960	IGFETS
XRCA79885	Granted	710271	11-Mar-198	5 4633283	30-Dec-1986	CIRCUIT AND STRUCTURE FOR PROTECTING
		}			İ	INTEGRATED CIRCUITS FROM DESTRUCTIVE TRANSIENT VOLTAGES
XRCA79944	Granted	634397	25-Jui-1984	14584026	22-Apr-1986	ION-IMPLANTATION OF PHOSPHORUS, ARSENIC
	Clarited	004007	25-301-130-	1304020	22-Api-1300	OR BORON B
						·
XRCA80087 🕺	Granted	717827	29-Mar-1985	4641130	03-Feb-1987	ANALOG-TO-DIGITAL CONVERTER WITH SCALING OF INPUT
			İ			or we or
XRCA80205	Granted	562530	19-Dec-1983	4460435	17-Jul-1984	PATTERNING OF SUBMICROMETER METAL
						SILICIDE STRUCTU
XRCA80221	Granted	755012	· 15-Jul-1985	4689575		CLOCK SYNCHRONIZATION CIRCUIT FOR A COMPUTER TIMER
	. ]					
XRCA80760A	Granted	940167	10-Dec-1986	4947221	07-Aug-1990	MEMORY CELL FOR A DENSE EPROM
				er 222 von 88 - 122 i 100 m 183 - 1824		
XRCA80765	Granted	609360	11-May-1984	AC1 4007	30 Con 1096	SWITCHING CIRCUIT
ANCAOUTOS	. Granted	009300	11-May-1904	4014097	30-3ep-1900	SWITCHING CIRCOIT
XRCA80768	Granted	778986	23-Sep-1985	4637836	20-Jan-1987	PROFILE CONTROL OF BORON IMPLANT
	·				,	
XRCA80776	Granted	625910	29-Jun-1984	4648074	03-Mar-1987	REFERENCE CIRCUIT WITH SEMICONDUCTOR
					1	MEMORY ARRAY
XRCA80777	Granted	628302	06-Jul-1984	4594518	10-Jun-1986	VOLTAGE LEVEL SENSING CIRCUIT
		1				

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XRCA80794	Granted	809132	16-Dec-198	5 4695744	22-Sep-198	7 LEVEL SHIFT CIRCUIT
XRCA80885	Granted	687366	28-Dec-198	4 4576829	18-Mar-1986	LOW TEMPERATURE GROWTH OF SILICON DIOXIDE ON SILIC
XRCA80960	Granted	748350	24-Jun-198	4605479	12-Aug-1986	IN-SITU CLEANED OHMIC CONTACTS
XRCA81246	Granted	655692	28-Sep-1984	4547261	15-Oct-1985	ANISOTROPIC ETCHING OF ALUMINUM
XRCA81287	Granted	766285	16-Aug-1985	4621042	04-Nov-1986	ABSORPTIVE PLANARIZING LAYER FOR OPTICAL LITHOGRAP
XRCA81366	Granted	852289	15-Apr-1986	4735919	05-Apr-1988	METHOD OF MAKING A FLOATING GATE MEMORY CELL
XRCA81381	Granted	636832	06-Aug-1984	4546016	08-Oct-1985	DEPOSITION OF BOROPHOSPHOSILICATE GLASS
XRCA81526A	Granted	885744	.21-Jul-1986	4684970		HIGH CURRENT LATERAL TRANSISTOR STRUCTURE
XRCA81549	Granted	710284	11-Mar-1985	4585515	29-Apr-1986	FORMATION OF CONDUCTIVE LINES
XRCA81555	Granted	793237	31-Oct-1985	4613829	23-Sep-1986	SWITCHABLE OSCILLATOR CIRCUIT
XRCA81632	Granted	694100	23-Jan-1985	4592792		METHOD FOR FORMING UNIFORMLY THICK SELECTIVE EPITA
XRCA81773	Granted	748355	24-Jun-1985	4609614		PROCESS OF USING ABSORPTIVE LAYER IN OPTICAL LITHO
XRCA81793	Granted	702338	15-Feb-1985	4608118		REACTIVE SPUTTER ETCHING OF METAL SILICIDE STRUCTU
(RCA81824	Granted	711720	14-Mar-1985	1612270	16-Sep-1986	TWO-LAYER NEGATIVE RESIST
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XRCA81830	Granted	833074	26-Feb-1986	4792837	20-Dec-198	8 ORTHOGONAL BIPOLAR TRANSISTOR
XRCA81884	Granted	741358	05-Jun-1985	4618565	21-Oct-198	6 ABSORPTIVE LAYER FOR OPTICAL LITHOGRAPHY
XRCA81976	Granted	755915	17-Jul-1985	4620366	04-Nov-198	6 AUTOMATIC PIN EXTRACTION APPARATUS FOR INTEGRATED
XRCA82016	Granted	729165	30-Apr-1985	4615762	07-Oct-1986	METHOD FOR THINNING SILICON
XRCA82091	Granted	792535	29-Oct-1985	4741926	03-May-1988	SPIN-COATING PROCEDURE
XRCA82163	Granted	739820	31-May-1985	4631562	23-Dec-1986	ZENER DIODE STRUCTURE
XRCA82199	Granted	857154	29-Apr-1986	4685199	11-Aug-1987	METHOD FOR FORMING DIELECTRICALLY ISOLATED PMOS, N
XRCA82251A	Granted	148209	22-Jan-1988	4881010 .	14-Nov-1989	ION IMPLANTATION METHOD AND APPARATUS
XRCA82287	Granted	891170	31-Jul-1986	1741212	03-May-1988	METHOD FOR DETERMINING STRUCTURAL DEFECTS IN SEMIC
XRCA82355	Granted	792473	29-Oct-1985 4	614294		APPARATUS FOR HOLDING A PART IN A WAVE SOLDERING M
XRCA82389A	Granted	905077	09-Sep-1986 4	784936	15-Nov-1988	PROCESS OF FORMING A RESIST STRUCTURE
XRCA82410	Granted	792790	30-Oct-1985 4	687730	•	LIFT-OFF TECHNIQUE FOR SUB-MICROMETER LITHOGRAPHY
XRCA82427	Granted	762521	05-Aug-1985 4	662064		METHOD OF FORMING MULTI-LEVEL METALLIZATION
XRCA82468	Granted	852290	15-Apr-1986 4	687537	18-Aug-1987	EPITAXIAL METAL SILICIDE LAYERS

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XRCA82522	Granted	878259	25-Jun-1986	1692992	15-Sep-198	7 METHOD OF FORMING ISOLATION REGIONS IN A SEMICONDUCTOR DEVI CE
XRCA82533	Granted	799825	20-Nov-1985 4	1789889	06-Dec-198	8 INTEGRATED CIRCUIT DEVICE HAVING SLANTED PERIPHERA
XRCA82741	. Granted	802994	29-Nov-1985 4	698316	06-Oct-198	7 METHOD OF DEPOSITING UNIFORMLY THICK SELECTIVE EPI
XRCA83023	Granted	820808	22-Jan-1986 4	779161	18-Oct-1986	MULTI-DRIVER INTEGRATED CIRCUIT
XRCA83024	Granted	885165	14-Jul-1986 4	710440	01-Dec-1987	TEST MASK FOR DETERMINING ALIGNMENT OF AN AUTOMATI
XRCA83058	Granted	880031	30-Jun-1986 47	722654	02-Feb-1988	ARTICLE TRANSFER SYSTEM
XRCA83074	Granted	834386	28-Feb-1986 46	54545	31-Mar-1987	OVERVOLTAGE COMPARATOR
XRCA83075	Granted	834387	28-Feb-1986 46	80483	14-Jul-1987	COMPARATOR CIRCUIT
XRCA83114	Granted	834385	28-Feb-1986 47	86961		BIPOLAR TRANSISTOR WITH TRANSIENT SUPPRESSOR
XRCA83208	Granted	925982	03-Nov-1986 469	95922		CONSTANT RATIO, SIZE INSENSITIVE, CAPACITOR STRUCT
XRCA83325	Granted	298148	18-Jan-1989 489	97366		METHOD OF MAKING SILICON-ON-INSULATOR ISLANDS
XRCA83355	Granted	856277	28-Apr-1986 472	22912	1	METHOD OF FORMING A SEMICONDUCTOR STRUCTURE
XRCA83405	Granted	015478	17-Feb-1987 473	11695		CAPACITOR AND METHOD FOR MAKING SAME WITH HIGH YIE
XRCA83805	Granted	913325	30-Sep-1986 469	8132		METHOD OF FORMING TAPERED CONTACT OPENINGS

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XRCA83806		Granted	007858	.28-Jan-198	7 4710261	01-Dec-198	7 APPARATUS AND METHOD FOR MAINTAINING A UNIFORM ETCHING SOLUTION COMPOSITION
XRCA83868A		Granted	418762	06-Oct-198	9 4927777	22-May-199	0 METHOD OF MAKING AN MOS TRANSISTOR
XRCA83895		Granted	306356	06-Feb-1989	5053345	01-Oct-199	1 METHOD OF EDGE DOPING SOI ISLANDS
XRCA84087		Granted	07/278400	01-Dec-1988	5003615	26-Mar-199	OPTOELECTRONIC SYSTEM FOR DETERMINING SURFACE IRREGULARITIES OF A WORKPIECE HAVING A NOMINALLY PLANE REFLECTIVE SURFACE
XRCA83775		Granted	243367	12-Sep-1988	4872141	03-Oct-1989	RADIATION HARD MEMORY CELL HAVING NONOCRYSTALLINE AND NONO MONOCRYSTALLINE INVERTERS AND METHOD FOR MAKING SAME
XRCA83854		Granted	904271	05-Sep-1986	4989061	29-Jan-1991	RADIATION HARD MEMORY CELL STRUCTURE WITH DRAIN SHIELDING
XRCA83471	-	Granted	900520	26-Aug-1986	4833644	23-May-1989	MEMORY CELL CIRCUIT HAVING RADIATION HARDNESS
RD 18539		Granted	151045	01-Feb-1988	4933742		METALLIZATION CONTACT SYSTEM FOR LARGE SCALE INTEGRATED CIRCUITS
RD 19325		Granted	312849	17-Feb-1989	4914812	10-Apr-1990	SELF PACKAGING CHIP MOUNT
SE-807		Granted	07/791853	14-Nov-1991	5220868	22-Jun-1993	PRINT BAND CLEANER
28-IS-0066		Granted	07/720082	24-Jun-1991	5332931	26-Jul-1994	HIGH SPEED DIFFERENTIAL COMPARATOR
28-IS-0066	A	Granted .	08/018619	17-Feb-1993	5329187	12-Jul-1994	HIGH SPEED DIFFERENTIAL COMPARATOR
28-SP-1397		Granted	07/663224	01-Mar-1991	5105099		LEVEL SHIFT CIRCUIT WITH COMMON MODE REJECTION
28-SV-0045		Granted	07/696481	06-May-1991	5142244	25-Aug-1992 i	FULL RANGE INPUT/OUTPUT COMPARATOR
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	Granted	07/682482	09-Apr-199	1 5196737	23-Mar-199	3 LATCHING COMPARATOR EMPLOYING TRANSFER
					ų	GATES
	Granted	07/716488	17-Jun-199	1 5335132	02-Aug-199	4 OVER-VOLTAGE SENSOR WITH HYSTERESIS
	Granted	453090	22-Dec-1989	4999691	12-Mar-199	1 IC WITH STACKED MOS FIELD EFFECT TRANSISTORS AND METHODS OF MAKING SAME
	Granted	07/667932	12-Mar-1991	5130569	14-Jul-1992	POWER-ON RESET CIRCUIT
	Granted	07/791856	14-Nov-1991	5302859	12-Apr-1994	SYMMETRIC, HIGH SPEED, VOLTAGE SWITCHING CIRCUIT POSSESSING REVERSE VOLTAGE APPLICATION IMMUNITY
	Granted	07/806074	11-Dec-1991	5229661	20-Jul-1993	HI SPEED BIPOLAR DIGITAL LOGIC GATE ARCHITECTURE
	Granted	07/854805	19-Mar-1982	5217919	08-Jun-1993	METHOD OF FORMING ISLAND WITH POLYSILICON FILLED TRENCH ISOLATION
	Granted	07/904848	26-Jun-1992	5300877	05-Apr-1994	PRECISION VOLTAGE REFERENCE CIRCUIT
	Granted	07/785395	25-Oct-1991	5382916	17-Jan-1995	DIFFERENTIAL VOLTAGE FOLLOWER
A	Granted	08/287763	09-Aug-1994	5471131	28-Nov-1995	DIFFERENTIAL VOLTAGE FOLLOWER
	Granted	07/785325	30-Oct-1991	5369309	1 1	ANALOG-TO-DIGITAL CONVERTER AND METHOD OF FABRICATION
C	Granted	08/571693	13-Dec-1995	5631599		ANALOG-TO-DIGITAL CONVERTER AND METHOD OF FABRICATION
В	Granted	08/391490	21-Feb-1995	5481129	02-Jan-1996	ANALOG-TO-DIGITAL CONVERTER
	Granted	121183	16-Nov-1987	1845050		OHMIC CONTACTS AND INTERCONNECTS TO SILICON AND METHOD OF MAKING THE SAME
	A	Granted Granted Granted Granted Granted Granted Granted Granted Granted Granted Granted Granted Granted Granted Granted Granted	Granted 07/716488  Granted 453090  Granted 07/667932  Granted 07/791856  Granted 07/806074  Granted 07/854805  Granted 07/7904848  Granted 07/785395  A Granted 08/287763  Granted 07/785325  C Granted 08/571693  B Granted 08/391490	Granted 07/716488 17-Jun-199  Granted 453090 22-Dec-1989  Granted 07/667932 12-Mar-1991  Granted 07/791856 14-Nov-1991  Granted 07/806074 11-Dec-1991  Granted 07/854805 19-Mar-1982  Granted 07/904848 26-Jun-1992  Granted 07/785395 25-Oct-1991  A Granted 08/287763 09-Aug-1994  Granted 07/785325 30-Oct-1991  C Granted 08/571693 13-Dec-1995 3	Granted 07/716488 17-Jun-1991 5335132  Granted 453090 22-Dec-1989 4999691  Granted 07/667932 12-Mar-1991 5130569  Granted 07/791856 14-Nov-1991 5302859  Granted 07/806074 11-Dec-1991 5229661  Granted 07/854805 19-Mar-1982 5217919  Granted 07/785395 25-Oct-1991 5382916  A Granted 08/287763 09-Aug-1994 5471131  Granted 07/785325 30-Oct-1991 5369309  C Granted 08/571693 13-Dec-1995 5631599  B Granted 08/391490 21-Feb-1995 5481129	Granted 07/682482 09-Apr-1991 5195737 23-Mar-1991

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RD 18903P		Granted	218425	12-Jul-198	8 4903094	20-Feb-199	MEMORY CELL STRUCTURE HAVING RADIATION HARDNESS
RD 19030		Granted	246068	16-Sep-198	8 4903107	20-Feb-199	METHOD OF MAKING A BURIED OXIDE FIELD INSULATION STRUCTURE
RD 17387		Granted	866530	23-May-198	6 4737217	12-Apr-198	A SUBSTRATE FORA SEMICONDUCTOR CHIP PACKAGE AND A METHOD OF FABRICATING THE SAME
SE-862/870		Granted	07/832694	06-Feb-199	2 5298434	29-Mar-1994	SELECTIVE RECRYSTALLIZATION TO REDUCE P- CHANNEL TRANSISTOR LEAKAGE IN SILICON-ON- SAPPHIRE CMOS RADIATION HARDENED IC's.
SE-862/870	A	Granted	08/171280	21-Dec-1993	5391903	21-Feb-1995	SELECTIVE RECRYSTALLIZATION TO REDUCE P- CHANNEL TRANSISTOR LEAKAGE IN SILICON-ON- SAPPHIRE CMOS RADIATION HARDENED IC's.
28-SV-0071	·	Granted	07/781626	24-Oct-1991	5262689	16-Nov-1993	BIMOS CURRENT DRIVER CIRCUIT
28-SV-0065		Granted	07/846286	03-Mar-1992	5640346	17-Jun-1997	ELECTRICALLY PROGRAMMABLE MEMORY CELL
SE-861 ·		Granted	07/831252	23-Dec-1991	5434357	18-Jul-1995	REDUCED SEMICONDUCTOR SIZE PACKAGE
SE-877		Granted	07/855834	23-Mar-1992	5293052		SOI CMOS DEVICE HAVING DIFFERENTIALLY DOPED BODY EXTENSION FOR PROVIDING
SE-852		Granted	07/839426	20-Feb-1992	5228330		IMPROVED BACKSIDE LEAKAGE CHANNEL STOP HERMETIC IC PACKAGE MOISTURE TESTER
SE-826		Granted	07/917635	20-Jul-1992	5856605	05 Jan 1999	BICMOS DEVICES
OL 020		Crancu	07/317033		3030033	00-0an-1999	BIOMIOS DEVICES
RD 19963	,	Granted	07/603495	26-Oct-1990	5184206	ľ	DIRECT THERMOCOMPRESSION BONDING TECHNOLOGY FOR THIN ELECTRONIC POWER CHIP PACKAGES
RD 19963	A .	Granted	07/950553	25-Sep-1992	5206186	,	DIRECT THERMOCOMPRESSION BONDING FECHNOLOGY FOR THIN ELECTRONIC POWER CHIP PACKAGES
RD 19963	В	Granted	08/007300	21-Jan-1993 !	5304847	, i	DIRECT THERMOCOMPRESSION BONDING TECHNOLOGY FOR THIN ELECTRONIC POWER CHIP PACKAGES

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RD 20108		Granted	07/632876	24-Dec-199	5418002	23-May-199	DIRECT BONDING OF COPPER TO ALUMINUM NITRIDE SUBSTRATES
SE-873	В	Granted	08/474647	07-Jun-199	5 5622878	22-Apr-199	7 INTEGRATION OF HIGH VOLTAGE LATERAL CMOS DEVICES IN LOW VOLTAGE MOS ARCHITECTURE USING CMOS COMPATIBLE PROCESS STEPS
SE-898/900		Granted	07/921197	28-Jul-199	2 5362667	08-Nov-199	4 BONDED WAFER PROCESSING
SE-898/900	A	Granted	08/287773	09-Aug-199	4 5517047	14-May-199	6 BONDED WAFER PROCESSING
SE-898/900	В	Granted	08/573551	15-Dec-199	5728624	17-Mar-1998	BONDED WAFER PROCESSING
SE-894		Granted	07/935765	26-Aug-1992	2 5382541	17-Jan-1995	METHOD FOR FORMING RECESSED OXIDE ISOLATION CONTAINING DEEP AND SHALLOW TRENCHES
SE-894	Α .	Granted	08/339966	15-Nov-1994	5504033	02-Apr-1996	METHOD FOR FORMING RECESSED OXIDE ISOLATION CONTAINING DEEP AND SHALLOW TRENCHES
SE-872 ·		Granted	07/925077	05-Aug-1992	5338960	16-Aug-1994	FORMATION OF DUAL POLARITY SOURCE/DRAIN EXTENSIONS IN LATERAL COMPLEMENTARY CHANNEL MOS ARCHITECTURES
SE-895		Granted	07/913844	14-Jul-1992	5279850		GAS PHASE CHEMICAL REDUCTION OF METALLIC BRANDING LAYER OF ELECTRONIC CIRCUIT PACKAGE FOR DEPOSITION OF BRANDING INK
SE-865		Granted	07/930926	14-Aug-1992	5276633	04-Jan-1994	SINE/COSINE GENERATOR AND METHOD
SE-865	A	Granted	08/400811	08-Mar-1995	RE36388	09-Nov-1999	SINE/COSINE GENERATOR AND METHOD
SE-876		Granted	07/930169	14-Aug-1992	5455782		A DIGITAL DECIMATING FILTER WITH VIRTUAL REGISTER SPACE AND VARIABLE DECIMATION RATES
SE-887		Granted	07/911902	10-Jul-1992	5352327	ŀ	REDUCED TEMPERATURE SUPPRESSION OF VOLATILIZATION OF PHOTOEXCITED HALOGEN REACT PRODUCTS FROM SILICON WAFER
28-SV-0027	<u>,, , , , , , , , , , , , , , , , , , ,</u>	Granted	07/935830	26-Aug-1992	5334929	- 1	CIRCUIT FOR PROVIDING A CURRENT PROPORTIONAL TO ABSOLUTE TEMPERATURE

-Gients	( .) St.b	Gase Castrilis	S P AND	* Fileby		als Date:	
28-SV-0058	3	Granted	07/936596	27-Aug-199		15-Feb-199	4 COMPARATOR AMPLIFIER
28-SV-0061		Granted	07/962309	16-Oct-199	2 5307023	26-Apr-199	4 IMPROVED NON-LINEAR OTA
RD 21590	. A	Granted	07/777495	15-Oct-199	1 5100740	31-Mar-199	2 DIRECT BONDED SYMMETRIC-METALLIC- LAMINATE/SUBSTRATE STRUCTURES
28-SV-0079		Granted	07/941736	08-Sep-199	2 5347169	13-Sep-199	4 INDUCTIVE LOAD DUMP CIRCUIT
SE-907	A	Granted	08/430312	28-Apr-1995	5 5849627	15-Dec-1998	BONDED WAFER PROCESSING WITH OXIDATIVE BONDING
SE-912		Granted	07/930737	14-Aug-1992	5428492	27-Jun-1995	CURRENT DRIVER HAVING VOLTAGE TRANSITION FAILURE-BASED SHORT CIRCUIT PROTECTION CIRCUIT
SE-902		Granted	07/984187	20-Nov-1992	5416351	16-May-1995	ELECTROSTATIC DISCHARGE PROTECTION
28-MT-0047		Granted	08/001752	.07-Jan-1993	5382825	17Jan-1995	SPIRAL EDGE PASSIVATION STRUCTURE FOR SEMICONDUCTOR DEVICES
SE-915	A	Granted	08/440707	15-May-1995 :	5717617	10-Feb-1998	RATE CHANGE FILTER AND METHOD
SE-911		Granted	08/029860	25-Mar-1993	5272104	1 1	BONDED WAFER PROCESS INCORPORATING DIAMOND INSULATOR
SE-911	A	Granted	08/513950	04-Dec-1995	5650639	22-Jul-1997	BONDED WAFER PROCESS INCORPORATING DIAMOND INSULATOR
SE-879/886		Granted	07/930930	14-Aug-1992	5440506	08-Aug-1995	SEMICONDUCTOR ROM DEVICE AND METHOD
SE-879/886	A	Granted	08/346178	21-Nov-1994	5586072	17-Dec-1996	SEMICONDUCTOR ROM DEVICE AND METHOD
SE-879/886	В	Granted	08/345689	21-Nov-1994 5	5563834	08-Oct-1996	SEMICONDUCTOR ROM DEVICE AND METHOD
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Official Ref	Saca	se i ligils.	Age	P. (Date)		( Issuele y	
SE-879/886	C	Granted	08/450878	26-May-19	95 5650971	22-Jul-199	7 SEMICONDUCTOR ROM DEVICE AND METHOD
						بو	
SE-879/886	D	Granted	08/450879	26-May-199	55544095	06-Aug-199	6 SEMICONDUCTOR ROM DEVICE AND METHOD
					1		
28-SV-0080	<del> </del>	Granted	07/980570	20-Nov-199	25207071	15 Ech 100	4 AMPLIFIER WITH HIGH COMMON MODE
20-37-0000		Granteu	07/900570	20-1404-198	12/520/0/1	15-Feb-199	REJECTION
					ļ		
28-SV-0081	+	Granted	07/979209	20-Nov-199	2 5406223	11-Apr-199	AMPLIFIER SYSTEM FOR LOW LEVEL SIGNAL
SE-889		Granted	07/995442	23-Dec-199	2 5312262	17-May-1994	DECOUPLING TOOL MECHANISM FOR ELECTRICAL CONNECTORS
	1			·			LEECTRICAL CONNECTORS
SE-866/867	<u> </u>	Granted	07/930170	14 Aug 1001	2 5402504	20 Fab 4000	DIGITAL DOWN CONVERTER AND METHOD
SE-000/00/		Granted	07/930170	14-Aug-1992	2 3493361	20-Feb-1990	DIGITAL DOWN CONVERTER AND METHOD
				i .			
SE-866/867	A	Granted	08/478683	07-Jun-1995	5633815	27-May-1997	DIGITAL DOWN CONVERTER AND METHOD
		ļ					,
	l			•			
SE-866/867.	В	Granted	08/457234	01-Jun-1995	5617344	01-Арг-1997	DIGITAL DOWN CONVERTER AND METHOD
				•	İ		·
SE-866/867	С	Crostod	00/450950	01-Jun-1995	r=70202	20 0-1 1000	DIGITAL DOWN CONVERTER AND METHOD
SE-000/00/		Granted	08/456859	01-200-1995	5570392	29-OCI-1996	DIGITAL DOWN CONVERTER AND METHOD
		· ·	1	·		:	
SE-866/867	D	Granted	08/478682	07-Jun-1995	5757794	26-May-1998	DIGITAL DOWN CONVERTER AND METHOD
SE-933		Granted	08/023117	26-Feb-1993	5357089	i , i	CIRCUIT AND METHOD FOR EXTENDING THE SAFE OPERATING AREA OF A BJT
							OF EIGHTING ANEA OF A BOT
28SV00076	-	Granted	08/082546	28-Jun-1993	F367211	22 Nov 1004	DIFFERENTIAL AMPLIFIER WITH HYSTERISIS
203 400070		Granteu	08/082348	20-3011-1333	5507211	22-NOV-1994	DIFFERENTIAL AWIFLIPLER WITH THOTERIOIS
SE-932	A	Granted	08/471759	06-Jun-1995	5683939	04-Nov-1997	DIAMOND INSULATOR DEVICES AND METHOD OF
i				j			FABRICATION
28SV0087		Granted	08/066854	25-May-1993	5359236	25-Oct-1994	NTEGRATED CIRCUIT THERMAL SENSOR
	i			·	İ		
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Comme	S15G	se s Status		A Mai Date		Se esperie	
SE-901		Granted	08/030980	12-Mar-199	3 5370568	06-Dec-199	4 CURING OF A TUNGSTEN FILAMENT IN AN ION IMPLANTER
SE-926	<del>- </del>	Granted	08/066355	21-May-199	3 5639688	17-Jun-199	7 METHOD OF MAKING INTEGRATED CIRCUIT STRUCTURE WITH NARROW LINE WIDTHS
SE-926	A 	Granted	08/460993	05-Jun-199	5 5773891	30-Jun-199	METHOD OF MAKING INTEGRATED CIRCUIT STRUCTURE WITH NARROW LINE WIDTHS
SE-919		Granted	08/053244	28-Apr-1993	3 5373183	13-Dec-1994	INTEGRATED CIRCUIT WITH IMPROVED REVERSE BIAS BREAKDOWN
SE-920		Granted	08/053243	28-Apr-1993	6008512	28-Dec-1999	SEMICONDUCTOR DEVICE WITH INCREASED MAXIMUM TERMINAL VOLTAGE
SE-920	A	Granted	08/463560	<b>05-Jun-199</b> 5	5665634	09-Sep-1997	SEMICONDUCTOR DEVICE WITH INCREASED MAXIMUM TERMINAL VOLTAGE
SE-931		Granted	08/090978	09-Jul-1993	5341009	_	FAST CHARGING MOS CAPACITOR STRUCTURE FOR HIGH MAGNITUDE VOLTAGE OF EITHER POSITIVE OR NEGATIVE POLARITY
SE-934		Granted	08/135093	12-Oct-1993	5561607		METHOD OF MANUFACTURE OF MULTI-CELL INTEGRATED CIRCUIT ARCHITECTURE
SE-948		Granted	08/106251	13-Aug-1993	5581475		METHOD FOR INTERACTIVELY TAILORING TOPOGRAPHY OF INTEGRATED CIRCUIT LAYOUT IN ACCORDANCE WITH ELECTROMIGRATION MODEL-BASED MINIMUM WIDTH METAL AND
SE-909	Α .	Granted	08/292588	18-Aug-1994	5448102		TRENCH ISOLATION STRESS RELIEF
		<del>-</del>					
SE-909	В	Granted	08/465246	05-Jun-1995	5683075	04-Nov-1997	TRENCH ISOLATION STRESS RELIEF
SE-916		Granted	08/125411	22-Sep-1993	5552345		DIE SEPARATION METHOD FOR SILICON ON DIAMOND CIRCUIT STRUCTURES
SE-929		Granted	08/108358	18-Aug-1993	5585661		SUBMICRON BONDED SOI BY TRENCH PLANARIZATION
RD 15503		Granted	07/595800	02-Apr-1984	1871617	i i	OHMIC CONTACTS AND INTERCONNECTS TO SILICON AND METHOD OF MAKING SAME
	<u> </u>	<u> </u>	<u> </u>				

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SE-938		Granted	08/123157	07-Sep-199	33 5395774	07-Mar-199	95 METHODS FOR FORMING A TRANSISTOR HAVING AN EMITTER WITH ENHANCED EFFICIENCY
SE-952		Granted	08/118063	08-Sep-199			PHOTORESIST SACRIFICIAL LAYER & TWO-STEP ETCHING PROCESS FOR PLANARIZING OXIDE-FILLED SHALLOW TRENCH STRUCTURE
SE-950		Granted	08/271292	06-Jul-199	4 5450326	12-Sep-199	5 GRAPHICAL DISPLAY DISCRIMINANT FACTOR INDICATOR FOR ANOMALY IDENTIFICATION IN SEMICONDUCTOR MANUFACTURE BATCH PROCESS
SE-906		Granted	07/939786	03-Sep-199	2 5387555	07-Feb-199	5 BONDED WAFER PROCESSING WITH METAL SILICIDATION
SE-906	A	Granted	08/351933	08-Dec-1994	5569620	29-Oct-199	BONDED WAFER PROCESSING WITH METAL SILICIDATION
SE-954-SP	·	Granted	08/090617	12-Jul-1993	5809410	15-Sep-1998	LOW VOLTAGE RF AMPLIFIER AND MIXER WITH SINGLE BIAS BLOCK AND METHOD
SE-957		Granted	08/135092	12-Oct-1993	5576695	19-Nov-1996	RESISTANCE-MEASUREMENT BASED ARRANGEMENT FOR MONITORING INTEGRITY OF TRAVEL PATH GROUND LINK IN ELECTRONIC COMPONENT HANDLING APPARATUS
SE-959		Granted	08/314489	28-Sep-1994	5637908	10-Jun-1997	STRUCTURE AND TECHNIQUE FOR TAILORING EFFECTIVE RESISTIVITY OF A SIPOS LAYER BY PATTERNING AND CONTROL OF DOPANT INTRODUCTION
SE-922	·	Granted	07/993585	21-Dec-1992	5345236	06-Sep-1994	ANALOG-TO-DIGITAL CONVERTER AND METHOD
SE-953		Granted	08/198002	17-Feb-1994	5574618	12-Nov-1996	ESD PROTECTION USING SCR CLAMPING
				·	·		
28-SV-0085		Granted	08/192398	03-Feb-1994	5583442	10-Dec-1996	DIFFERENTIAL VOLTAGE MONITOR USING A BRIDGE CIRCUIT WITH RESISTORS ON AND OFF OF AN INTEGRATED CIRCUIT
SE-956		Granted	08/190998	03-Feb-1994	5526768	·	METHOD FOR PROVIDING A SILICON AND DIAMOND SUBSTRATE HAVING A CARBON TO SILICON TRANSITION LAYER AND APPARATUS THEREOF
SE-956	Α	Granted	08/587953	17-Jan-1996	_		METHOD FOR PROVIDING A SILICON AND DIAMOND SUBSTRATE HAVING A CARBON TO SILICON TRANSITION LAYER AND APPARATUS THEREOF
SE-963		Granted	08/180666	13-Jan-1994	5446368	,	VOLTAGE INDEPENDENT SYMMETRICAL CURRENT SOURCE WITH CROSS-COUPLED TRANSISTORS

Figura Rose Still	Case 3 Selin	7 And 7	FILERIE		/ Issence	
28-SV-0093	Granted	08/204710	02-Mar-19	94 5508551	16-Apr-199	CURRENT MIRROR WITH SATURATION LIMITING
					14	
28-SV-0092	Granted	08/204718	. 02 14 40/	04/500050	04.14==400	
28-5V-0092	Granted	06/204718	UZ-War-19	94 5608259	04-Mar-199	7 REVERSE CURRENT FLOW PREVENTION IN A DIFFUSED RESISTOR
28-SV-0090	Granted	08/204711	02-Mar-199	5420499	30-May-199	5 CURRENT RISE AND FALL TIME LIMITED VOLTAGE
				1		FOLLOWER
SE-974	Granted	08/497124	30-Jun-199	5 5546038	13-Aug-199	6 SCR-INDUCTOR TRANSIENT CLAMP
		100/10/12/	00 00 100	00,000	107.09 100	SOLUTION TO THE SEAVE
SE-973	Pending	08/276290	18-Jul-199	4		CMOS INTEGRATED CIRCUIT ARCHITECTURE INCORPORATION DEEP IMPLANTED EMITTER
						REGION TO FORM AUXILIARY BIPOLAR
SE-935/936	Granted	08/299741	01-Sep-199	4 5541538	30-Jul-1996	TRANSISTOR HIGH SPEED COMPARATOR
SE-981	Granted	08/235979	02-May-199	45519732	21-May-1996	DIGITAL BASEBAND TO IF CONVERSION IN CELLULAR BASE STATIONS
<u> </u>			-	1		·
28-SV-0091 A	Granted	08/562609	24-Nov-1995	5610792	11-Mar-1997	APPARATUS FOR CONTROLLING THE RESET OF A
						BUS CONNECTED TRANSCEIVER
SE-976	Granted	08/265355	24-Jun-1994	E42200	42 tu- 4005	PROCESS FOR MANUFACTURING A MULTI-PORT
. SE-970	Granted	08/203333	24-Juli-1994	3423009		ADHESIVE DISPENSING TOOL
				:		
SE-982	Granted	08/279027	22-Jul-1994	5622890	, ,	METHOD OF MAKING CONTACT REGIONS FOR
						NARROW TRENCHES IN SEMICONDUCTOR DEVICES
SE-983	Granted	08/301622	07-Sep-1994	5574572	12-Nov-1996	VIDEO SCALING METHOD AND DEVICE
SE-984/985	Granted	08/269470	30-Jun-1994	5808489		HIGH SPEED A/D CONVERTER AND SLEW CONTROLLED PULSE DETECTOR
		•	·			
SE-987	Granted	08/497008	30-Jun-1995	5621478	15-Apr-1997	MULTISTANDARD DECODER FOR VIDEO SIGNALS
					ŀ	AND VIDEO SIGNAL DECODING METHOD
05.000				=====		
SE-988	Granted	08/497181	30-Jun-1995	5619270		SAMPLE RATE CONVERTER AND SAMPLE RATE CONVERSION METHOD
					. [	
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SE-989		Granted	08/496868	30-Jun-199	5 5621477	15-Apr-199	7 DIGITAL DECODER AND METHOD FOR DECODING COMPOSITE VIDEO SIGNALS
SE-993		Granted	08/267436	29-Jun-1994	1 5515417	07-May-199	6 GROUND KEY DETECTOR FOR A SLIC
SE-994		Granted	08/266567	28-Jun-1994	5614867	25-Mar-199	CURRENT FOLLOWER WITH ZERO INPUT
SE-1001-TL		Granted ·	08/380410	30-Jan-1995	5528682	18-Jun-1996	DOUBLE DUTY CAPACITOR CIRCUIT AND METHOD
28-MT-0066		Granted	08/332300	31-Oct-1994	5569957	29-Oct-1996	LOW INDUCTANCE POWER PACKAGE DESIGN
SE-991		Granted .	08/267434	29-Jun-1994	5515434	07-May-1996	IMPEDANCE SETTING CIRCUIT FOR A SLIC
SE-972	A	Granted	08/543754	16-Oct-1995	5652153		JFET STRUCTURES FOR SEMICONDUCTOR DEVICES WITH COMPLEMENTARY BIPOLAR TRANSISTORS & METHOD
SE-995		Granted	08/269133	30-Jun-1994	5517565		AN INTEGRATED RINGER RELAY CIRCUIT AND METHOD
SE-971	,	Granted	08/419610	10-Apr-1995	5644309	1 1	DIGITAL COMPONENT TESTING APPARATUS AND METHOD
SE-1022-MS		Granted	08/537051	29-Sep-1995	5621355		SAMPLED DATA BIASING OF CONTINUOUS TIME INTEGRATED CIRCUIT
SE-1010-TD		Granted	08/405660	17-Mar-1995	5614422		PROCESS FOR DOPING TWO LEVELS OF A DOUBLE POLY BIPOLAR TRANSISTOR AFTER FORMATION OF SECOND POLY LAYER
SE-1020-TL		Granted	08/340342	14- <u>N</u> ov-1994 5	649009		A DIFFERENTIAL LONGITUDINAL AMPLIFIER FOR SUBSCRIBER LINE INTERFACE CIRCUIT
SE-1025-TD		Granted	08/503048	17-Jul-1995 5	650344		NON-UNIFORMLY NITRIDED GATE OXIDE AND METHOD
SE-1027-TD		Granted	08/387233	13-Feb-1995 5	547896		DIRECT ETCH FOR THIN FILM RESISTOR USING A HARD MASK

Clutto.	SiliCa	e Madic			e per le	a space	
SE-1041-TD		Granted	08/383261	03-Feb-199	55 5567978	22-Oct-199	6 HIGH VOLTAGE, JUNCTION ISOLATION SEMICONDUCTOR DEVICE HAVING DUAL CONDUCTIVITY TYPE BURIED REGIONS AND ITS PROCESS OF MANUFACTURE
SE-1023-SP		Granted	08/331015	28-Oct-199	4 5598157	28-Jan-199	7 SIGMA DELTA ANALOG TO DIGITAL CONVERTER WITH THREE POINT CALIBRATION APARATUS AND METHOD
SE-1030-SP		Granted	08/441726	16-May-199	5 5576654	19-Nov-199	6 A BI-MOS DRIVER CIRCUIT WITH REDUCED POWER SUPPLY GLITCHES
SE-1039-SP		Granted	08/372118 °	13-Jan-199	5 5636274	03-Jun-199	7 SWITCH CONTROLLER AND METHOD
SE-1057-TL	-	Granted	08/380413	30-Jan-199	5 5812658	22-Sep-1998	METHOD AND CIRCUIT FOR FAILSAFE SWITCH- HOOK DETECTION DURING FAULT IN A TELEPHONE SYSTEM
SE-1058-TL		Granted	08/380411	30-Jan-1995	5659570	19-Aug-1997	CIRCUIT AND METHOD FOR LOOPBACK TEST AND ON-HOOK TRANSMISSION INTEGRATED INTO A TELEPHONE SUBSCRIBER LINE INTERFACE CIRCUIT
SE-1050-MS		Granted	08/505671	21-Jul-1995	5621307	15-Apr-1997	FAST RECOVERY TEMPERATURE COMPENSATED PRECISION REFERENCE SOURCE
SE-1036-TD		Granted	08/705536	29-Aug-1996	5798557	25-Aug-1998	LID WAFER BOND PACKAGING AND MICROMACHINING
SE-1048-TD		Granted	08/443242	17-May-1995	5603779	18-Feb-1997	BONDED WAFER
SE-1069-AP		Granted	08/395814	28-Feb-1995	5724370	03-Mar-1998	CRC GENERATION & DETECTION METHOD
SE-1070-AP	······································	Granted	08/395590	28-Feb-1995	5526392		METHOD OF SCALING THE OUTPUTS OF A BINARY COUNTER
SE-1071-AP		Granted	08/395863	28-Feb-1995	5678030		MODIFICATION OF TIMING IN AN EMULATOR CIRCUIT AND METHOD
SE-1072-AP		Granted	08/395591	28-Feb-1995	5661736		MULTIPLE USE TIMER AND METHOD FOR PULSE WIDTH GENERATION, ECHO FAILURE DETECTION, AND RECEIVE PULSE WIDTH MEASUREMENT
SE-1034-TD		Granted	08/382346	01-Feb-1995	5625566		CONFIGURATION DEPENDENT AUTO-BIASING OF BIPOLAR TRANSISTOR
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SE-939	a tradeia	Granted	08/552711 .	03-Nov-199	5 5669599	22-Sep-199	7 MAGNETIC BOATS
		-				*	
SE-1000-TD		Granted	08/386785	10-Feb-199	5 5682336	28-Oct-199	7 SIMULATION OF NOISE BEHAVIOR OF NON-
						1 20 000 100	LINEAR CIRCUIT
			·				
SE-1087-SP		Granted	08/438251	10-May-199	5 5617090	01-Apr-199	MULTICHANNEL SIGMA-DELTA A/D CONVERTERS WITH IMPROVED THROUGHPUT
	1						
SE-1081-IP	†	Granted	08/438636	10-May-199	5 5610503	11-Mar-1997	LOW VOLTAGE DC-TO-DC POWER CONVERTER
							INTEGRATED CIRCUIT AND RELATED METHODS
SE-1074-MS	<del> </del>	Granted	08/490566	15-Jun-199	5 5525869	11-Jun-1996	EFFICIENT BATTERY OPERATED INVERTER
		1.			}		CIRCUIT FOR CAPACITIVE LOADS SUCH AS ELECTROLUMINESCENT LAMPS
1075 110		<u> </u>		10.1.10			
SE-1075-MS		Granted	08/490016	13-Jun-1995	5 5557175	17-Sep-1996	BATTERY OPERATED INVEERTER CIRCUIT FOR CAPACITIVE LOADS SUCH AS
	. ·	1					ELECTROLUMINESCENT LAMPS
SE-1097-AP		Granted	08/505695	21-Jul-1995	5642247		AUTOMATIC FAULT MONITORING SYSTEM AND MOTOR CONTROL SYSTEM INCORPORATING
		·					SAME
SE-1104-TD	-	Granted	08/481115	07-Jun-1995	5750432		DEFECT CONTROL IN FORMATION OF
	·						DIELECTRICALLY ISOLATED SEMICONDUCTOR DEVICE REGIONS
SE-1107-TD		Granted	08/497404	30-Jun-1995	5772151	20 Jun 1009	SEMI-INSULATING WAFER
SE-1107-1D		Gianteu	00/45/404	20-2011-1993	5//3151	30-3011-1990	SEMI-INSULATING WAPER
		<u> </u>					
SE-1102-MS		Granted	08/490952	15-Jun-1995	5539707	23-Jul-1996	ELECTROLUMINESCENT LAMP DRIVER SYSTEM
		<u> </u>			· · · · · · · · · · · · · · · · · · ·		
SE-1131-TD	· :	Granted	08/461951	05-Jun-1995	5646067	1	METHOD OF BONDING WAFERS HAVING VIAS
		ļ					INCLUDING CONDUCTIVE MATERIAL
SE-1132-TD	•	Granted	08/461643	05-Jun-1995	5608264	04-Mar-1997	SURFACE MOUNTABLE INTEGRATED CIRCUIT
							WITH CONDUCTIVE VIAS
OF 4400 TD			00/10/007	05 1 1005	504.4000	20.0	DESCRIPTION OF THE PROPERTY OF
SE-1133-TD		Granted	08/461037	05-Jun-1995	2614669	• •	INTEGRATED CIRCUIT WITH COAXIAL ISOLATION AND METHOD
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SE-1134-TD		Granted	08/463388	05-Jun-1995	5668409	•	NTEGRATED CIRCUIT WITH EDGE CONNECTIONS AND METHOD
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SE-1135-TD		Granted	08/462876	05-Jun-199	5682062	28-Oct-199	7 SYSTEM FOR INTERCONNECTING STACKED INTEGRATED CIRCUITS
SE-1114-TD		Granted	08/512323	08-Aug-199	5 5696452	09-Dec-199	7 ARRANGEMENT & METHOD FOR IMPROVING ROOM-TEMPERATURE TESTABILITY OF CMOS INTEGRATED CIRCUITS OPTIMIZED FOR CRYOGENIC TEMPERATURE OPERATOR
SE-1052-TD		Granted	08/474559	07-Jun-199	5 5777362	07-Jul-199	BHIGH EFFICIENCY QUASI-VERTICAL DMOS IN A CMOS OR BICMOS PROCESS
SE-1053-TD		Granted	08/483691	07-Jun-199	5 5689129	18-Nov-199	HIGH EFFICIENCY POWER MOS SWITCH
SE-1054-TD		Granted	08/483692	07-Jun-199	5 5684305	04-Nov-1997	PILOT TRANSISTOR FOR QUASI-VERTICAL DMOS
SE-1122-TL	·. ·	Granted	08/494395	26-Jun-1995	5736885	07-Apr-1998	OFFSET ADJUSTMENT FOR FULLY DIFFERENTIAL AMPLIFIERS
SE-1123-TL		Granted	08/493454	23-Jun-1995	5617473	01-Apr-1997	SIGN BIT INTEGRATOR AND METHOD
SE-1062-SP		Granted	08/515435	15-Aug-1995	5701097	23-Dec-1997	STATISTICALLY BASED CURRENT GENERATOR CIRCUIT
SE-1060-TD		Granted	08/481116	07-Jun-1995	5580816	03-Dec-1996	LOCAL OXIDATION PROCESS FOR HIGH FIELD THRESHOLD APPLICATIONS
SE-1028-LN		Granted	08/507192	26-Jul-1995	5581444		DEVICE AND METHOD FOR ENHANCING THERMAL AND HIGH FREQUENCY PERFORMANCE OF INTEGRATED CIRCUIT PACKAGES
SE-1147-TL		Granted	08/509462	31-Jul-1995	5712870		PACKET HEADER GENERATION AND DETECTION CIRCUITRY
SE-1151-TL		Granted	08/509589	31-Jul-1995	5675339		A/D REFERENCE LEVEL ADJUSTMENT CIRCUIT TO MAINTAIN OPTIMUM DYNAMIC RANGE AT THE A/D
SE-1148-TL		Granted	08/509588	31-Jul-1995	5654991	· · ·	FAST ACQUISITION BIT TIMING LOOP CIRCUIT METHOD AND APPARATUS
SE-1149-TL		Granted	08/509587	31-Jul-1995	5883921	į	SHORT BURST ACQUISITION CIRCUIT AND METHOD FOR DIRECT SEQUENCE SPREAD SPECTRUM LINKS

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		Constant	08/509586	31-Jul-199	E 5722405	24 May 100	8 A METHOD OF ESTIMATING SIGNAL QUALITY FOR
SE-1150-TL		Granted	06/309366	. 31-Jul-199	515732105	24-Wai-199	A DIRECT SEQUENCE SPREAD SPECTRUM RECEIVER DEVICE
SE-1153-TL		Granted	08/512405	08-Aug-199	5 5606288	25-Feb-199	7 DIFFERENTIAL TRANSIMPEDANCE AMPLIFIER
SE-1117-TL		Granted	08/527548	13-Sep-1999	5 5610093	11-Mar-199	7 METHOD OF MANUFACTURING A PROGRAMMABLE HYBRID BALANCE NETWORK
SE-1037-TD		Granted	08/536257	29-Sep-1995	5830279	03-Nov-1998	DEVICE AND METHOD FOR IMPROVING CORROSION RESISTANCE AND ETCH TOOL INTEGRITY IN DRY METAL ETCHING
SE-1106-TD	,	Granted	08/596079	06-Feb-1996	5883414	16-Mar-1999	ELECTROSTATIC DISCHARGE PROTECTION DEVICE
SE-1138-TL		Granted	08/506978	28-Jul-1995	5654662	05-Aug-1997	INVERTED BJT CURRENT SOURCES/SINKS IN RF CIRCUITS AND METHODS
SE-1162-IP		Granted	08/602287	16-Feb-1996	5717322	10-Feb-1998	METHOD TO IMPROVE THE PEAK-CURRENT LIMIT IN SLOPE-COMPENSATED, CURRENT-MODE DC/DC CONVERTERS
SE-1158-IP		Granted	08/799959	14-Feb-1997	5793193		DC-TO-DC CONVERTER HAVING ENHANCED CONTROL FEATURES AND ASSOCIATED METHODS
SE-1175-MS	<u>.</u>	Granted	08/584366	11-Jan-1996	5668468	, .	COMMON MODE STABILIZING CIRCUIT AND METHOD
SE-1118-TL		Granted	08/552379	03-Nov-1995	5717736		TESTING CIRCUIT FOR A CODEC HYBRID BALANCE NETWORK
SE-1137-AP		Granted	08/512417	08-Aug-1995	5614852	1	WIDE COMMON MODE RANGE COMPARATOR AND METHOD
SE-999		Granted	08/427231	24-Apr-1995	5602052		METHOD OF FORMING DUMMY ISLAND CAPACITOR
SE-1155-TL		Granted	08/608728	29-Feb-1996	5831423		PHASE METER AND METHOD OF PROVIDING A VOLTAGE INDICATIVE OF A PHASE DIFFERENCE
SE-1179-MS		Granted	08/601401	14-Feb-1996	5798724		INTERPOLATING DIGITAL TO ANALOG CONVERTER ARCHITECTURE FOR IMPROVED SPURIOUS SIGNAL SUPPRESSION

G. Chemies	Sales		Aniele			al 15 issDaic 3	
SE-1119-TL		Granted	08/590940	24-Jan-199	6 5680072	21-Oct-199	7 DIFFERENTIAL INTERPOLATION SWITCHED CAPACITOR FILTER AND METHOD
SE-1173-TD		Granted	08/586556	16-Jan-199	6 5670413	23-Sep-199	METHOD & APPARATUS FOR RADIATION HARDENED ISOLATION
SE-1191-MS		Granted	08/613381	07-Mar-199	5 5677599	14-Oct-1997	A CIRCUIT FOR DRIVING AN ELECTROLUMINESCENT LAMP
SE-1178-MS	·	Granted	08/608812	29-Feb-1996	5742204	21-Apr-1998	DIGITALLY PROGRAMMABLE DIFFERENTIAL ATTENUATOR WITH TRACKING COMMON MODE REFERENCE
SE-1061-MS		Granted	08/560289	17-Nov-1995	5666083	09-Sep-1997	IMPROVED DISCRETE PROGRAMMING METHODOLOY AND CIRCUIT FOR AN ACTIVE TRANSCONDUCTANCE C-FILTER
SE-1164-TD		Granted	08/637132	24-Apr-1996	5717243	10-Feb-1998	AN INTEGRATED CIRCUIT WITH AN IMPROVED INDUCTOR STRUCTURE AND METHOD OF FABRICATION
SE-1089-AP	A	Granted	08/652933	24-May-1996	5675281	07-Oct-1997	METHOD AND CIRCUIT FOR PREVENTING FORWARD BIAS OF A PARASITIC DIODE IN AN INTEGRATED CIRCUIT
SE-905-TD	A	Granted	08/573099	15-Dec-1995	5729038	17-Mar-1998	SILICON GLASS-BONDED WAFERS
SE-822-SP	E	Granted	08/645139	13-May-1996	5659261		ANALOG-TO-DIGITAL CONVERTER AND METHOD OF FABRICATION
SE-873	c	Granted	08/612695	08-Mar-1996	5650658	}	INTEGRATION OF HIGH VOLTAGE LATERAL CMOS DEVICES IN LOW VOLTAGE MOS ARCHITECTURE USING CMOS COMPATIBLE PROCESS STEPS
SE-822-SP	D	Granted	08/630874	02-Apr-1996	5682111		ANALOG-TO-DIGITAL CONVERTER AND METHOD OF FABRICATION
SE-1196-TD		Granted	08/646471	08-May-1996	5856700		SEMICONDUCTOR DEVICE WITH DOPED SEMICONDUCTOR AND DIELECTRIC TRENCH SIDEWALL LAYERS
SE-1188-TD		Granted	08/643295	08-May-1996	5837603		PLANARIZATION METHOD BY THE USE OF PARTICLE DISPERSION AND SUBSEQUENT THERMAL FLOW
SE-1112-LN		Granted	08/640108	30-Apr-1996	5686822		METHOD OF MAKING A REFERENCE CURRENT GENERATOR

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SE-1078-TD		Granted	08/650688	20-May-199	6 5825092	20-Qct-199	8 INTEGRATED CIRCUIT WITH AN AIR BRIDGE HAVING A LID
SE-1099-TD		Granted	08/587692	17-Jan-199	5 5587103;	24-Dec-199	6 COMPOSITION, AND METHOD FOR USING SAME, FOR ETCHING METALLIC ALLOYS FROM A SUBSTRATE
SE-1063-TD		Granted	08/654316	28-May-1996	5965933	12-Oct-199	SEMICONDUCTOR PACKAGING APPARATUS
SE-1033-TD		Granted	08/650762	20-May-1996	5949144	07-Sep-199	PRE-BOND CAVITY AIR BRIDGE
SE-1211-TD		Granted	08/637937	26-Apr-1996	5933746	03-Aug-1999	WAFER TRENCH ARTICLE AND PROCESS
SE-1198-TD		Granted	08/654393	28-May-1996	5804846	08-Sep-1998	PROCESS FOR FORMING A SELF-ALIGNED RAISED SOURCE/DRAIN MOS DEVICE AND DEVICE THEREFROM
SE-1038-IP		Granted	08/493824	22-Jun-1995	5627489	06-May-1997	LEVEL SHIFTER WITH IMPROVED REJECTION OF VOLTAGE VARIATIONS
SE-1157-SP		Granted	08/671025	25-Jun-1996	5930301		UP-CONVERSION MECHANISM EMPLOYING SIDE LOBE-SELECTIVE PRE-DISTORTION FILTER AND FREQUENCY REPLICA-SELECTING BANDPASS FILTER RESPECTIVELY INSTALLED UPSTREAM
SE-1182-TD		Granted	08/669066	24-Jun-1996	5920219		CLOCK -CONTROLLED PRECISION MONOSTABLE CIRCUIT
SE-811	A	Pending	08/674585	02-Jul-1996			NEGATIVE BIASING OF ISOLATION TRENCH FILL TO ATTRACT MOBILE POSITIVE IONS AWAY FROM BIPOLAR DEVICE REGIONS
SE-1250-TD		Granted	08/666258	20-Jun-1996	5808353	15-Sep-1998	RADIATION HARDENED DIELECTRIC FOR EEPROM
SE-1041-TD	A	Granted	08/683599	15-Jul-1996	5837553		HIGH VOLTAGE, JUNCTION ISOLATION SEMICONDUCTOR DEVICE HAVING DUAL CONDUCTIVITY TYPE BURIED REGIONS AND ITS PROCESS OF MANUFACTURE
SE-1176-MS		Granted	08/606958	23-Feb-1996	5953379	14-Sep-1999	CURRENT-CONTROLLED CARRIER TRACKING FILTER FOR IMPROVED SPURIOUS SIGNAL SUPPRESSION
SE-1177-MS		Granted	08/637140	24-Apr-1996	736903		CARRIER BUFFER HAVING CURRENT- CONTROLLED TRACKING FILTER FOR SPURIOUS SIGNAL SUPPRESSION

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SE-1218-TD		Granted	08/671243	27-Jun-199	6 5841,169	24-Nov-199	INTEGRATED CIRCUIT CONTAINING DEVICES DIELECTRICALLY ISOLATED AND JUNCTION ISOLATED FROM A SUBSTRATE
SE-1219-TD		Granted	08/671157	28-Jun-1990	5817564	06-Oct-199	8 DOUBLE DIFFUSED MOS DEVICE AND METHOD
SE-1228-TD		Granted	08/673396	28-Jun-1996	5663860	02-Mar-199	8 HIGH VOLTAGE PROTECTION CIRCUITS
28-SP-1401	A	Granted	08/656987	06-Jun-1996	5870266	09-Feb-199	9 BRIDGE CONTROL CIRCUIT AND METHOD
SE-1186-MS		Granted	08/671781	20-Jun-1996	5841324	24-Nov-1998	B CHARGE BASED FREQUENCY LOCKED LOOP AND METHOD
SE-1137-AP	A	Granted	08/719873	25-Sep-1996	5789949	04-Aug-1998	WIDE COMMON MODE RANGE COMPARATOR AND METHOD
SE-1248-TD		Granted	08/707271	03-Sep-1996	5770880	23-Jun-1998	P COLLECTOR HV PMOS SWITCH VT ADJUSTED SOURCE
SE-1235-DA		Granted	08/714019	11-Sep-1996	5790060		DIGITAL-TO-ANALOG CONVERTER HAVING ENHANCED CURRENT STEERING AND ASSOCIATED METHOD
SE-1215-DA		Granted	08/712027	11-Sep-1996	5771012		INTEGRATED CIRCUIT ANALOG-TO-DIGITAL CONVERTER AND ASSOCIATED CALIBRATION METHOD AND APPARATUS
SE-1092-TL		Granted	08/687995	29-Jul-1996	5767757		ELECTRICALLY VARIABLE R/C NETWORK AND METHOD
SE-1009-DA		Granted	08/707380	04-Sep-1996	5923209	1 1	TWO TRIM CURRENT SOURCE AND METHOD FOR A DIGITAL-TO-ANALOG CONVERTER
SE-1083-TD		Granted	08/726183	04-Oct-1996	5708549		INTEGRATED CIRCUIT HAVING ENHANCED TRANSIENT VOLTAGE PROTECTION AND ASSOCIATED METHODS
SE-1048-TD	A	Granted	08/710694	19-Sep-1996 5	5744852	28-Apr-1998	BONDED WAFER
SE-822-SP	F	Granted	08/739898	30-Oct-1996 5	994755		ANALOG-TO-DIGITAL CONVERTER AND METHOD OF FABRICATION

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SE-1032-TD		Granted	08/726659	07-Oct-199	6 5807783	15-Sep-199	8 SURFACE MOUNT DIE BY HANDLE REPLACEMENT
							,
SE-1254-AP		Granted	08/738393	24-Oct-199	6 5719326	17-Feb-199	8 RECONFIGURABLE FILTER SYSTEM
SE-921-TD	В	Granted	08/733368	17-Oct-199	6 5872044	16-Feb-199	LATE PROCESS METHOD AND APPARATUS FOR TRENCH ISOLATION
SE-1026-TD	A	Granted	08/754596	20-Nov-199	6 5833758	10-Nov-1998	PLASMA CLEANING METHOD FOR IMPROVED DIE TO SUBSTRATE SOLDERABILITY
SE-992	A	Granted	08/741639	28-Oct-1990	5 5841182	24-Nov-1998	CAPACITOR STRUCTURE IN A BONDED WAFER AND METHOD OF FABRICATION
SE-1234-TL		Granted	08/725924	04-Oct-1996	5 5812029	22-Sep-1998	GAIN CONTROL CIRCUIT AND METHOD
SE-921-TD	С	Granted	08/745104	07-Nov-1996	5920108	06-Jul-1999	LATE PROCESS METHOD AND APPARATUS FOR TRENCH ISOLATION
SE-967	В	Granted	08/754597	20-Noy-1996	5882423	<b>!</b> i	PLASMA CLEANING METHOD FOR IMPROVED INK BRAND PERMANENCY ON IC PACKAGES WITH METALLIC PARTS
SE-1265-WR		Granted	08/781736	10-Jan-1997	5949695	· .	INTERPOLATOR USING A PLURALITY OF POLYNOMIAL EQUATIONS AND ASSOCIATED METHODS
SE-1266-WR		Granted	08/781334	10-Jan-1997	5764113		RE-SAMPLING CIRCUIT AND ASSOCIATED METHOD
SE-758	C	Granted	08/786569	21-Jan-1997	5892264		HIGH FREQUENCY ANALOG TRANSISTORS, METHOD OF FABRICATION AND CIRCUIT IMPLEMENTATION
SE-1010-TD	Ā	Granted	08/775360	03-Jan-1997	5776814	ļ	PROCESS FOR DOPING TWO LEVELS OF A DOUBLE POLY BIPOLAR TRANSISTOR AFTER FORMATION OF SECOND POLY LAYER
SE-1010-TD	B .	Granted	08/77536.1	03-Jan-1997	5686322	ļ.	PROCESS FOR DOPING TWO LEVELS OF A DOUBLE POLY BIPOLAR TRANSISTOR AFTER FORMATION OF SECOND POLY LAYER
SE-1245-TD		Granted	08/771944	23-Dec-1996	5914280		DEEP TRENCH ETCH ON BONDED SILICON WAFER
		1		<u> </u>			

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SE-1261-TD	511111	Granted	08/798039	06-Feb-199	7 5830048	03-Nov-199	8 PIVOT SAMPLE BLOCK CROSS-SECTION TOOL
							· ·
						1.	·
SE-1094-LN	Α	Granted	08/777101	30-Dec-199	6 5923207	13-Jul-199	9 COMPLEMENTARY MULTIPLEXER WITH LOW DISABLED-OUTPUT CAPACITANCE, AND METHOD
							DISABLED-OUTFUT CAPACITANCE, AND METHOD
05.040		Cuartad	00/702702	45 Jan 400	7.5700244	44 101 400	8 BONDED WAFER PROCESSING
SE-812	D	Granted	08/783792	15-Jan-199	/ 5/80311	14-Jul-199	BONDED WAFER PROCESSING
			Ţ'				i i
SE-1517-PD	1	Granted	09/344868	28-Jun-199	9 6242784	05-Jun-200	EDGE TERMINATION FOR SILICON POWER
		}				<u> </u>	DEVICES
SE-1468-TD		Pending	09/345261	30-Jun-1999	9		METHOD FOR MAKING A DIFFUSED BACK-SIDE LAYER ON A BONDED-WAFER WITH A THICK
		.[		:			BOND OXIDE
05 4407 77	ļ	D	09/342948	20 10-4000			BRUSHLESS MULTIPASS SILICON WAFER
SE-1467-TD		Pending	09/342948	. 29-Jun-1999	"		CLEANING PROCESS FOR POST CHEMICAL
		<u> </u>	i	·			MECHANICAL POLISHING USING IMMERSION
SE-1504-TD	<del> </del>	Pending	09/343845	30-Jun-1999		· · · · · · · · · · · · · · · · · · ·	METHOD OF MANUFACTURING A PLATED
				:	1		ELECTRONIC TERMINATION
					ļ		
SE-1497-TD	<u> </u>	Pending	09/339274	23-Jun-1999			INTEGRATED RESISTIVE CONTACT
	1						·
OF 4470 TD	ļ	Constad	00/250200	24 1:1 4000	0050454	40, 1,1,2004	USE OF BARRIER REFRACTIVE OR ANTI-
SE-1478-TD	ļ	Granted	09/358266	21-Jul-1999	6259151	10-301-2001	REFLECTIVE LAYER TO IMPROVED LASER TRIM
				•			CHARACTERISTICS OF THIN FILM RESISTORS
SE-1498-TL	1	Granted	09/365238	30-Jul-1999	6137189	24-Oct-2000	LINE CIRCUIT APPARATUS FOR SUPPLYING
		.					POWER TO A TELEPHONE SET IN TELECOMMUNICATION SYSTEMS
		-					TELEGOMMIONION OTOTENIO
SE-1053-TD	В	Pending	09/392806	09-Sep-1999			HIGH EFFICIENCY POWER MOS SWITCH
OF 4070 TD		0	00.7700702	42 Fab 4007	5070044	02 Nov. 4000	INTEGRATED CIRCUIT WITH THIN FILM
SE-1278-TD		Granted	08/799793	12-Feb-1997	5976944		RESISTORS AND A METHOD FOR CO-PATTERNING
•				ļ			THIN FILM RESISTORS WITH DIFFERENT COMPOSITORS
SE-1004-TD	Α	Granted	08/810127	25-Feb-1997	5895953	20-Apr-1999	METHOD FOR MAKING OHMIC CONTACT TO
,		].			,		LIGHTLY DOPED ISLAND FROM A SILICIDE BURIED LAYER AND APPLICATION
	,	1			j		LAYER AND APPLICATION
SE-1301-WR		Granted	08/819846	17-Mar-1997	5982807		HIGH DATA RATE SPREAD SPECTRUM
	·				.]		TRANSCEIVER AND ASSOCIATED METHODS
			<u> </u>				

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SE-982	A	Granted	08/845214	21-Apr-199	7 5962908	05-Oct-199	9 METHOD OF MAKING CONTACT REGIONS FOR NARROW TRENCHES IN SEMICONDUCTOR DEVICES
SE-1187-TD		Granted	08/855385	13-May-199	7 5945699	.31-Aug-199	REDUCED WIDTH, DIFFERENTIALLY DOPED VERTICAL JFET DEVICE
SE-1274-AP		Granted	08/858845	19-May-199	5900643	04-May-1999	INTEGRATED CIRCUIT CHIP STRUCTURE FOR IMPROVED PACKAGING
SE-765	С	Granted	08/868813	04-Jun-1997	5929502	27-Jul-1999	PUNCH THROUGH DIODES AND APPLICATIONS
SE-765	D	Granted	08/868815	04-Jun-1997	5929503	27-Jul-1999	PUNCH THROUGH DIODES AND APPLICATIONS
SE-1120-TL	A	Granted	08/873902	13-Jun-1997	5856742	05-Jan-1999	TEMPERATURE INSENSITIVE BANDGAP VOLTAGE GENERATOR TRACKING POWER SUPPLY VARIATIONS
SE-1159-IP		Granted	08/800420	14-Feb-1997	5821740		DC-TO-DC CONVERTER HAVING FAST OVER- CURRENT DETECTION AND ASSOCIATED METHODS
SE-1276-DA		Granted	08/885273	30-Jun-1997	5861826	19-Jan-1999	METHOD AND APPARATUS FOR CALIBRATING INTEGRATED CIRCUIT ANALOG-TO-DIGITAL CONVERTERS
SE-954-SP	A	Granted	08/884635	27-Jun-1997	6018270	25-Jan-2000	LOW VOLTAGE RF AMPLIFIER AND MIXER WITH SINGLE BIAS BLOCK AND METHOD
SE-1264-TD		Granted	08/885897	30-Jun-1997	5892223	06-Apr-1999	MULTILAYER MICROTIP PROBE AND METHOD
SE-1304-DA		Granted	08/885274	30-Jun-1997	5892472		PROCESSOR CONTROLLED ANALOG-TO-DIGITAL CONVERTER CIRCUIT
SE-905-TD	В	Granted	08/884787	30-Jun-1997	5994204	30-Nov-1999	SILICON GLASS-BONDED WAFERS
SE-1305-IP		Granted	08/883624	27-Jun-1997	5926384		DC-DC CONVERTER HAVING DYNAMIC REGULATOR WITH CURRENT SOURCING AND SINKING MEANS
SE-1285-TD		Granted	08/885707	30-Jun-1997	5956583		METHOD FOR FORMING COMPLIMENTARY WELLS AND SELF-ALIGNED TRENCH WITH A SINGLE MASK

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SE-1281-MS		Granted	08/748641	13-Nov-199	6 5744984	. 28-Apr-199	8 DRIVER CIRCUIT PROVIDING CONTROLLABLE BATTERY OVERLOAD PROTECTION
SE-1323-PD		Granted	08/885923	30-Jun-199	7 6157076	05-Dec-200	HERMETIC THIN PACK SEMICONDUCTOR DEVICE
SE-1161-IP		Granted	08/800421	14-Feb-199	7 5808883	15-Sep-199	DC-TO-DC CONVERTER HAVING CHARGE PUMP AND ASSOCIATED METHODS
SE-1364-DA		Granted	08/916569	22-Aug-199	5949362	07-Sep-1999	DIGITAL-TO-ANALOG CONVERTER INCLUDING CURRENT CELL MATRIX WITH ENHANCED LINEARITY AND ASSOCIATED METHODS
SE-812	E	Granted	08/843302	14-Apr-1997	5801084	01-Sep-1998	BONDED WAFER PROCESSING
SE-1259-AP		Granted	08/918345	26-Aug-1997	5892375	06-Apr-1999	COMPARATOR WITH SMALL SIGNAL SUPPRESSION CIRCUITRY
SE-1259-AP	A	Granted	08/918307	22-Aug-1997	6060913	09-May-2000	COMPARATOR WITH SMALL SIGNAL SUPPRESSION CIRCUITRY
SE-1322-WR		Granted	08/941704	01-Oct-1997	5883565	16-Mar-1999	FREQUENCY DEPENDENT RESISTIVE ELEMENT
SE-1076-TL	А	Granted	08/873899	13-Jun-1997	5896053	i i	SINGLE ENDED TO DIFFERENTIAL CONVERTER AND 50% DUTY CYCLE SIGNAL GENERATOR AND METHOD
SE-1332-TD		Granted	08/964672	05-Nov-1997	5978192		SCHMITT TRIGGER-CONFIGURED ESD PROTECTION CIRCUIT
SE-811	В	Granted	08/968618	12-Nov-1997	6051474		NEGATIVE BIASING OF ISOLATION TRENCH FILL TO ATTRACT MOBILE POSITIVE IONS AWAY FROM BIPOLAR DEVICE REGIONS
SE-1192-TL		Granted	08/972887	18-Nov-1997	5977829		LOW DISTORTION CURRENT FEEDBACK AMPLIFIER WITH DYNAMIC BIASING
SE-1286-TD		Granted	08/960337	29-Oct-1997	6034411	1	INVERTED THIN FILM RESISTOR AND METHOD FOR MANUFACTURE
SE-1353-DA		Granted	09/006071	12-Jan-1998	6006071		RF COMMUNICATIONS SYSTEM OPERABLE IN THE PRESENCE OF A REPETITIVE INTERFERENCE SOURCE AND RELATED METHODS

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SE-1268-MM	7. 7.78 a	Granted	09/019241	05-Feb-199	8 5990713	23-Nov-199	ADJUSTABLE PHASE CLOCK CIRCUIT USING THE
						•	SAME AND RELATED METHODS
SE-1251-AP	-	Granted	09/024203	17-Feb-199	8 5920224	06-Jul-199	NETWORK FOR IMPROVING ELETRO-MAGNETIC INTERFERENCE RESPONSE
			<u> </u>				
SE-1251-AP	A	Pending	09/024099	17-Feb-199	8		NETWORK FOR IMPROVING ELETRO-MAGNETIC INTERFERENCE RESPONSE
SE-1283-TL		Granted	09/027257	20-Feb-199	8 6167131	26-Dec-2000	RING GENERATOR
							·.
SE-826	A	Granted	08/956074	22-Oct-199	7 5851864	22-Dec-1998	BICMOS DEVICES
SE-1250-TD	A	Granted	09/061602	16-Apr-1998	3 6130172 	10-Oct-2000	RADIATION HARDENED DIELECTRIC FOR EEPROM
SE-800	В	Granted	09/378157	10-Mar-1998	8 6184565		BIASING OF ISLAND-SURROUNDING MATERIAL TO SUPPRESS REDUCTION OF BREAKDOWN VOLTAGE DUE TO FIELD PLATE ACTING ON BURIED LAYER/ISLAND JUNCTION BETWEEN HIGH
SE-1367-AP		Granted	09/055528	06-Apr-1998	6069502		SAMPLE-AND-HOLD CIRCUIT HAVING REDUCED SUBTHRESHOLD CONDUCTION EFFECTS AND RELATED METHODS
SE-1368-AP		Granted	09/055562	06-Apr-1998	6016067		SAMPLE AND HOLD CIRCUIT HAVING REDUCED AMPLIFIER OFFSET EFFECTS AND RELATED METHODS
SE-1422-AP		Granted	09/055561	06-Apr-1998	6002277		SAMPLE-AND-HOLD CIRCUIT HAVING REDUCED PARASITIC DIODE EFFECTS AND RELATED METHODS
SE-1373-TD	•	Granted	09/064029	21-Apr-1998	5932022		SC-2 BASED PRE-THERMAL TREATMENT WAFER CLEANING PROCESS
SE-1327-PD		Granted	09/107475	30-Jun-1998	6159663		METHOD OF CREATING A SOLDERABLE METAL LAYER ON GLASS OR CERAMIC
SE-1036-TD	Ā	Granted	09/073776	05-May-1998	5915168		LID WAFER BOND PACKAGING AND MICROMACHINING
SE-1073-AP	<b>A</b>	Granted	08/854681	12-May-1997	6108352		CIRCUIT AND METHOD FOR SYNCHRONIZING OUTPUTS OF TWO SIMULTANEOUSLY TRANSMITTING DEVICES IN A MULTIPLEXED COMMUNICATION SYSTEM

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SE-1361-TL	1	Granted	09/079304	15-May-19	98 6233335	15-May-200	DI BATTERY SWITCHING SUBSCRIBER LOOP INTERFACE CIRCUIT
	ļ				Ì		INTERFACE CIRCOTT
		<u> </u>					<u> </u>
SE-1346-TD		Granted	09/082892	21-May-199	98 5929508	27-Jul-199	9 DEFECT GETTERING BY INDUCED STRESS
·						1	
SE-1380-TD		Granted	09/106622	29-Jun-199	8 6054012	25-Apr-200	0 DECAPSULATING METHOD AND APPARATUS FOR
				1	Ţ		INTEGRATED CIRCUIT PACKAGES
	<u> </u>				}		
SE-1441-IP		Granted	09/108059	30-Jun-199	8 6005303	21-Dec-199	9 LINEAR VOLTAGE REGULATOR COMPATIBLE
ļ	1			<u> </u>			WITH BIPOLAR AND MOSFET PASS DEVICES AND ASSOCIATED METHODS
	}			İ		· ·	
SE-1197-PD		Granted	09/109268	02-Jul-199	8 6057612	02-May-200	FLAT POWER PACK
	1			•		ļ	
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SE-1277-TD		Granted	09/108963	02-Jul-199	8 6064340	16-May-200	ESD LOCATING APPARATUS AND METHOD
	1	· [ .			ł	<u> </u>	•
SE-1032-TD	А	Granted	09/110721	07-Jul-1998	6114768	05-Sep-2000	SURFACE MOUNT DIE BY HANDLE REPLACEMENT
					ļ		·
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SE-1053-TD	Α	Granted	08/973769	27-Jul-1998	5973368	26-Oct-1999	HIGH EFFICIENCY POWER MOS SWITCH
·						ļ	
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SE-1429-TD	Α	Granted	09/139932	26-Aug-1998	6278186	21-Aug-2001	PARASITIC CURRENT BARRIERS
J	1	Ì	1				
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SE-1406-DA	l	Granted	09/148955	08-Sep-1998	6107950	22-Aug-2000	ANALOG-TO-DIGITAL CONVERTER HAVING
							ENHANCED ACCURACY GAIN STAGE, AND
							ASSOCIATED DEVICES AND METHODS
SE-1439-DA		Granted	09/149154	08-Sep-1998	6118398	12-Sep-2000	DIGITAL-TO-ANALOG CONVERTER HAVING
			"				ENHANCED ACCURACY AND ASSOCIATED
							METHODS
SE-1442-TD	<del></del>	Granted	09/150429	09-Sep-1998	6140652	31-Oct-2000	DEVICE CONTAINING SAMPLE PREPARATION
			1				SITES FOR TRANSMISSION ELECTRON
							MICROSCOPIC ANALYSIS AND PROCESSES OF FORMATION AND USE
SE-1349-TL		Pending	09/145182	01-Sep-1998			PROGRAMMABLE SUBSCRIBER LOOP INTERFACE
				·		-	CIRCUIT AND METHOD
						ĺ	
SE-1453-WR		Pending	09/163802	30-Sep-1998			PULSED BEACON-BASED INTERFERENCE
				,			REDUCTION MECHANISM FOR WIRELESS
		·			j		COMMUNICATION NETWORKS
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SE-1374-IP		Granted	09/220780	24-Dec-1998	5982160	09-Nov-199	9 DC-TO-DC CONVERTER WITH INDUCTOR CURRENT SENSING AND RELATED METHODS
SE-1024-TD	A	Granted	09/199292	24-Nov-1998	6211056	03-Apr-200	1 INTEGRATED CIRCUIT AIR BRIDGE STRUCTURES AND METHOD OF FABRICATING SAME
SE-1472-TD		Granted	09/255231	22-Feb-1999	6255195	03-Jul-200	BONDED SUBSTRATE FOR AN INTEGRATED CIRCUIT CONTAINING A PLANAR INTRINSIC GETTERING ZONE (as amended)
SE-1063-TD	A	Granted	09/204904	03-Dec-1998	6114191	05-Sep-2000	SEMICONDUCTOR PACKAGING APPARATUS
SE-1400-MM		Pending	09/245674	08-Feb-1999			METHOD OF DIGITALLY DECODING A COMPOSITE VIDEO SIGNAL AND A DIGITAL DECODER FOR COMPOSITE VIDEO SIGNALS
SE-1407-WR		Pending	09/231608	14-Jaṇ-1999	-	·	METHOD OF PERFORMING ANTENNA DIVERSITY IN SPREAD SPECTRUM IN WIRELESS LOCAL AREA NETWORK
SE-1492-WR		Pending	09/231184	14-Jan-1999	V-1-0	1	WIRELESS LOCAL AREA NETWORK SPREAD SPECTRUM TRANSCEIVER WITH MULTIPATH MITIGATION
SE-1500-WR		Pending	09/231228	14-Jan-1999		1	SPREAD SPECTRUM TRANSCEIVER FOR USE IN WIRELESS LOCAL AREA NETWORK AND HAVING MULTIPATH MITIGATION
SE-1350-TL		Pending	09/208457	10-Dec-1998			APPARATUS AND METHOD FOR TESTING SUBSCRIBER LOOP INTERFACE CIRCUITS
SE-1322-WR	A	Granted	09/246815	09-Feb-1999 5	999080	07-Dec-1999	FREQUENCY DEPENDENT RESISTIVE ELEMENT
SE-1094-LN	В	Granted	09/247510	10-Feb-1999 6	114896		COMPLEMENTARY MULTIPLEXER WITH LOW DISABLED-OUTPUT CAPACITANCE, AND METHOD
SE-1488-WR		Granted	09/261981	04-Mar-1999 6	172556		FEEDBACK-CONTROLLED LOW VOLTAGE CURRENT SINK/SOURCE
6E-1482-WR		Pending	09/266386	10-Mar-1999		ļ	SUCCESSIVE APPROXIMATION CORRECTION OF DC OFFSET IN FILTER-BUFFER BASEBAND PATH OF DATA RADIO
SE-1106-TD	A	Granted	09/268605	15-Mar-1999 60	051457	•	ELECTROSTATIC DISCHARGE PROTECTION DEVICE

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SE-1245-TD	A	Granted	09/266066	10-Mar-199	9 6198150	06-Mar-200	1 DEEP TRENCH ETCH ON BONDED SILICON WAFER
SE-1373-TD	A	Pending	09/335113	17-Jun-1999	9		SC-2 BASED PRE-THERMAL TREATMENT WAFER CLEANING PROCESS
SE-1176-MS	A	Granted	09/334998	17-Jun-1999	6233293	15-May-200	CURRENT-CONTROLLED CARRIER TRACKING FILTER FOR IMPROVED SPURIOUS SIGNAL SUPPRESSION
SE-1278-TD	A	Pending	09/335134	17-Jun-1999			INTEGRATED CIRCUIT WITH THIN FILM RESISTORS AND A METHOD FOR CO-PATTERNING THIN FILM RESISTORS WITH DIFFERENT COMPOSITONS
SE-1346-TD	A	Granted	09/334987	17-Jun-1999	6274460	14-Aug-2001	DEFECT GETTERING BY INDUCED STRESS
SE-1479-WR		Granted	09/342583	29-Jun-1999	6233273	15-May-2001	RAKE RECEIVER WITH EMBEDDED DECISION FEEDBACK EQUALIZER
SE-1535-TD		Pending	09/345929	01-Jul-1999	- i - · · · ·		LOW TEMPERATURE COEFFICIENT RESISTOR (TCRL)
SE-1371-TD		Pending	09/367325	11-Aug-1999		·	CO-PATTERNING THIN-FILM RESISTORS OF DIFFERENT COMPOSITIONS WITH A CONDUCTIVE HARD MASK AND METHOD FOR SAME
SE-1454-WR		Pending	09/378532	20-Aug-1999			PROGRAMMABLE FILTERING MECHANISM TO ALLOW BANDWIDTH OVERLAP BETWEEN DIRECT SEQUENCE SPREAD SPECTRUM COMMUNICATION DEVICE AND FREQUENCY-
SE-1348-TL		Pending	09/378962	23-Aug-1999	-		LOOP IMPEDANCE MEASURING APPARATUS AND METHOD FOR SUBSCRIBER LOOP INTERFACE CIRCUITS
SE-822-SP	G	Granted	09/394802	10-Sep-1999 (	6329260		ANALOG-TO-DIGITAL CONVERTER AND METHOD OF FABRICATION
SE-1417-WR		Pending	09/426847	26-Oct-1999			TRANSCEIVER INCLUDING REACTIVE TERMINATION TO IMPROVE CROSS-MODULATION PERFORMANCE AND RELATED METHODS
SE-1380-TD	A	Pending <sub>.</sub>	09/430391	29-Oct-1999			DECAPSULATING METHOD AND APPARATUS FOR INTEGRATED CIRCUIT PACKAGES
SE-1286-TD	A	Granted	09/429933	29-Oct-1997 6	5121105		NVERTED THIN FILM RESISTOR AND METHOD FOR MANUFACTURE

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SE-1541-SP	<b>200</b>	Pending	09/442291	19-Nov-1999			BACKWARDS DRIVABLE MOS OUTPUT DRIVER
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			20/40 4000	28-Jan-2000			PIACED CORRECTED DAVE DECEMENTO
SE-1481-WR		Pending	09/494000	28-Jan-2000			BIASED-CORRECTED RAKE RECEIVER FOR DIRECT SEQUENCE SPREAD SPECTRUM WAVEFORM
SE-1562-TD		Pending	09/506711	18-Feb-2000			BREAKDOWN IMPROVEMENT METHOD AND STRUCTURE FOR LATERAL EXTENSION MOS DEVICE
SE-1393-IP	A	Granted	08/974862	20-Nov-1997	6058030	02-May-2000	MULTIPLE OUTPUT DC-TO-DC CONVERTER HAVING ENHANCED NOISE MARGIN AND RELATED METHODS
SE-1375-PD	A	Granted	09/030871	19-May-2000	6275093	14-Aug-2001	IGBT GATE DRIVE CIRCUIT WITH SHORT CIRCUIT PROTECTION
SE-1541-SP	A	Pending	09/569894	12-May-2000	<del></del>	· · · · · · · · · · · · · · · · · · ·	BACKWARDS DRIVABLE MOS OUTPUT DRIVER
13E-1341-3F		rending	03/303034	12-Way-2000			BACKWARDS BRIVABLE MOS OUT OT BRIVER
SE-1539-IP		Granted	09/591404	12-Jun-2000	6278263	21-Aug-2001	MULTI-PHASE CONVERTER WITH BALANCED CURRENTS
SE-1536-IP		Granted	09/591360	09-Jun-2000	6181120		CURRENT MODE DC/DC CONVERTER WITH CONTROLLED OUTPUT IMPEDANCE
SE-1489-WR		Pending	09/571822	16-May-2000			AN ULTRA LINEAR HIGH FREQUENCY TRANSCONDUCTOR STRUCTURE
SE-1616-WR		Pending	09/586571	02-Jun-2000			A DUAL PACKET CONFIGURATION FOR WIRELESS COMMUNICATIONS
SE-1388-DA		Pending	09/524992	14-Mar-2000	Ī		SUBSAMPLING DIGITIZER-BASED FREQUENCY SYNTHESIZER
·							
SE-1535-TD	A	Pending	09/607080	29-Jun-2000			LOW TEMPERATURE COEFFICIENT RESISTOR (TCRL)
SE-1323-PD	A	Pending	09/621449	21-Jul-2000			HERMETIC THIN PACK SEMICONDUCTOR DEVICE
SE-1519-WR	•	Pending	09/572417	17-May-2000		1	APPARATUS FOR RADIO FREQUENCY PROCESSING WITH SINGLE OSCILLATOR FOR INTERMEDIATE FREQUENCY PROCESSING

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SE-1520-WR		Pending	09/573782	17-May-2000		, a	APPARATUS FOR RADIO FREQUENCY PROCESSING WITH DUAL MODULUS SYNTHESIZER
SE-1537-IP		Granted	09/633316	07-Aug-2000	6246220	12-Jun-200	SYNCHRONOUS-RECTIFIED DC. TO DC CONVERTER WITH IMPROVED CURRENT SENSING AND ASSOCIATED METHODS
SE-1510-WR	·	Pending	09/612848	10-Jul-2000			NEGATIVE FEEDBACK GAIN CONTROL FOR COMMON ELECTRODE TRANSISTOR
SE-1597-IP		Pending	09/639407	14-Aug-2000			OSCILLATOR HAVING REDUCED SENSITIVITY TO SUPPLY VOLTAGE CHANGES
SE-1480-WR.		Pending	09/612823	10-Jul-2000			RAPID ESTIMATION OF WIRELESS CHANNEL IMPULSE RESPONSE
SE-1573-TL		Pending	09/639408	14-Aug-2000			TRANSCONDUCTANCE AMPLIFIER CIRCUIT
SE-1598-IP		Granted	09/645070	23-Aug-2000	6249446		CASCADABLE, HIGH EFFICIENCY CHARGE PUMP CIRCUIT AND RELATED METHODS
SE-1563-TL		Pending	09/686505	11-Oct-2001	· ·		PRECISION, LOW-POWER CURRENT-SENSE TRANSMISSION CHANNEL FOR SUBSCRIBER LINE INTERFACE CIRCUIT, PROGRAMMABLE WITH SINGLE ENDED IMPEDANCES AND CAPABLE OF
SE-1584-TL		Pending	09/686926	11-Oct-2000			BIASING ARRANGEMENT FOR OPTIMIZING DC FEED CHARACTERISITICS FOR SUBSCRIBER LINE INTERFACE CIRCUIT
SE-1564-TL		Pending	09/686504	11-Oct-2000			MECHANISM FOR PREVENTING CLIPPING OF PULSE METERING SIGNALS IN TELEPHONE LINE CARD CHANNELS
SE-1579-TL		Pending	09/686247	11-Oct-2000		-  -	CONTROLLED SWITCHING MECHANISM FOR ACCOMPLISHING SOFT POLARITY REVERSAL, RING-TRIP FILTERING, AND LINE VOLTAGE MEASUREMENTS IN A SUBSCRIBER LINE
SE-1572-TL		Pending :	09/686514	11-Oct-2000		ı	MECHANISM FOR MINIMIZING UNDESIRABLE EFFECTS OF PARASITIC COMPONENTS IN INTEGRATED CIRCUITS
SE-1568-TL		Pending	09/686515	11-Oct-2000		ļ	MECHANISM FOR GENERATING PRECISION USER- PROGRAMMABLE PARAMETERS IN ANALOG NTEGRATED CIRCUIT
SE-1567-TL		Pending	09/686517	11-Oct-2000		T	MECHANISM FOR MEASURING RESISTANCE OF TELEPHONE SUBSCRIBER LINE AND GENERATING MEASUREMENT AS PULSE WIDTH OF PERIODIC NAVEFORM

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SE-1581-TL		Pending	09/686634	11-Oct-2000			TRANSISTOR BASE CURRENT ERROR CORRECTION SCHEME FOR LOW OVERHEAD VOLTAGE APPLICATIONS
SE-1577-TL		Pending	09/686633	11-Oct-2000			CURRENT MIRROR-EMBEDDED LOW-PASS FILTER FOR SUBSCRIBER LINE INTERFACE CIRCUIT APPLICATIONS
SE-1569-TL	-	Granted	09/686506	11-Oct-2000	6292033	18-Sep-2001	PRECISION, LOW-POWER TRANSIMPEDANCE CIRCUIT WITH DIFFERENTIAL CURRENT SENSE INPUTS AND SINGLE ENDED VOLTAGE OUTPUT
SE-1666-WR		Pending	09/252308	11-Feb-1999			DATA COMMUNICATON NETWORK
SE-1667-WR		Pending	09/527407	17-Mar-2000			INTERFACE CARD
SE-1668-WR		Pending	09/526607	16-Mar-2000			PROTECTED DATA TRAFFIC
SE-1621-WR		Pending	09/678901	02-Oct-2000			DC COMPENSATION SYSTEM FOR A WIRELESS COMMUNICATION DEVICE CONFIGURED IN A ZERO INTERMEDIATE FREQUENCY ARCHITECTURE
SE713	A	Pending	09/570009	12-May-2000			VARIABLE WAVELENGTH OPTICAL ALIGN SYSTEM
SE-1588-WR		Pending	09/717459	20-Nov-2000			DUAL-EDGE FUNCTION CLOCK GENERATOR AND METHOD OF DERIVING CLOCKING SIGNALS FOR EXECUTION REDUCED INSTRUCTION SEQUENCES IN A RE-PROGRAMMABLE I/O INTERFACE
SE-1589-WR		Pending	09/717495	20-Nov-2000			SEQUENCER AND METHOD OF SELECTIVELY INHIBITING CLOCK SIGNALS TO EXECUTE REDUCED INSTRUCTION SEQUENCES IN A RE- PROGRAMMING I/0 INTERFACE
SE-1641-WR		Pending	09/747138	21-Dec-2000		ŀ	SYSTEM AND METHOD FOR DETECTING AND CORRECTING PHASE ERROR BETWEEN DIFFERENTIAL SIGNALS
SE-1630-WR		Pending	09/747321	21-Dec-2000			BIAS CIRCUIT FOR A LOW VOLTAGE DIFFERENTIAL CIRCUIT
SE-1631-WR		Pending	09/747163	21-Dec-2000			QUADRATURE OSCILLATOR WITH PHASE ERROR CORRECTION
SE-1576-TL	F	Pending	09/686324	11-Oct-2000		\$	PRECISION LOOP VOLTAGE DETECTOR FOR SUBSCRIBER LINE INTERFACE CIRCUIT APPLICATIONS

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SE-1622-WR		Pending	09/677975	02-Oct-2000	A CALIBRATED DC COMPENSATION SYSTEM FOR A WIRELESS COMMUNICATION DEVICE CONFIGURED IN A ZERO INTERMEDIATE FREQUENCY ARCHITECTURE
SE-1629-WR		Pending	60/259295	02-Jan-2001	PRECISION PROGRAMMABLE WIDEBAND AUTOMATIC GAIN CONTROL AMPLIFIER
SE-1560-MS		Pending	09/741221	19-Dec-2000	OVERVOLTAGE PROTECTION CIRCUIT FOR BIDIRECTIONAL TRANSMISSION GATE
SE-1632-WR		Pending	09/746736	21-Dec-2000	A SWITCHED ELECTROSTATIC DISCHARGE RING FOR INTEGRATED CIRCUITS WITH MULTIPLE POWER INPUTS
SE-1558-IP		Pending	09/791509	22-Feb-2001	METHODS TO CONTROL THE DROOP WHEN POWERING DUAL MODE PROCESSORS AND ASSOCIATED CIRCUITS
SE-1596-WR		Pending	60/274261	08-Mar-2001	INTEROPERABLE FORWARD ERROR CORRECTION IN A NETWORK WITH HETEROGENEOUS STATION CAPABILITIES
SE-1731-TD		Pending	60/282011	06-Apr-2001	DESIGN OF AN ON-WAFER TEST STRUCTURE TO DETECT PROCESS-INDUCED HIGH FREQUENCY PARAMETRIC VARIATIONS THROUGH DC MEASUREMENTS
SE-1517-PD	В	Pending	09/815672	23-Mar-2001	EDGE TERMINATION FOR SILICON POWER DEVICES
SE-1479-WR	A	Pending	09/823845	30-Mar-2001	RAKE RECEIVER WITH EMBEDDED DECISION FEEDBACK EQUALIZER
SE-1472-TD	A	Pending	09/846795	01-May-2001	BONDED SUBSTRATE FOR AN INTEGRATED CIRCUIT CONTAINING A PLANAR INTRINSIC GETTERING ZONE (as amended)
SE-1602-IP		Pending	09/846721	01-May-2001	DC TO DC CONVERTER METHOD AND CIRCUITRY
SE-1176-MS	В	Pending	09/855332	15-May-2001	CURRENT-CONTROLLED CARRIER TRACKING FILTER FOR IMPROVED SPURIOUS SIGNAL SUPPRESSION
SE-1696-WR	Р	Pending	60/272187	28-Feb-2001	AN AUTOMATIC GAIN CONTROL CIRCUIT WITH HIGH LINEARITY AND MONOTONICALLY CORRELATED OFFSET VOLTAGE
SE-1620-WR		Pending	09/849002	04-May-2001	A SYSTEM AND METHOD OF REPETITIVE TRANSMISSION OF FRAMES FOR FRAME-BASED COMMUNICATIONS

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SE-1618-WF		Pending	09/849053	04-May-2001	A STATUTE	SYSTEM AND METHOD FOR SYNCHRONIZING
	`	, chaing		0 \ay 200		DATA TRANSMISSION ACROSS AN INTERFACE WITH VARIABLE TIMING
			İ			WITH VARIABLE TIMING
SE-1619-WR		Pending	09/849101	04-May-2001		A SYSTEM AND METHOD FOR PROVIDING A
• .						SELECTABLE RETRY STRATEGY FOR FRAME- BASED COMMUNICATIONS
					·	DAGES COMMONIONICS
SE-1614-WR	0	Pending	09/864676	24-May-2001		A COMMUNICATION SYSTEM USING
	1.					ORTHOGONAL WAVELET DIVISION MULTIPLEXING (OWDM) AND OWDM-SPREAD SPECTRUM (OWSS)
						SIGNALING
SE-1385-TD	Α .	Pending	09/062964	23-May-2001		DEVICE WITH AND METHODS FOR PATTERNED
			<u> </u>	ĺ.		WELLS
	ļ		ĺ			
SE-1468-TD	A	Pending	09/961613	24-Sep-2001		METHOD FOR MAKING A DIFFUSED BACK-SIDE
		Í		1		LAYER ON A BONDED-WAFER WITH A THICK BOND OXIDE
					·	
SE-1661-MS	0	Pending	09/973106	09-Oct-2001	· ·	REDUNDANT COMPARATOR DESIGN FOR
				i . i	}	IMPROVED OFFSET VOLTAGE AND SINGLE EVENT EFFECTS HARDNESS
	1	-	1	1		ELI LEGIO MARANESS
SE-822-SP	Н	Pending	09/973390	09-Oct-2001		ANALOG-TO-DIGITAL CONVERTER AND METHOD
	1				Ĭ	OF FABRICATION
SE-1660-TD		Pending		12-Oct-2001		INTEGRATED CIRCUIT WITH A MOS STRUCTURE
		1			.	HAVING REDUCED PARASITIC BIPOLAR TRANSISTOR ACTION
		Í		1		TRANSISTOR ACTION
SE-1555-MS	0	Pending	1	30-Oct-2001		REDUNDANT LATCH CIRCUIT AND ASSOCIATED
		İ				METHODS
	1		1			
SE-1301-WR	а	Pending	982807	09-Nov-2001		HIGH DATA RATE SPREAD SPECTRUM
			1			TRANSCEIVER AND ASSOCIATED METHODS
	·					
SE-1540-TD		Pending		21-Nov-2001		SELF-ALIGNMENT OF SEPARATED REGIONS IN A
				•		LATERAL MOSFET STRUCTURE OF AN INTEGRATED CIRCUIT
						INTEGRALES SINGSIV
SE-1712-MS	0	Pending	09/996448	28-Nov-2001		SPATIALLY REDUNDANT AND COMPLEMENTARY
					ļ	SEMICONDUCTOR DEVICE-BASED, SINGLE EVENT TRANSIENT-RESISTANT LINEAR AMPLIFIER
			i .		1	CIRCUIT ARCHITECTURE
SE-1211-TD	С	Pending		16-Nov-2001		WAFER TRENCH ARTICLE AND PROCESS
				1	İ	
			1		-	
SE-1669-WR	0	Pending	10/005096	03-Dec-2001		COMMON MODE OUTPUT CURRENT CONTROL
						CIRCUIT AND METHOD
L			<del></del>			

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SE-1642-WR	O	Pending	C	03-Dec-2001	٠	ATTENUATOR CONTROL CIRCUIT
SE-1735-WR		Pending	09/943803	31-Aug-2001		SYSTEM AND METHOD FOR ORDERING DATA MESSAGES HAVING DIFFERING LEVELS OF PRIORITY FOR TRANSMISSION OVER A SHARED COMMUNICATION CHANNEL
SE-1463-TD	A	Pending	09/949736	10-Sep-2001		LASER DECAPSULATION APPARATUS AND METHOD
SE-1730-IP	O	Pending	09/950469	10-Sep-2001		METHOD TO SET OUTPUT VOLTAGE OF INTEGRATED PWM CONTROLLER AND A CIRCUIT FOR THEREOF
SE-1633-WR		Pending	09/952184	14-Sep-2001		LINEARIZATION BIAS CIRCUIT FOR BJT AMPLIFIERS
SE-1647-TD		Pending	09/877272	08-Jun-2001		LATERAL DMOS STRUCTURE WITH LATERAL EXTENSION STRUCTURE FOR REDUCED CHARGE TRAPPING IN GATE OXIDE
SE-1451-TD		Pending	09/880726	13-Jun-2001	, , , , , , , , , , , , , , , , , , ,	REFERENCE CURRENT/VOLTAGE GENERATOR HAVING REDUCED SENSITIVITY TO VARIATIONS IN POWER SUPPLY VOLTAGE
SE-1734-BW		Pending	09/884000	19-Jun-2001		REMOTE POWER AMPLIFIER LINEARIZATION
SE-1663-DA	0	Pending	09/900588	06-Jul-2001		AN OPERATIONAL AMPLIFIER INCLUDING A RIGHT- HALF PLANE ZERO REDUCTION CIRCUIT AND RELATED METHOD
SE-1741-WR		Pending	60/303444	06-Jul-2001		MIXED WAVEFORM CONFIGURATION FOR WIRELESS COMMUNICATIONS
SE-1574-TL		Pending	09/901259	09-Jul-2001		MULTISTAGE PRECISION, LOW INPUT/OUTPUT OVERHEAD, LOW POWER, HIGH OUTPUT IMPEDANCE AND LOW CROSSTALK CURRENT MIRROR
SE-1575-TL	·	Pending	09/901439	09-Jul-2001		MECHANISM FOR MINIMIZING CURRENT MIRROR TRANSISTOR BASE CURRENT ERROR FOR LOW OVERHEAD VOLTAGE APPLICATIONS
SE-1570-TL		Pending	09/901265	09-Jul-2001		PRECISION LOW POWER OPERATIONAL AMPLIFIER WITH GAIN INVARIANT BANDWIDTH
SE-1585-TL		Pending	09/901260	09-Jul-2001		TRANSCONDUCTANCE AMPLIFIER BASED PRECISION HALF WAVE AND FULL WAVE RECTIFIER CIRCUIT

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SE-1582-TL		Pending	09/901327	09-Jul-2001		p	REDUCED PROPAGATION DELAY CURRENT MODE CASCADED ANALOG-TO-DIGITAL CONVERTER AND THRESHOLD BIT CELL THEREFOR
SE-1565-TL		Pending	09/901326	09-Jul-2001			TEMPERATURE-INSENSITIVE OUTPUT CURRENT LIMITER NETWORK FOR ANALOG INTEGRATED CIRCUIT
SE-1689-TD		Pending	09/899332	03-Jul-2001	;	·	MOSINTEGRATED CIRCUIT WITH REDUCED ON RESISTANCE
SE-1698-TL	0	Pending	09/909183	19-Jul-2001			SUBSCRIBER LINE INTERFACE CIRCUIT (SLIC) INCLUDING A TRANSIENT OUTPUT CURRENT LIMIT CIRCUIT AND RELATED METHOD
SE-1578-TL		Pending	09/901506	09-Jul-2001			CAPACITOR MULTIPLIER
SE-1664-WR	0	Pending	09/911060	23-Jul-2001			MIXER DRIVER CIRCUIT
SE-1554-MS	0	Pending	09/915119	25-Jul-2001			POWER DEVICE DRIVING CIRCUIT AND ASSOCIATED METHODS
SE-1623-WR	0	Pending	09/918409	30-Jul-2001			PACKET ACQUISITION AND CHANNEL TRACKING FOR A WIRELESS COMMUNICATION DEVICE CONFIGURED IN A ZERO INTERMEDIATE FREQUENCY ARCHITECTURE
SE-1553-MS	0	Pending	09/918208	30-Jul-2001			COMPLEMENTARY METAL OXIDE SEMICONDUCTOR WITH IMPROVED SINGLE EVENT PERFORMANCE
SE-1211-TD	В	Pending	283530	26-Jul-2001			WAFER TRENCH ARTICLE AND PROCESS
		· · · · · · · · · · · · · · · · · · ·					
SE-1652-IP	0	Pending	09/928857	13-Aug-2001			INTEGRATED CIRCUIT WITH CURRENT-LIMITED POWER OUTPUT AND ASSOCIATED METHOD
SE-1653-IP	0	Pending	09/928821	13-Aug-2001			INTEGRATED CIRCUIT WITH CURRENT SENSE CIRCUIT
SE-1738-SP	0	Pending	60/293445	21-Aug-2001	_		APPARATUS AND METHOD FOR MINIMIZING SPURIOUS HARMONIC NOISE IN SWITCHED CURRENT STEERING ARCHITECTURES
SE-1569-TL	а	Pending	09/939191	24-Aug-2001			PRECISION, LOW-POWER TRANSIMPEDANCE CIRCUIT WITH DIFFERENTIAL CURRENT SENSE INPUTS AND SINGLE ENDED VOLTAGE OUTPUT

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SE-1659-WR	0	Pending	09/943668	31-Aug-200	1 .		A VARIABLE TRANSCONDUCTANCE AMPLIFIER
		1		1	}		
SE-1673-WR	0	Pending	09/944000	31-Aug-200	1		SINGLE-ENDED TO DIFFERENTIAL AND DIFFERENTIAL TO SINGLE-ENDED CONVERSION
·		4			ļ		USING A COMMON MODE SHUNT
	<u></u>	<u> </u>			<u> </u>		
28-IS-0064		Granted	07/740700	.06-Aug-1991	5184128	02-Feb-1993	INTEGRATING A/D CONVERTER WITH MEANS FOR REDUCING ROLLOVER ERROR
	ŀ				ļ		NEBOOMO NOLEOVEN ENTIRE
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XRCA78203		Granted	817489	09-Jan-1986	4882749	21-Nov-1989	CONTROL OF SIGNAL TRANSMISSION
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XRCA78673		Granted	220712	18-Jul-1988	4924113		TRANSISTOR BASE CURRENT COMPENSATION CIRCUITRY
		· ·			ļ .	Ì	OINCOTTAT
XRCA79485		Granted	605241	30-Apr-1984	4594517	10-Jun-1986	POWER DOWN SENSOR
		1					
XRCA83734		Granted	915985	03-Oct-1986	4785339		INTEGRATED LATERAL PNP TRANSISTOR AND CURRENT LIMI
					_		CORREINT LIMI
RD 15280		Granted	530328	08-Sep-1983	4472628		FIBER OPTICS TRANSDUCER FOR SENSING PARAMETER MAGNITUDE
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XRCA79243		Granted	695297	28-Jan-1985	4730131	08-Mar-1988	INPUT SIGNAL CONDITIONING CIRCUIT
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#### SCHEDULE A PATENT DISCLOSURES

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SE-1625-WR	Authorized	ZIF ARCHITECTURE WITH MULTIPLEXED AUTOMATIC GAIN CONTROL AMPLIFIER					
SE-1766-WR	Authorized	THRESHOLD DETECTION OF CORRELATOR OUTPUT FOR OFDM ACQUISITION					
SE-1769-IP	Authorized	METHOD OF SETTING AND DETECTING FAST LOOP TRIP POINTS					
SE-1514-TD	Authorized	CAPACITIVE COUPLED LEVEL SHIFTER AND METHOD					
SE-1545-TD	Authorized	ESD PROTECTION NETWORKS UTILIZING PRECHARGED BUS LINES					
SE-1591-WR	Authorized	PROGRAMMABLE INTERFACE APPARATUS HAVING INSTRUCTION WITH CONDITIONAL EXECUTION DURATION					
SE-1592-WR	Authorized	PROGRAMMABLE INTERFACE APPARATUS HAVING LOOP CONTROL INSTRUCTION WITH DATA-DEPENDENT OVERRIDE					
SE-1593-WR	Authorized	PROGRAMMABLE INTERFACE APPARATUS HAVING A PROGRAM COUNTER THAT OPERATES AS A BIT COUNTER					
SE-1759-BW Authorized		CONNECTIONLESS COMMUNICATION NETWORK AND WIRELESS CHANNEL ALLOCATION METHOD THEREFOR					
SE-1626-WR	Authorized	ANTENNA DIVERSITY					
SE-1627-WR	Authorized	FORWARD ERROR CORRECTION SCHEME					
SE-1628-WR	Authorized	APRIORI FREQUENCY OFFSET					
SE-1636-WR	Authorized	VOLTAGE CONTROLLED OSCILLATOR (VCO)					
SE-1733-TD	Authorized	ENHANCED EPROM STRUCTURES AND METHOD OF FABRICATION					
SE-1726-SP	Authorized	AN ANALOG TO DIGITAL CONVERTER WITH INTERPOLATING AND SUBRANGING ARCHITECTURE					
SE-1727-SP Authorized		DIFFERENTIAL CALIBRATION OF RESISTIVE LADDER USING PARALLEL RESISTIVE CORRECTION					
SE-1728-SP Authorized DIFFERENTIAL CALIB		DIFFERENTIAL CALIBRATION OF PREAMPLIFIER OFFSETS					
SE-1729-SP	Authorized	HIGH SPEED TRACK AND HOLD CIRCUIT WITH DUAL PUMP CIRCUIT					

#### SCHEDULE A PATENT DISCLOSURES

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SE-1732-TD	Authorized	PATTERNED GROUND SHIELDS AND OTHER LAYOUT INNOVATIONS FOR SYMMETRIC ON-CHIP TRANSFORMERS
SE-1748-WR	Authorized	A RAPID ACQUISITION AND TRACKING SYSTEM FOR A WIRELESS PACKET BASED COMMUNICATION DEVICE
SE-1640-WR	Authorized	AUTOMATIC PER CHANNEL POWER SETTING AND PROGRAMMING BASED ON SIDELOBE LEVEL
SE-1746-WR	Authorized	MAGNETIC THIN FILM INDUCTORS
SE-1747-TL	Authorized	IMPROVED EFFICIENCY EL-DRIVER
SE-1772-IP	Open	SYNTHETIC RIPPLE REGULATOR
SE-1770-BW	Open	POWER AMPLIFIER MEMORY-EFFECT COMPENSATION WITH INTERPOLATED PRESDISTORTION
SE-1773-IP	Open	AUTOMATIC DEADTIME ADJUSTMENT FOR DC TO DC POWER DRIVER
SE-1764-TL	Open	A LINE VOLTAGE REGULATOR CIRCUIT FOR SUBSCRIBER LINE APPLICATIONS
	Open	
SE-1763-TL	Open	A HIGH VOLTAGE INTERFACE CIRCUIT FOR SUBSCRIBER LINE APPLICATIONS
SE-1750-TD	Open	REDUCED MASK COUNT DUAL BURIED LAYER PROCESS
SE-1774-IP	Open	AUTO-ZEROED VIRTUAL GROUND CURRENT SENSE TECHNIQUE FOR DC TO DC CONVERTER DRIVER
SE-1775-IP	Open	CONTROLLED TURN ON OF UPPER FET TO CONTROL PHASE RINGING IN BUCK PWM DC TO DC
6E-1776-IP	Open	LEVEL SHIFTED LOWER GATE DRIVER FOR DC TO DC DRIVER
6E-1611-WR	Open	IMPROVED FEC REPEAT CODE DEMODULATION METHOD
6E-1781-IP	Open	TECHNIQUE TO PREVENT CURRENT INJECTION INTO UPPER FET OF SYNCHRONOUS BUCK DC TO DC
E-1740-TL	Open	CIRCUIT DESIGN FOR TESTING HIGH PERFORMANCE DEVICES

## SCHEDULE A PATENT DISCLOSURES

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SE-1658-SP	Open	SINGLE BIT OVER-SAMPLED A/D - D/A SERVE CONTROL OF LOAD CURRENT IN A POWER MOSPET
SE-1780-IP	1-1	TECHNIQUE TO USE "PILOTED" LOWER N-CHANNEL FET FOR CURRENT SENSING IN PWM APPLICATIONS